

# LPC11U6x

32-bit ARM Cortex-M0+ microcontroller; up to 256 KB flash and 36 KB SRAM; 4 KB EEPROM; USB; 12-bit ADC

Rev. 1.5 — 12 August 2020

Product data sheet

# 1. General description

The LPC11U6x are an ARM Cortex-M0+ based, low-cost 32-bit MCU family operating at CPU frequencies of up to 50 MHz. The LPC11U6x support up to 256 KB of flash memory, a 4 KB EEPROM, and 36 KB of SRAM.

The ARM Cortex-M0+ is an easy-to-use, energy-efficient core using a two-stage pipeline and fast single-cycle I/O access.

The peripheral complement of the LPC11U6x includes a DMA controller, a CRC engine, one full-speed USB device controller with XTAL-less low-speed mode, two I<sup>2</sup>C-bus interfaces, up to five USARTs, two SSP interfaces, PWM/timer subsystem with six configurable multi-purpose timers, a Real-Time Clock, one 12-bit ADC, temperature sensor, function-configurable I/O ports, and up to 80 general-purpose I/O pins.

For additional documentation related to the LPC11U6x parts, see <u>Section 17</u> "References".

# 2. Features and benefits

- System:
  - ARM Cortex-M0+ processor (version r0p1), running at frequencies of up to 50 MHz with single-cycle multiplier and fast single-cycle I/O port.
  - ARM Cortex-M0+ built-in Nested Vectored Interrupt Controller (NVIC).
  - AHB Multilayer matrix.
  - System tick timer.
  - Serial Wire Debug (SWD) and JTAG boundary scan modes supported.
  - Micro Trace Buffer (MTB) supported.
- Memory:
  - ◆ Up to 256 KB on-chip flash programming memory with page erase.
  - Up to 32 KB main SRAM.
  - Up to two additional SRAM blocks of 2 KB each.
  - Up to 4 KB EEPROM.
- ROM API support:
  - Boot loader.
  - USART drivers.
  - I2C drivers.
  - USB drivers.
  - DMA drivers.



- Power profiles.
- Flash In-Application Programming (IAP) and In-System Programming (ISP).
- ◆ 32-bit integer division routines.
- Digital peripherals:
  - Simple DMA engine with 16 channels and programmable input triggers.
  - High-speed GPIO interface connected to the ARM Cortex-M0+ IO bus with up to 80 General-Purpose I/O (GPIO) pins with configurable pull-up/pull-down resistors, programmable open-drain mode, input inverter, and programmable glitch filter and digital filter.
  - Pin interrupt and pattern match engine using eight selectable GPIO pins.
  - Two GPIO group interrupt generators.
  - CRC engine.
- Configurable PWM/timer subsystem (two 16-bit and two 32-bit standard counter/timers, two State-Configurable Timers (SCTimer/PWM)) that provides:
  - Up to four 32-bit and two 16-bit counter/timers or two 32-bit and six 16-bit counter/timers.
  - Up to 21 match outputs and 16 capture inputs.
  - ◆ Up to 19 PWM outputs with 6 independent time bases.
- Windowed WatchDog timer (WWDT).
- Real-time Clock (RTC) in the always-on power domain with separate battery supply pin and 32 kHz oscillator.
- Analog peripherals:
  - One 12-bit ADC with up to 12 input channels with multiple internal and external trigger inputs and with sample rates of up to 2 Msamples/s. The ADC supports two independent conversion sequences.
  - Temperature sensor.
- Serial interfaces:
  - Up to five USART interfaces, all with DMA, synchronous mode, and RS-485 mode support. Four USARTs use a shared fractional baud generator.
  - Two SSP controllers with DMA support.
  - Two I<sup>2</sup>C-bus interfaces. One I<sup>2</sup>C-bus interface with specialized open-drain pins supports I2C Fast-mode plus.
  - USB 2.0 full-speed device controller with on-chip PHY. XTAL-less low-speed mode supported.
- Clock generation:
  - ◆ 12 MHz internal RC oscillator trimmed to 1 % accuracy for -25 °C ≤ T<sub>amb</sub> ≤ +85 °C that can optionally be used as a system clock.
  - On-chip 32 kHz oscillator for RTC.
  - Crystal oscillator with an operating range of 1 MHz to 25 MHz. Oscillator pins are shared with the GPIO pins.
  - Programmable watchdog oscillator with a frequency range of 9.4 kHz to 2.3 MHz.
  - PLL allows CPU operation up to the maximum CPU rate without the need for a high-frequency crystal.
  - A second, dedicated PLL is provided for USB.
  - Clock output function with divider that can reflect the crystal oscillator, the main clock, the IRC, or the watchdog oscillator.

- Power control:
  - Integrated PMU (Power Management Unit) to minimize power consumption.
  - Reduced power modes: Sleep mode, Deep-sleep mode, Power-down mode, and Deep power-down mode.
  - Wake-up from Deep-sleep and Power-down modes on external pin inputs and USART activity.
  - Power-On Reset (POR).
  - Brownout detect.
- Unique device serial number for identification.
- Single power supply (2.4 V to 3.6 V).
- Separate VBAT supply for RTC.
- Operating temperature range –40 °C to 105 °C.
- Available as LQFP48, LQFP64, and LQFP100 packages.

# 3. Applications

- Three-phase e-meter
- GPS tracker
- Gaming accessories

- Car radio
- Medical monitor
- PC peripherals

Product data sheet

# 4. Ordering information

#### Table 1.Ordering information

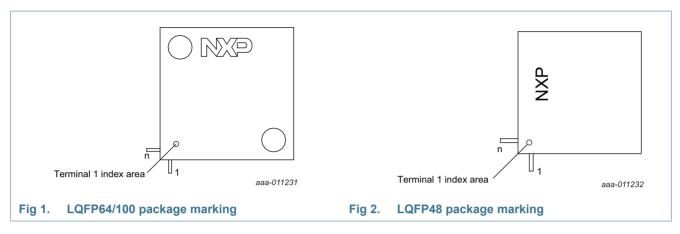
Type number	Package		
	Name	Description	Version
LPC11U66JBD48	LQFP48	plastic low profile quad flat package; 48 leads; body $7 \times 7 \times 1.4$ mm	SOT313-2
LPC11U67JBD48	LQFP48	plastic low profile quad flat package; 48 leads; body $7 \times 7 \times 1.4$ mm	SOT313-2
LPC11U67JBD64	LQFP64	plastic low profile quad flat package; 64 leads; body $10 \times 10 \times 1.4$ mm	SOT314-2
LPC11U67JBD100	LQFP100	plastic low profile quad flat package; 100 leads; body $14 \times 14 \times 1.4$ mm	SOT407-1
LPC11U68JBD48	LQFP48	plastic low profile quad flat package; 48 leads; body $7 \times 7 \times 1.4$ mm	SOT313-2
LPC11U68JBD64	LQFP64	plastic low profile quad flat package; 64 leads; body $10 \times 10 \times 1.4$ mm	SOT314-2
LPC11U68JBD100	LQFP100	plastic low profile quad flat package; 100 leads; body 14 $\times$ 14 $\times$ 1.4 mm	SOT407-1

# 4.1 Ordering options

# Table 2. Ordering options

Type number	Flash/ KB	EEPROM/ KB	SRAM/ KB	USB	<b>USART0</b>	<b>USART1</b>	<b>USART2</b>	<b>USART3</b>	<b>USART4</b>	I <sup>2</sup> C	SSP	Timers with PWM	12-bit ADC channels	GPIO
LPC11U66JBD48	64	4	12	1	Y	Y	Y	Ν	Ν	2	2	6	8	34
LPC11U67JBD48	128	4	20	1	Y	Y	Y	Ν	Ν	2	2	6	8	34
LPC11U67JBD64	128	4	20	1	Y	Y	Y	Ν	Ν	2	2	6	10	48
LPC11U67JBD100	128	4	20	1	Y	Y	Y	Y	Y	2	2	6	12	80
LPC11U68JBD48	256	4	36	1	Y	Y	Y	Ν	Ν	2	2	6	8	34
LPC11U68JBD64	256	4	36	1	Y	Y	Y	Ν	Ν	2	2	6	10	48
LPC11U68JBD100	256	4	36	1	Y	Y	Y	Y	Y	2	2	6	12	80

# 5. Marking



The LPC11U6x devices typically have the following top-side marking for LQFP100 packages:

LPC11U6xJBD100

XXXXXX XX

xxxyywwxR[x]

The LPC11U6x devices typically have the following top-side marking for LQFP64 packages:

LPC11U6xJ

XXXXXX XX

xxxyywwxR[x]

The LPC11U6x devices typically have the following top-side marking for LQFP48 packages:

LPC11U6xJ

XX XX

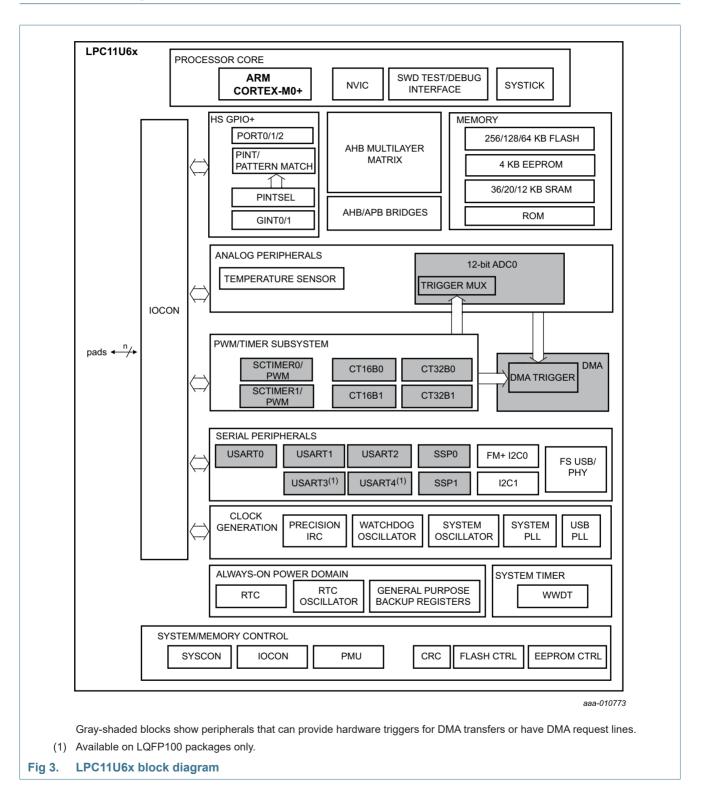
хххуу

wwxR[x]

Field 'yy' states the year the device was manufactured. Field 'ww' states the week the device was manufactured during that year. Field 'R' states the chip revision.

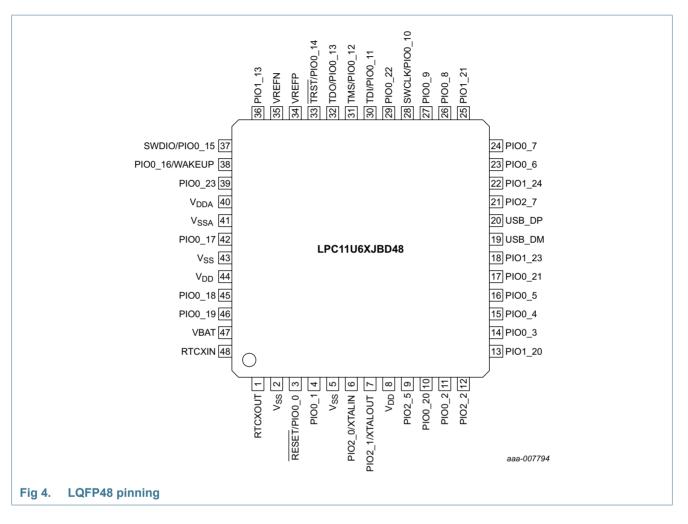
LPC11U6x

# 6. Block diagram

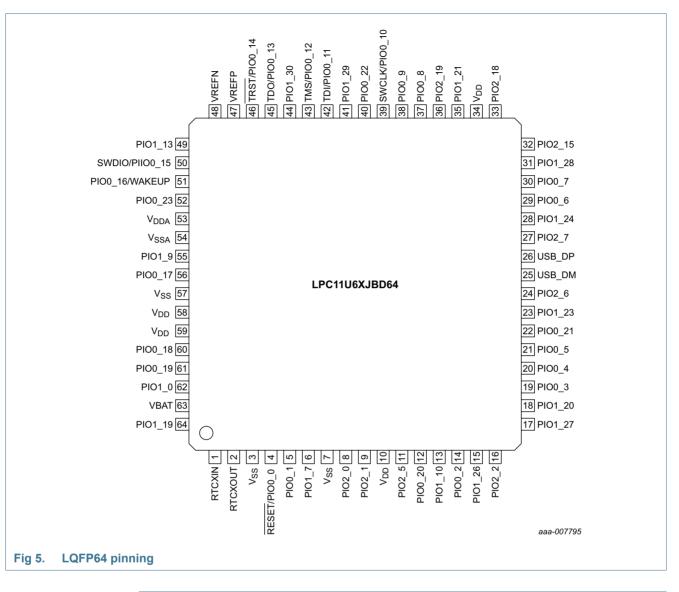


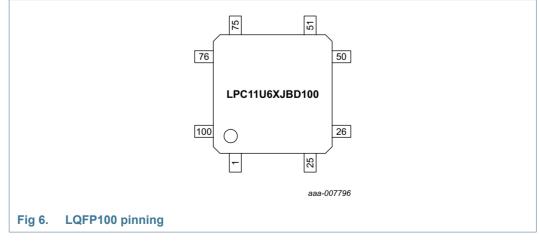
# 7. Pinning information

# 7.1 Pinning



Product data sheet





# 7.2 Pin description

#### Table 3. Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
RESET/PIO0_0	3	4	8	[8]	I; PU	I	<b>RESET</b> — External reset input with 20 ns glitch filter. A LOW-going pulse as short as 50 ns on this pin resets the device, causing I/O ports and peripherals to take on their default states, and processor execution to begin at address 0. This pin also serves as the debug select input. LOW level selects the JTAG boundary scan. HIGH level selects the ARM SWD debug mode.
							In deep power-down mode, this pin must be pulled HIGH externally. The RESET pin can be left unconnected or be used as a GPIO pin if an external RESET function is not needed and Deep power-down mode is not used.
						IO	PIO0_0 — General-purpose digital input/output pin.
PIO0_1	4	5	9	<u>[6]</u>	I; PU	IO	<b>PIO0_1</b> — General-purpose digital input/output pin. A LOW level on this pin during reset starts the ISP command handler or the USB device enumeration.
						0	CLKOUT — Clockout pin.
						0	CT32B0_MAT2 — Match output 2 for 32-bit timer 0.
						0	USB_FTOGGLE — USB 1 ms Start-of-Frame signal.
PIO0_2	11	14	19	9 [6]	I; PU	IO	<b>PIO0_2</b> — General-purpose port 0 input/output 2.
						IO	SSP0_SSEL — Slave select for SSP0.
						I	CT16B0_CAP0 — Capture input 0 for 16-bit timer 0.
						-	R_0 — Reserved.
PIO0_3	14	19	30	<u>[6]</u>	I; PU	IO	<b>PIO0_3</b> — General-purpose digital input/output pin. A LOW level on this pin during reset starts the ISP command handler. A HIGH level during reset starts the USB device enumeration.
						I	USB_VBUS — Monitors the presence of USB bus power.
						-	R_1 — Reserved.
PIO0_4	15	20	31	[7]	IA	Ю	<b>PIO0_4</b> — General-purpose port 0 input/output 4 (open-drain).
						IO	<b>I2C0_SCL</b> — I <sup>2</sup> C-bus clock input/output (open-drain). High-current sink only if I <sup>2</sup> C Fast-mode Plus is selected in the I/O configuration register.
						-	R_2 — Reserved.
PIO0_5	16	21	32	[7]	IA	IO	<b>PIO0_5</b> — General-purpose port 0 input/output 5 (open-drain).
						IO	<b>I2C0_SDA</b> — I <sup>2</sup> C-bus data input/output (open-drain). High-current sink only if I <sup>2</sup> C Fast-mode Plus is selected in the I/O configuration register.
						-	R_3 — Reserved.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO0_6	23	29	44	[6]	I; PU	IO	<b>PIO0_6</b> — General-purpose port 0 input/output 6.
						-	R — Reserved.
						10	SSP0_SCK — Serial clock for SSP0.
						-	R_4 — Reserved.
PIO0_7	24	30	45	[5]	I; PU	Ю	<b>PIO0_7</b> — General-purpose port 0 input/output 7 (high-current output driver).
						I	<b>U0_CTS</b> — Clear To Send input for USART.
						-	R_5 — Reserved.
						Ю	<b>I2C1_SCL</b> — I <sup>2</sup> C-bus clock input/output. This pin is not open-drain.
PIO0_8	26	37	58	[6]	I; PU	IO	PIO0_8 — General-purpose port 0 input/output 8.
						IO	SSP0_MISO — Master In Slave Out for SSP0.
						0	CT16B0_MAT0 — Match output 0 for 16-bit timer 0.
						-	R_6 — Reserved.
PIO0_9	27	38	59	[6]	I; PU	IO	PIO0_9 — General-purpose port 0 input/output 9.
					IO	SSP0_MOSI — Master Out Slave In for SSP0.	
						0	CT16B0_MAT1 — Match output 1 for 16-bit timer 0.
						-	R_7 — Reserved.
SWCLK/PIO0_10	28	39	60	[6]	I; PU	IO	<b>SWCLK</b> — Serial Wire Clock. SWCLK is enabled by default on this pin. In boundary scan mode: TCK (Test Clock).
						IO	PIO0_10 — General-purpose digital input/output pin.
						IO	SSP0_SCK — Serial clock for SSP0.
						0	CT16B0_MAT2 — 16-bit timer0 MAT2
TDI/PIO0_11	30	42	64	[3]	I; PU	IO	<b>TDI</b> — Test Data In for JTAG interface. In boundary scan mode only.
						IO	PIO0_11 — General-purpose digital input/output pin.
						AI	ADC_9 — A/D converter, input channel 9.
						0	CT32B0_MAT3 — Match output 3 for 32-bit timer 0.
						0	<b>U1_RTS</b> — Request To Send output for USART1.
						IO	<b>U1_SCLK</b> — Serial clock input/output for USART1 in synchronous mode.
TMS/PIO0_12	31	43	66	[3]	I; PU	IO	<b>TMS</b> — Test Mode Select for JTAG interface. In boundary scan mode only.
						IO	PIO0_12 — General-purpose digital input/output pin.
						AI	ADC_8 — A/D converter, input channel 8.
						I	CT32B1_CAP0 — Capture input 0 for 32-bit timer 1.
						I	<b>U1_CTS</b> — Clear To Send input for USART1.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
TDO/PIO0_13	32	45	68	[3]	I; PU	IO	<b>TDO</b> — Test Data Out for JTAG interface. In boundary scan mode only.
						IO	PIO0_13 — General-purpose digital input/output pin.
						AI	ADC_7 — A/D converter, input channel 7.
						0	CT32B1_MAT0 — Match output 0 for 32-bit timer 1.
						I	U1_RXD — Receiver input for USART1.
TRST/PIO0_14	33	46	69	[3]	I; PU	Ю	<b>TRST</b> — Test Reset for JTAG interface. In boundary scan mode only.
						IO	PIO0_14 — General-purpose digital input/output pin.
						AI	ADC_6 — A/D converter, input channel 6.
						0	CT32B1_MAT1 — Match output 1 for 32-bit timer 1.
						0	U1_TXD — Transmitter output for USART1.
SWDIO/PIO0_15	37	50	81	<u>[3]</u>	I; PU	Ю	<b>SWDIO</b> — Serial Wire Debug I/O. SWDIO is enabled by default on this pin. In boundary scan mode: TMS (Test Mode Select).
						IO	PIO0_15 — General-purpose digital input/output pin.
						AI	ADC_3 — A/D converter, input channel 3.
						0	CT32B1_MAT2 — Match output 2 for 32-bit timer 1.
PIO0_16/WAKEUP	38	51	82	[4]	I; PU	IO	<b>PIO0_16</b> — General-purpose digital input/output pin. This pin also serves as the Deep power-down mode wake-up pin with 20 ns glitch filter. Pull this pin HIGH externally before entering Deep power-down mode. Pull this pin LOW to exit Deep power-down mode. A LOW-going pulse as short as 50 ns wakes up the part.
						AI	ADC_2 — A/D converter, input channel 2.
						0	CT32B1_MAT3 — Match output 3 for 32-bit timer 1.
						-	R_8 — Reserved.
PIO0_17	42	56	90	[6]	I; PU	IO	PIO0_17 — General-purpose digital input/output pin.
						0	<b>U0_RTS</b> — Request To Send output for USART0.
						I	CT32B0_CAP0 — Capture input 0 for 32-bit timer 0.
						10	<b>U0_SCLK</b> — Serial clock input/output for USART0 in synchronous mode.
PIO0_18	45	60	94	[6]	I; PU	IO	PIO0_18 — General-purpose digital input/output pin.
						I	<b>U0_RXD</b> — Receiver input for USART0. Used in UART ISP mode.
						0	CT32B0_MAT0 — Match output 0 for 32-bit timer 0.
PIO0_19	46	61	95	[6]	I; PU	IO	PIO0_19 — General-purpose digital input/output pin.
						0	<b>U0_TXD</b> — Transmitter output for USART0. Used in UART ISP mode.
						0	CT32B0_MAT1 — Match output 1 for 32-bit timer 0.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO0_20	10	12	17	[6]	I; PU	Ю	PIO0_20 — General-purpose digital input/output pin.
						I	CT16B1_CAP0 — Capture input 0 for 16-bit timer 1.
						I	U2_RXD — Receiver input for USART2.
PIO0_21	17	22	33	[6]	I; PU	10	PIO0_21 — General-purpose digital input/output pin.
						0	CT16B1_MAT0 — Match output 0 for 16-bit timer 1.
						IO	SSP1_MOSI — Master Out Slave In for SSP1.
PIO0_22	29	40	62	[3]	I; PU	10	PIO0_22 — General-purpose digital input/output pin.
						AI	ADC_11 — A/D converter, input channel 11.
						I	CT16B1_CAP1 — Capture input 1 for 16-bit timer 1.
						IO	SSP1_MISO — Master In Slave Out for SSP1.
PIO0_23	39	52	83	[3]	I; PU	IO	PIO0_23 — General-purpose digital input/output pin.
						AI	ADC_1 — A/D converter, input channel 1.
						-	R_9 — Reserved.
						I	<b>U0_RI</b> — Ring Indicator input for USART0.
						IO	SSP1_SSEL — Slave select for SSP1.
PIO1_0	-	62	97	[6]	I; PU	10	PIO1_0 — General-purpose digital input/output pin.
						0	CT32B1_MAT0 — Match output 0 for 32-bit timer 1.
						-	R_10 — Reserved.
						0	U2_TXD — Transmitter output for USART2.
PIO1_1	-	-	28	[6]	I; PU	10	PIO1_1 — General-purpose digital input/output pin.
						0	CT32B1_MAT1 — Match output 1 for 32-bit timer 1.
						-	R_11 — Reserved.
						0	<b>U0_DTR</b> — Data Terminal Ready output for USART0.
PIO1_2	-	-	55	[6]	I; PU	10	PIO1_2 — General-purpose digital input/output pin.
						0	CT32B1_MAT2 — Match output 2 for 32-bit timer 1.
						-	R_12 — Reserved.
						I	U1_RXD — Receiver input for USART1.
PIO1_3	-	-	72	[3]	I; PU	IO	PIO1_3 — General-purpose digital input/output pin.
						0	CT32B1_MAT3 — Match output 3 for 32-bit timer 1.
						-	R_13 — Reserved.
						Ю	I2C1_SDA — I <sup>2</sup> C-bus data input/output (not open-drain).
						AI	ADC_5 — A/D converter, input channel 5.
PIO1_4	-	-	23	[6]	I; PU	Ю	PIO1_4 — General-purpose digital input/output pin.
						I	CT32B1_CAP0 — Capture input 0 for 32-bit timer 1.
						-	R_14 — Reserved.
						1	<b>U0_DSR</b> — Data Set Ready input for USART0.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO1_5	-	-	47	[6]	I; PU	IO	PIO1_5 — General-purpose digital input/output pin.
						I	CT32B1_CAP1 — Capture input 1 for 32-bit timer 1.
						-	R_15 — Reserved.
						I	<b>U0_DCD</b> — Data Carrier Detect input for USART0.
PIO1_6	-	-	98	[6]	I; PU	IO	PIO1_6 — General-purpose digital input/output pin.
						-	R_16 — Reserved.
						I	U2_RXD — Receiver input for USART2.
						I	CT32B0_CAP2 — Capture input 2 for 32-bit timer 0.
PIO1_7	-	6	10	[6]	I; PU	IO	PIO1_7 — General-purpose digital input/output pin.
						-	R_17 — Reserved.
						I	<b>U2_CTS</b> — Clear To Send input for USART2.
						I	CT16B1_CAP0 — Capture input 0 for 32-bit timer 1.
PIO1_8	-	-	61	[6]	I; PU	IO	PIO1_8 — General-purpose digital input/output pin.
						-	R_18 — Reserved.
						0	U1_TXD — Transmitter output for USART1.
						I	CT16B0_CAP0 — Capture input 0 for 16-bit timer 0.
PIO1_9	-	55	86	[3]	I; PU	IO	PIO1_9 — General-purpose digital input/output pin.
						I	<b>U0_CTS</b> — Clear To Send input for USART0.
						0	CT16B1_MAT1 — Match output 1 for 16-bit timer 1.
						I	ADC_0 — A/D converter, input channel 0.
PIO1_10	-	13	18	[6]	I; PU	IO	PIO1_10 — General-purpose digital input/output pin.
						0	<b>U2_RTS</b> — Request To Send output for USART2.
						IO	<b>U2_SCLK</b> — Serial clock input/output for USART2 in synchronous mode.
						0	CT16B1_MAT0 — Match output 0 for 16-bit timer 1.
PIO1_11	-	-	65	[6]	I; PU	IO	PIO1_11 — General-purpose digital input/output pin.
						IO	I2C1_SCL — I <sup>2</sup> C1-bus clock input/output (not open-drain).
						0	CT16B0_MAT2 — Match output 2 for 16-bit timer 0.
						I	<b>U0_RI</b> — Ring Indicator input for USART0.
PIO1_12	-	-	89	[6]	I; PU	IO	PIO1_12 — General-purpose digital input/output pin.
						10	SSP0_MOSI — Master Out Slave In for SSP0.
						0	CT16B0_MAT1 — Match output 1 for 16-bit timer 0.
						-	R_21 — Reserved.
PIO1_13	36	49	78	[6]	I; PU	IO	<b>PIO1_13</b> — General-purpose digital input/output pin.
						I	U1_CTS — Clear To Send input for USART1.
						0	SCT0_OUT3 — SCTimer0/PWM output 3.
						-	<b>R_22</b> — Reserved.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO1_14	-	-	79	[6]	I; PU	IO	PIO1_14 — General-purpose digital input/output pin.
						IO	I2C1_SDA — I <sup>2</sup> C1-bus data input/output (not open-drain).
						0	CT32B1_MAT2 — Match output 2 for 32-bit timer 1.
						-	R_23 — Reserved.
PIO1_15	-	-	87	[6]	I; PU	IO	PIO1_15 — General-purpose digital input/output pin.
						IO	SSP0_SSEL — Slave select for SSP0.
						0	CT32B1_MAT3 — Match output 3 for 32-bit timer 1.
						-	R_24 — Reserved.
PIO1_16	-	-	96	[6]	I; PU	IO	PIO1_16 — General-purpose digital input/output pin.
						IO	SSP0_MISO — Master In Slave Out for SSP0.
						0	CT16B0_MAT0 — Match output 0 for 16-bit timer 0.
						-	R_25 — Reserved.
PIO1_17	-	-	34	[6]	I; PU	IO	PIO1_17 — General-purpose digital input/output pin.
						I	CT16B0_CAP2 — Capture input 2 for 16-bit timer 0.
						I	U0_RXD — Receiver input for USART0.
						-	R_26 — Reserved.
PIO1_18	01_18	-	43	<u>[6]</u>	I; PU	IO	PIO1_18 — General-purpose digital input/output pin.
						I	CT16B1_CAP1 — Capture input 1 for 16-bit timer 1.
						0	<b>U0_TXD</b> — Transmitter output for USART0.
						-	R_27 — Reserved.
PIO1_19	-	64	4	[6]	I; PU	IO	PIO1_19 — General-purpose digital input/output pin.
						I	<b>U2_CTS</b> — Clear To Send input for USART2.
						0	SCT0_OUT0 — SCTimer0/PWM output 0.
						-	R_28 — Reserved.
PIO1_20	13	18	29	[6]	I; PU	IO	PIO1_20 — General-purpose digital input/output pin.
						I	<b>U0_DSR</b> — Data Set Ready input for USART0.
						IO	SSP1_SCK — Serial clock for SSP1.
						0	CT16B0_MAT0 — Match output 0 for 16-bit timer 0.
PIO1_21	25	35	56	[6]	I; PU	IO	PIO1_21 — General-purpose digital input/output pin.
						I	<b>U0_DCD</b> — Data Carrier Detect input for USART0.
						IO	SSP1_MISO — Master In Slave Out for SSP1.
						I	CT16B0_CAP2 — Capture input 2 for 16-bit timer 0.
PIO1_22	-	-	80	[3]	I; PU	IO	PIO1_22 — General-purpose digital input/output pin.
						IO	SSP1_MOSI — Master Out Slave In for SSP1.
						I	CT32B1_CAP1 — Capture input 1 for 32-bit timer 1.
						AI	ADC_4 — A/D converter, input channel 4.
						-	<b>R_29 —</b> Reserved.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO1_23	18	23	35	[6]	I; PU	IO	PIO1_23 — General-purpose digital input/output pin.
						0	CT16B1_MAT1 — Match output 1 for 16-bit timer 1.
						IO	SSP1_SSEL — Slave select for SSP1.
						0	U2_TXD — Transmitter output for USART2.
PIO1_24	22	28	42	[6]	I; PU	IO	PIO1_24 — General-purpose digital input/output pin.
						0	CT32B0_MAT0 — Match output 0 for 32-bit timer 0.
						IO	I2C1_SDA — I <sup>2</sup> C-bus data input/output (not open-drain).
PIO1_25	-	-	100	[6]	I; PU	IO	PIO1_25 — General-purpose digital input/output pin.
						0	U2_RTS — Request To Send output for USART2.
						Ю	<b>U2_SCLK</b> — Serial clock input/output for USART2 in synchronous mode.
						I	SCT0_IN0 — SCTimer0/PWM input 0.
						-	R_30 — Reserved.
PIO1_26	-	15	20	[6]	I; PU	IO	PIO1_26 — General-purpose digital input/output pin.
						0	CT32B0_MAT2 — Match output 2 for 32-bit timer 0.
						I	<b>U0_RXD</b> — Receiver input for USART0.
						-	R_19 — Reserved.
PIO1_27	-	17	22	[6]	I; PU	IO	PIO1_27 — General-purpose digital input/output pin.
						0	CT32B0_MAT3 — Match output 3 for 32-bit timer 0.
						0	<b>U0_TXD</b> — Transmitter output for USART0.
						-	R_20 — Reserved.
						IO	SSP1_SCK — Serial clock for SSP1.
PIO1_28	-	31	46	[6]	I; PU	IO	PIO1_28 — General-purpose digital input/output pin.
						I	CT32B0_CAP0 — Capture input 0 for 32-bit timer 0.
						Ю	<b>U0_SCLK</b> — Serial clock input/output for USART in synchronous mode.
						0	<b>U0_RTS</b> — Request To Send output for USART0.
PIO1_29	-	41	63	[3]	I; PU	IO	PIO1_29 — General-purpose digital input/output pin.
						IO	SSP0_SCK — Serial clock for SSP0.
						I	CT32B0_CAP2 — Capture input 2 for 32-bit timer 0.
						0	<b>U0_DTR</b> — Data Terminal Ready output for USART0.
						AI	ADC_10 — A/D converter, input channel 10.
PIO1_30	-	44	67	[6]	I; PU	IO	PIO1_30 — General-purpose digital input/output pin.
						IO	I2C1_SCL — I <sup>2</sup> C1-bus clock input/output (not open-drain)
						I	SCT0_IN3 — SCTimer0/PWM input 3.
						-	R_31 — Reserved.
PIO1_31	-	-	48	[5]	I; PU	IO	<b>PIO1_31</b> — General-purpose digital input/output pin (high-current output driver).

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO2_0	6	8	12	[10]	I; PU	IO	PIO2_0 — General-purpose digital input/output pin.
						AI	<b>XTALIN</b> — Input to the oscillator circuit and internal clock generator circuits. Input voltage must not exceed 1.8 V.
PIO2_1	7	9	13	[10]	I; PU	IO	PIO2_1 — General-purpose digital input/output pin.
						AO	<b>XTALOUT</b> — Output from the oscillator amplifier.
PIO2_2	12	16	21	[6]	I; PU	IO	PIO2_2 — General-purpose digital input/output pin.
						0	<b>U3_RTS</b> — Request To Send output for USART3.
						10	<b>U3_SCLK</b> — Serial clock input/output for USART3 in synchronous mode.
							SCT0_OUT1 — SCTimer0/PWM output 1.
PIO2_3	-	-	36	[6]	I; PU	IO	PIO2_3 — General-purpose digital input/output pin.
						I	U3_RXD — Receiver input for USART3.
						0	CT32B0_MAT1 — Match output 1 for 32-bit timer 0.
PIO2_4	-	-	41	[6]	I; PU	IO	PIO2_4 — General-purpose digital input/output pin.
						0	U3_TXD — Transmitter output for USART3.
						0	CT32B0_MAT2 — Match output 2 for 32-bit timer 0.
PIO2_5	9	11	15	[6]	I; PU	IO	PIO2_5 — General-purpose digital input/output pin.
						I	<b>U3_CTS</b> — Clear To Send input for USART3.
						I	SCT0_IN1 — SCTimer0/PWM input 1.
PIO2_6	-	24	37	[6]	I; PU	IO	PIO2_6 — General-purpose digital input/output pin.
						0	<b>U1_RTS</b> — Request To Send output for USART1.
						Ю	<b>U1_SCLK</b> — Serial clock input/output for USART1 in synchronous mode.
						I	SCT0_IN2 — SCTimer0/PWM input 2.
PIO2_7	21	27	40	[6]	I; PU	IO	PIO2_7 — General-purpose digital input/output pin.
						IO	SSP0_SCK — Serial clock for SSP0.
						I	SCT0_OUT2 — SCTimer0/PWM output 2.
PIO2_8	-	-	2	[6]	I; PU	IO	PIO2_8 — General-purpose digital input/output pin.
						I	SCT1_IN0 — SCTimer1/PWM input 0.
PIO2_9	-	-	3	[6]	I; PU	IO	PIO2_9 — General-purpose digital input/output pin.
						I	SCT1_IN1 — SCTimer1/PWM_IN1
PIO2_10	-	-	16	[6]	I; PU	IO	PIO2_10 — General-purpose digital input/output pin.
						0	<b>U4_RTS</b> — Request To Send output for USART4.
						Ю	<b>U4_SCLK</b> — Serial clock input/output for USART4 in synchronous mode.
PIO2_11	-	-	24	[6]	I; PU	IO	PIO2_11 — General-purpose digital input/output pin.
						I	U4_RXD — Receiver input for USART4.
PIO2_12	-	-	25	[6]	I; PU	IO	PIO2_12 — General-purpose digital input/output pin.
						0	U4_TXD — Transmitter output for USART4.

#### Table 3.Pin description

Symbol	LQFP48	LQFP64	LQFP100		Reset state <sup>[1]</sup>	Туре	Description of pin functions
PIO2_13	-	-	26	[6]	I; PU	IO	PIO2_13 — General-purpose digital input/output pin.
						I	U4_CTS — Clear To Send input for USART4.
PIO2_14	-	-	27	[6]	I; PU	IO	PIO2_14 — General-purpose digital input/output pin.
						I	SCT1_IN2 — SCTimer1/PWM input 2.
PIO2_15	-	32	49	[6]	I; PU	IO	PIO2_15 — General-purpose digital input/output pin.
						I	SCT1_IN3 — SCTimer1/PWM input 3.
PIO2_16	-	-	50	[6]	I; PU	IO	PIO2_16 — General-purpose digital input/output pin.
						0	SCT1_OUT0 — SCTimer1/PWM output 0.
PIO2_17	-	-	51	[6]	I; PU	IO	PIO2_17 — General-purpose digital input/output pin.
						0	SCT1_OUT1 — SCTimer1/PWM output 1.
PIO2_18	-	33	52	[6]	I; PU	IO	PIO2_18 — General-purpose port 2 input/output 18.
						0	SCT1_OUT2 — SCTimer1/PWM output 2.
PIO2_19	-	36	57	[6]	I; PU	IO	PIO2_19 — General-purpose port 2 input/output 19.
						0	SCT1_OUT3 — SCTimer1/PWM output 3.
PIO2_20	-	-	75	[6]	I; PU	IO	PIO2_20 — General-purpose port 2 input/output 20.
PIO2_21	-	-	76	[6]	I; PU	IO	PIO2_21 — General-purpose port 2 input/output 21.
PIO2_22	-	-	77	[6]	I; PU	IO	PIO2_22 — General-purpose port 2 input/output 22.
PIO2_23	-	-	1	[6]	I; PU	IO	PIO2_23 — General-purpose port 2 input/output 23.
RSTOUT	-	-	88	[6]	IA	IO	Internal reset status output.
USB_DP	20	26	39	[9]	F	-	USB bidirectional D+ line. Pad includes internal 33 $\Omega$ series termination resistor.
USB_DM	19	25	38	<u>[9]</u>	F	-	USB bidirectional D– line. Pad includes internal 33 $\Omega$ series termination resistor.
RTCXIN	48	1	5	[2]	-	-	RTC oscillator input. This input should be grounded if the RTC is not used.
RTCXOUT	1	2	6	[2]	-	-	RTC oscillator output.
VREFP	34	47	73		-	-	ADC positive reference voltage. If the ADC is not used, tie VREFP to $V_{DD}$ .
VREFN	35	48	74		-	-	ADC negative voltage reference. If the ADC is not used, tie VREFN to $V_{SS}.$
V <sub>DDA</sub>	40	53	84		-	-	Analog voltage supply. $V_{DDA}$ should typically be the same voltages as $V_{DD}$ but should be isolated to minimize noise and error. $V_{DDA}$ should be tied to $V_{DD}$ if the ADC is not used.
V <sub>DD</sub>	44, 8	58, 10, 34, 59	92, 14, 71, 54, 93		-	-	Supply voltage to the internal regulator and the external rail.

#### Table 3.Pin description

Pin functions are selected through the IOCON registers. See Table 2 for availability of USART3 and USART4 pin functions.

Symbol	LQFP48	LQFP64	LQFP100	Reset state <sup>[1]</sup>	Туре	Description of pin functions
VBAT	47	63	99	-	-	Battery supply. Supplies power to the RTC. If no battery is used, tie VBAT to VDD.
V <sub>SSA</sub>	41	54	85	-	-	Analog ground. $V_{SSA}$ should typically be the same voltage as $V_{SS}$ but should be isolated to minimize noise and error. $V_{SSA}$ should be tied to $V_{SS}$ if the ADC is not used.
V <sub>SS</sub>	43, 2, 5	57, 3, 7	91, 7, 11, 53, 70	-	-	Ground.

[1] Pin state at reset for default function: I = Input; AI = Analog Input; O = Output; PU = internal pull-up enabled; IA = inactive, no pull-up/down enabled;

F = floating; If the pins are not used, tie floating pins to ground or power to minimize power consumption.

- [2] Special analog pad.
- [3] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors, configurable hysteresis, and analog input. When configured as analog input, digital section of the pad is disabled and the pin is not 5 V tolerant; includes digital, programmable filter.
- [4] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors, configurable hysteresis, and analog input. When configured as analog input, digital section of the pad is disabled and the pin is not 5 V tolerant; includes digital input glitch filter. WAKEUP pin. The wake-up pin function can be disabled and the pin can be used for other purposes if the RTC is enabled for waking up the part from Deep power-down mode.
- [5] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors and configurable hysteresis; includes high-current output driver.
- [6] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors and configurable hysteresis.
- [7] I<sup>2</sup>C-bus pin compliant with the I<sup>2</sup>C-bus specification for I<sup>2</sup>C standard mode, I<sup>2</sup>C Fast-mode, and I<sup>2</sup>C Fast-mode Plus. The pin requires an external pull-up to provide output functionality. When power is switched off, this pin is floating and does not disturb the I2C lines. Open-drain configuration applies to all functions on this pin.
- [8] 5 V tolerant pad. RESET functionality is not available in Deep power-down mode. Use the WAKEUP pin to reset the chip and wake up from Deep power-down mode. An external pull-up resistor is required on this pin for the Deep power-down mode.
- [9] Pad provides USB functions. It is designed in accordance with the USB specification, revision 2.0 (Full-speed and Low-speed mode only). This pad is not 5 V tolerant.
- [10] 5 V tolerant pad providing digital I/O functions with configurable pull-up/pull-down resistors, configurable hysteresis, and analog crystal oscillator connections. When configured for the crystal oscillator input/output, digital section of the pad is disabled and the pin is not 5 V tolerant; includes digital, programmable filter.

# 8. Functional description

### 8.1 ARM Cortex-M0+ core

The ARM Cortex-M0+ core runs at an operating frequency of up to 50 MHz using a two-stage pipeline. Integrated in the core are the NVIC and Serial Wire Debug with four breakpoints and two watchpoints. The ARM Cortex-M0+ core supports a single-cycle I/O enabled port for fast GPIO access.

The core includes a single-cycle multiplier and a system tick timer.

# 8.2 AHB multilayer matrix

The AHB multilayer matrix supports three masters, the M0+ core, the DMA, and the USB. All masters can access all slaves (peripherals and memories).

LPC11U6x

INTERFACE	-	
ARM CORTEX-M0+	USB DMA masters	
m Js		
		slaves
		FLASH
<u> </u>		MAIN SRAM0
<u>\</u>		SRAM USB
<u> </u>		SRAM1
<u> </u>		ROM
<u>\</u>		EEPROM
<u>\</u>		SCTIMER0/PWM
<u>\</u>		SCTIMER1/PWM
<u> </u>		HS GPIO
<u> </u>		PINT/PATTERN MATCH
<u> </u>		CRC
<u> </u>		USB REGISTERS
<u> </u>		DMA REGISTERS
	AHB-TO-A BRIDGE	<sup>р</sup> В
AHB MUI		I2C0 WWDT USARTO CT16B0 CT16B1
		CT32B0 CT32B1 ADC I2C1 RTC DMA TRIGMUX
		PMU FLASHCTRL SSP0 IOCON SYSCON
		USART4 SSP1 GROUP0 GROUP1 USART1
mactor slave connection		USART2 USART3
master-slave connection		

# 8.3 On-chip flash programming memory

The LPC11U6x contain up to 256 KB on-chip flash program memory. The flash can be programmed using In-System Programming (ISP) or In-Application Programming (IAP) via the on-chip bootloader software.

The flash memory is divided into  $24 \times 4 \text{ KB}$  and  $5 \times 32 \text{ KB}$  sectors. Individual pages of 256 byte each can be erased using the IAP erase page command.

### 8.4 EEPROM

The LPC11U6x contain 4 KB of on-chip byte-erasable and byte-programmable EEPROM data memory. The EEPROM can be programmed using In-Application Programming (IAP) via the on-chip bootloader software.

#### 8.5 SRAM

The LPC11U6x contain a total of up to 36 KB on-chip static RAM memory. The main SRAM block contains either 8 KB, 16 KB, or 32 KB of main SRAM0. Two additional SRAM blocks of 2 KB (SRAM1 and USB SRAM) are located in separate areas of the memory map. See Figure 8.

# 8.6 On-chip ROM

The on-chip ROM contains the bootloader and the following Application Programming Interfaces (APIs):

- In-System Programming (ISP) and In-Application Programming (IAP) support for flash including IAP erase page command.
- IAP support for EEPROM
- USB API
- · Power profiles for configuring power consumption and PLL settings
- 32-bit integer division routines
- APIs to use the following peripherals:
  - I2C
  - USART0 and USART1/2/3/4
  - DMA

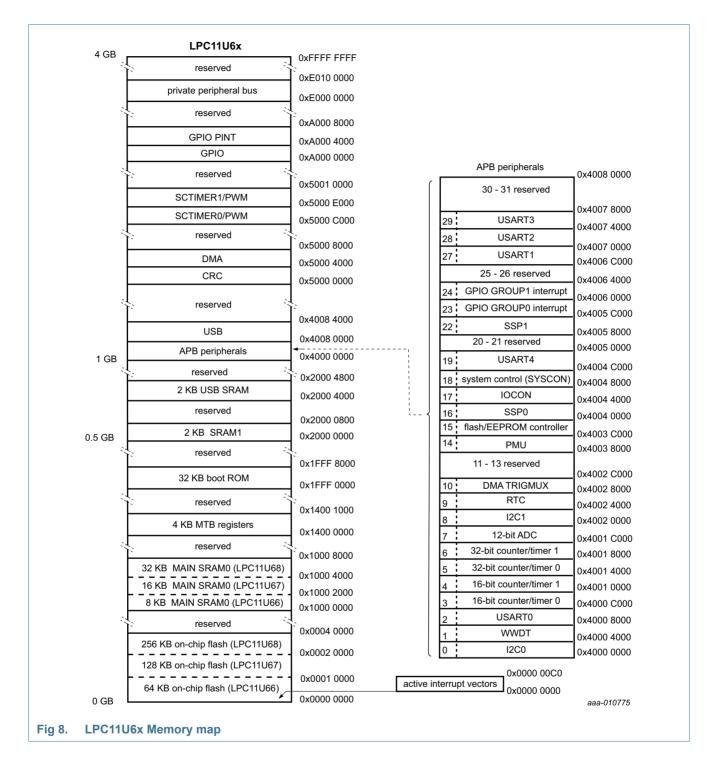
# 8.7 Memory mapping

The LPC11U6x incorporates several distinct memory regions, shown in the following figures. <u>Figure 8</u> shows the overall map of the entire address space from the user program viewpoint following reset. The interrupt vector area supports address remapping.

The AHB (Advanced High-performance Bus) peripheral area is 2 MB in size and is divided to allow for up to 128 peripherals. The APB (Advanced Peripheral Bus) peripheral area is 512 KB in size and is divided to allow for up to 32 peripherals. Each peripheral of either type is allocated 16 KB of space. This addressing scheme allows simplifying the address decoding for each peripheral.

# LPC11U6x

#### 32-bit ARM Cortex-M0+ microcontroller



# 8.8 Nested Vectored Interrupt Controller (NVIC)

The Nested Vectored Interrupt Controller (NVIC) is part of the Cortex-M0+. The tight coupling to the CPU allows for low interrupt latency and efficient processing of late arriving interrupts.

# 8.8.1 Features

- Controls system exceptions and peripheral interrupts.
- In the LPC11U6x, the NVIC supports vectored interrupts for each of the peripherals and the eight pin interrupts. The following peripheral interrupts are ORed to contribute to one interrupt in the NVIC:
  - USART1, USART4
  - USART2, USART3
  - SCTimer0/PWM, SCTimer1/PWM
  - BOD, WWDT
  - ADC end-of-sequence A interrupt, threshold crossing interrupt
  - ADC end-of-sequence B interrupt, overrun interrupt
  - Flash, EEPROM
- Four programmable interrupt priority levels with hardware priority level masking.
- Software interrupt generation.

#### 8.8.2 Interrupt sources

Each peripheral device has at least one interrupt line connected to the NVIC but can have several interrupt flags. Individual interrupt flags can also represent more than one interrupt source.

#### 8.9 IOCON block

The IOCON block allows selected pins of the microcontroller to have more than one function. Configuration registers control the multiplexers to allow connection between the pin and the on-chip peripherals.

Connect peripherals to the appropriate pins before activating the peripheral and before enabling any related interrupt.

Enabling an analog function disables the digital pad. However, the internal pull-up and pull-down resistors as well as the pin hysteresis must be disabled to obtain an accurate reading of the analog input.

#### 8.9.1 Features

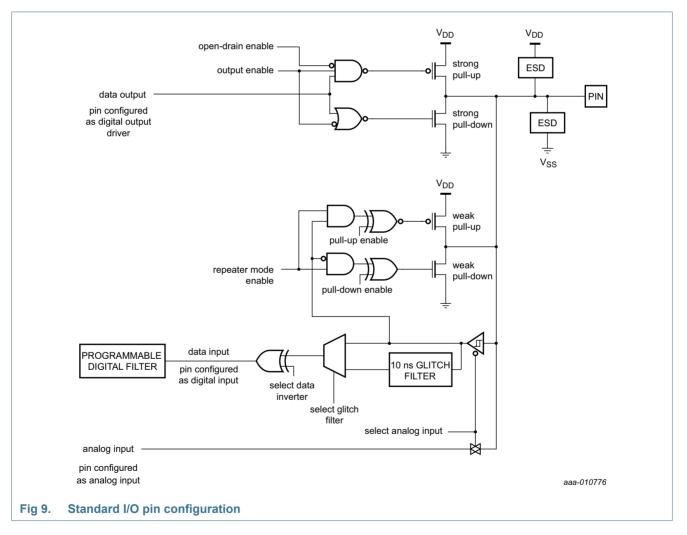
- Programmable pin function.
- Programmable pull-up, pull-down, or repeater mode.
- All pins (except PIO0\_4 and PIO0\_5) are pulled up to 3.3 V (V<sub>DD</sub> = 3.3 V) if their pull-up resistor is enabled.
- Programmable pseudo open-drain mode.
- Programmable (on/off) 10 ns glitch filter on pins PIO0\_22, PIO0\_23, PIO0\_11 to PIO0\_16, PIO1\_3, PIO1\_9, PIO1\_22, and PIO1\_29. The glitch filter is turned on by default.
- Programmable hysteresis.
- Programmable input inverter.

• Digital filter with programmable filter constant on all pins. The minimum filter constant is 1/50 MHz = 20 ns.

# 8.9.2 Standard I/O pad configuration

Figure 9 shows the possible pin modes for standard I/O pins with analog input function:

- Digital output driver with configurable open-drain output
- Digital input: Weak pull-up resistor (PMOS device) enabled/disabled
- Digital input: Weak pull-down resistor (NMOS device) enabled/disabled
- Digital input: Repeater mode enabled/disabled
- Digital input: Input digital filter selectable on all pins. In addition, a 10 ns digital glitch filter is selectable on pins with analog function.



#### • Analog input

# 8.10 Fast General-Purpose parallel I/O (GPIO)

Device pins that are not connected to a specific peripheral function are controlled by the GPIO registers. Pins may be dynamically configured as inputs or outputs. Multiple outputs can be set or cleared in one write operation.

LPC11U6x use accelerated GPIO functions:

- GPIO registers are on the ARM Cortex M0+ IO bus for fastest possible single-cycle I/O timing, allowing GPIO toggling with rates of up to 25 MHz.
- An entire port value can be written in one instruction.
- Mask, set, and clear operations are supported for the entire port.

#### 8.10.1 Features

- Bit level port registers allow a single instruction to set and clear any number of bits in one write operation.
- Direction control of individual bits.

#### 8.11 Pin interrupt/pattern match engine

The pin interrupt block configures up to eight pins from all digital pins for providing eight external interrupts connected to the NVIC.

The pattern match engine can be used, in conjunction with software, to create complex state machines based on pin inputs.

Any digital pin except pins PIO2\_8 and PIO2\_23 can be configured through the SYSCON block as input to the pin interrupt or pattern match engine. The registers that control the pin interrupt or pattern match engine are on the IO+ bus for fast single-cycle access.

#### 8.11.1 Features

- Pin interrupts
  - Up to eight pins can be selected from all digital pins except pins PIO2\_8 and PIO2\_23 as edge- or level-sensitive interrupt requests. Each request creates a separate interrupt in the NVIC.
  - Edge-sensitive interrupt pins can interrupt on rising or falling edges or both.
  - Level-sensitive interrupt pins can be HIGH- or LOW-active.
  - Pin interrupts can wake up the part from sleep mode, deep-sleep mode, and power-down mode.
- Pin interrupt pattern match engine
  - Up to 8 pins can be selected from all digital pins except pins PIO2\_8 and PIO2\_23 to contribute to a boolean expression. The boolean expression consists of specified levels and/or transitions on various combinations of these pins.
  - Each minterm (product term) comprising the specified boolean expression can generate its own, dedicated interrupt request.
  - Any occurrence of a pattern match can be programmed to generate an RXEV notification to the ARM CPU as well.
  - The pattern match engine does not facilitate wake-up.

# 8.12 GPIO group interrupts

The GPIO pins can be used in several ways to set pins as inputs or outputs and use the inputs as combinations of level and edge sensitive interrupts. For each port/pin connected to one of the two the GPIO Grouped Interrupt blocks (GINT0 and GINT1), the GPIO grouped interrupt registers determine which pins are enabled to generate interrupts and w the active polarities of each of those inputs.

The GPIO grouped interrupt registers also select whether the interrupt output is level or edge triggered and whether it is based on the OR or the AND of all of the enabled inputs.

When the designated pattern is detected on the selected input pins, the GPIO grouped interrupt block generates an interrupt. If the part is in a power-savings mode, it first asynchronously wakes up the part prior to asserting the interrupt request. The interrupt request line can be cleared by writing a one to the interrupt status bit in the control register.

### 8.12.1 Features

- Two group interrupts are supported to reflect two distinct interrupt patterns.
- The inputs from any number of digital pins can be enabled to contribute to a combined group interrupt.
- The polarity of each input enabled for the group interrupt can be configured HIGH or LOW.
- Enabled interrupts can be logically combined through an OR or AND operation.
- The grouped interrupts can wake up the part from sleep, deep-sleep or power-down modes.

# 8.13 DMA controller

The DMA controller can access all memories and the USART and SSP peripherals using DMA requests. DMA transfers can also be triggered by internal events like the ADC interrupts, timer match outputs, the pin interrupts (PINT0 and PINT1) and the SCTimer DMA requests.

#### 8.13.1 Features

- 16 channels with 14 channels connected to peripheral request inputs.
- DMA operations can be triggered by on-chip events or two pin interrupts. Each DMA channel can select one trigger input from 12 sources.
- Priority is user selectable for each channel.
- Continuous priority arbitration.
- Address cache with two entries.
- Efficient use of data bus.
- Supports single transfers up to 1,024 words.
- Address increment options allow packing and/or unpacking data.

# 8.14 USB interface

The Universal Serial Bus (USB) is a 4-wire bus that supports communication between a host and one or more (up to 127) peripherals. The host controller allocates the USB bandwidth to attached devices through a token-based protocol. The bus supports hot-plugging and dynamic configuration of the devices. All transactions are initiated by the host controller.

The USB interface consists of a full-speed device controller with on-chip PHY (PHYsical layer) for device functions.

**Remark:** Configure the part in default power mode with the power profiles before using the USB (see <u>Section 8.25.7.1 "Power profiles</u>"). Do not use the USB when the part runs in performance, efficiency, or low-power mode.

#### 8.14.1 Full-speed USB device controller

The device controller enables 12 Mbit/s data exchange with a USB Host controller. It consists of a register interface, serial interface engine, and endpoint buffer memory. The serial interface engine decodes the USB data stream and writes data to the appropriate endpoint buffer. The status of a completed USB transfer or error condition is indicated via status registers. An interrupt is also generated if enabled.

#### 8.14.1.1 Features

- Dedicated USB PLL available.
- Fully compliant with USB 2.0 specification (full speed).
- Supports 10 physical (5 logical) endpoints including one control endpoint.
- Single and double buffering supported.
- Each non-control endpoint supports bulk, interrupt, or isochronous endpoint types.
- Supports wake-up from Deep-sleep mode and Power-down mode on USB activity and remote wake-up.
- Supports SoftConnect functionality through internal pull-up resistor.
- Internal 33  $\Omega$  series termination resistors on USB\_DP and USB\_DM lines eliminate the need for external series resistors.
- Supports Link Power Management (LPM).
- Supports XTAL-less low-speed mode using the 1% accurate IRC as the clock source for the USB PLL. For board connection changes in low-speed mode, see <u>Section</u> 14.3.1 "USB Low-speed operation".

# 8.15 USART0

**Remark:** The LPC11U6x contains two distinctive types of UART interfaces: USART0 is software-compatible with the USART interface on the LPC11U1x/LPC11U2x/LPC11U3x parts. USART1 to USART4 use a different register interface.

The USART0 includes full modem control, support for synchronous mode, and a smart card interface. The RS-485/9-bit mode allows both software address detection and automatic address detection using 9-bit mode.

The USART0 uses a fractional baud rate generator. Standard baud rates such as 115200 Bd can be achieved with any crystal frequency above 2 MHz.

### 8.15.1 Features

- Maximum USART0 data bit rate of 3.125 Mbit/s in asynchronous mode and 10 Mbit/s in synchronous slave and master mode.
- 16 byte receive and transmit FIFOs.
- Register locations conform to 16C550 industry standard.
- Receiver FIFO trigger points at 1 B, 4 B, 8 B, and 14 B.
- Built-in fractional baud rate generator covering wide range of baud rates without a need for external crystals of particular values.
- Fractional divider for baud rate control, auto baud capabilities and FIFO control mechanism that enables software flow control implementation.
- Support for RS-485/9-bit mode.
- Support for modem control.
- Support for synchronous mode.
- Includes smart card interface.
- DMA support.

### 8.16 USART1/2/3/4

**Remark:** The LPC11U6x contains two distinctive types of UART interfaces: USART0 is software-compatible with the USART interface on the LPC11U1x/LPC11U2x/LPC11U3x parts. USART1 to USART4 use a different register interface to achieve the same UART functionality except for modem and smart card control.

Remark: USART3 and USART4 are available only on part LPC11U68JBD100.

Interrupts generated by the USART1/2/3/4 peripherals can wake up the part from Deep-sleep and power-down modes if the USART is in synchronous mode, the 32 kHz mode is enabled, or the CTS interrupt is enabled. This wake-up mechanism is not available with the USART0 peripheral.

#### 8.16.1 Features

- Maximum bit rates of 3.125 Mbit/s in asynchronous mode and 10 Mbit/s in synchronous mode.
- 7, 8, or 9 data bits and 1 or 2 stop bits
- Synchronous mode with master or slave operation. Includes data phase selection and continuous clock option.
- Multiprocessor/multidrop (9-bit) mode with software-address compare feature. (RS-485 possible with software address detection and transceiver direction control.)
- RS-485 transceiver output enable.
- Autobaud mode for automatic baud rate detection
- Parity generation and checking: odd, even, or none.
- One transmit and one receive data buffer.
- RTS/CTS for hardware signaling for automatic flow control. Software flow control can be performed using Delta CTS detect, Transmit Disable control, and any GPIO as an RTS output.

- Received data and status can optionally be read from a single register
- Break generation and detection.
- Receive data is 2 of 3 sample "voting". Status flag set when one sample differs.
- Built-in Baud Rate Generator with auto-baud function.
- A fractional rate divider is shared among all USARTs.
- Interrupts available for Receiver Ready, Transmitter Ready, Receiver Idle, change in receiver break detect, Framing error, Parity error, Overrun, Underrun, Delta CTS detect, and receiver sample noise detected.
- Loopback mode for testing of data and flow control.
- In synchronous slave mode, wakes up the part from deep-sleep and power-down modes.
- Special operating mode allows operation at up to 9600 baud using the 32 kHz RTC oscillator as the UART clock. This mode can be used while the device is in Deep-sleep or Power-down mode and can wake up the device when a character is received.
- USART transmit and receive functions work with the system DMA controller.

# 8.17 SSP serial I/O controller (SSP0/1)

The SSP controllers operate on a SSP, 4-wire SSI, or Microwire bus. The controller can interact with multiple masters and slaves on the bus. Only a single master and a single slave can communicate on the bus during a given data transfer. The SSP supports full duplex transfers, with frames of 4 bit to 16 bit of data flowing from the master to the slave and from the slave to the master. In practice, often only one direction carries meaningful data.

#### 8.17.1 Features

- Maximum SSP speed of 25 Mbit/s (master) or 4.17 Mbit/s (slave) (in SSP mode)
- Compatible with Motorola SPI (Serial Peripheral Interface), 4-wire Texas Instruments SSI (Serial Synchronous Interface), and National Semiconductor Microwire buses
- Synchronous serial communication
- Master or slave operation
- 8-frame FIFOs for both transmit and receive
- 4-bit to 16-bit frame
- DMA support

# 8.18 I<sup>2</sup>C-bus serial I/O controller

The LPC11U6x contain two I<sup>2</sup>C-bus controllers.

The I<sup>2</sup>C-bus is bidirectional for inter-IC control using only two wires: a Serial Clock line (SCL) and a Serial Data line (SDA). Each device is recognized by a unique address and can operate as either a receiver-only device (e.g., an LCD driver) or a transmitter with the capability to both receive and send information (such as memory). Transmitters and/or receivers can operate in either master or slave mode, depending on whether the chip has to initiate a data transfer or is only addressed. The I<sup>2</sup>C is a multi-master bus and can be controlled by more than one bus master connected to it.

# 8.18.1 Features

- One I<sup>2</sup>C-interface (I2C0) is an I<sup>2</sup>C-bus compliant interface with open-drain pins. The I<sup>2</sup>C-bus interface supports Fast-mode Plus with bit rates up to 1 Mbit/s.
- One I<sup>2</sup>C-interface (I2C1) uses standard digital pins. The I<sup>2</sup>C-bus interface supports bit rates up to 400 kbit/s.
- Easy to configure as master, slave, or master/slave.
- Programmable clocks allow versatile rate control.
- Bidirectional data transfer between masters and slaves.
- Multi-master bus (no central master).
- Arbitration between simultaneously transmitting masters without corruption of serial data on the bus.
- Serial clock synchronization allows devices with different bit rates to communicate via one serial bus.
- Serial clock synchronization can be used as a handshake mechanism to suspend and resume serial transfer.
- The I<sup>2</sup>C-bus can be used for test and diagnostic purposes.
- The I<sup>2</sup>C-bus controller supports multiple address recognition and a bus monitor mode.

# 8.19 Timer/PWM subsystem

Four standard timers and two state configurable timers can be combined to create multiple PWM outputs using the match outputs and the match registers for each timer. Each timer can create multiple PWM outputs with its own time base.

PWM outputs			Peripheral	Pin functions available for PWM			Match registers
LQFP100	LQFP64	LQFP48	-	LQFP100	LQFP64	LQFP48	used
3	3	3	CT16B0	CT16B0_MAT0, CT16B0_MAT1, CT16B0_MAT2	CT16B0_MAT0, CT16B0_MAT1, CT16B0_MAT2	CT16B0_MAT0, CT16B0_MAT1, CT16B0_MAT2	4
2	2	2	CT16B1	CT16B1_MAT0, CT16B1_MAT1	CT16B1_MAT0, CT16B1_MAT1	CT16B1_MAT0, CT16B1_MAT1	3
3	3	3	CT32B0	three of CT32B0_MAT0, CT32B0_MAT1, CT32B0_MAT2, CT32B0_MAT3	three of CT32B0_MAT0, CT32B0_MAT1, CT32B0_MAT2, CT32B0_MAT3	three of CT32B0_MAT0, CT32B0_MAT1, CT32B0_MAT2, CT32B0_MAT3	4

#### Table 4. PWM resources

PWM outputs			Peripheral	Pin functions available for PWM			Match registers
LQFP100	LQFP64	LQFP48	-	LQFP100	LQFP64	LQFP48	used
3	3	3	CT32B1	three of CT32B1_MAT0, CT32B1_MAT1, CT32B1_MAT2, CT32B1_MAT3	three of CT32B1_MAT0, CT32B1_MAT1, CT32B1_MAT2, CT32B1_MAT3	three of CT32B1_MAT0, CT32B1_MAT1, CT32B1_MAT2, CT32B1_MAT3	4
4	4	3	SCTIMER0/ PWM	SCT0_OUT0, SCT0_OUT1, SCT0_OUT2, SCT0_OUT3	SCT0_OUT0, SCT0_OUT1, SCT0_OUT2, SCT0_OUT3	SCT0_OUT1, SCT0_OUT2, SCT0_OUT3	up to 5
4	2	-	SCTIMER1/ PWM	SCT1_OUT0, SCT1_OUT1, SCT1_OUT2, SCT1_OUT3	SCT1_OUT2, SCT1_OUT3	· · · · · · · · · · · · · · · · · · ·	

#### Table 4. PWM resources ...continued

The standard timers and the SCTimers combine to up to eight independent timers. Each SCTimer can be configured either as one 32-bit timer or two independently counting 16-bit timers which use the same input clock. The following combinations are possible:

#### Table 5.Timer configurations

32-bit timers	Resources	16-bit timers	Resources
4	CT32B0, CT32B1, SCTimer0/PWM as 32-bit timer, SCTimer1/PWM as 32-bit timer	2	CT16B0, CT16B1
2	CT32B0, CT32B1	6	CT16B0, CT16B1, SCTimer0/PWM as two 16-bit timers, SCTimer1/PWM as two 16-bit timers
3	CT32B0, CT32B1, SCTimer0/PWM as 32-bit timer (or SCTimer1/PWM as 32-bit timer)	4	CT16B0, CT16B1, SCTimer1/PWM as two 16-bit timers (or SCTimer0/PWM as two 16-bit timers)

#### 8.19.1 State Configurable Timers (SCTimer0/PWM and SCTimer1/PWM)

The state configurable timer can create timed output signals such as PWM outputs triggered by programmable events. Combinations of events can be used to define timer states. The SCTimer/PWM can control the timer operations, capture inputs, change states, and toggle outputs triggered only by events entirely without CPU intervention.

If multiple states are not implemented, the SCTimer/PWM simply operates as one 32-bit or two 16-bit timers with match, capture, and PWM functions.

#### 8.19.1.1 Features

- Each SCTimer/PWM supports:
  - 5 match/capture registers.
  - 6 events.
  - 8 states.
  - 4 inputs and 4 outputs.
- Counter/timer features:
  - Each SCTimer is configurable as two 16-bit counters or one 32-bit counter.
  - Counters can be clocked by the system clock or selected input.
  - Configurable as up counters or up-down counters.
  - Configurable number of match and capture registers. Up to five match and capture registers total.
  - Upon match create the following events: interrupt; stop, limit, halt the timer or change counting direction; toggle outputs.
  - Counter value can be loaded into capture register triggered by a match or input/output toggle.
- PWM features:
  - Counters can be used with match registers to toggle outputs and create time-proportioned PWM signals.
  - Up to four single-edge or dual-edge PWM outputs with independent duty cycle and common PWM cycle length.
- Event creation features:
  - The following conditions define an event: a counter match condition, an input (or output) condition such as a rising or falling edge or level, a combination of match and/or input/output condition.
  - Selected events can limit, halt, start, or stop a counter or change its direction.
  - Events trigger state changes, output toggles, interrupts, and DMA transactions.
  - Match register 0 can be used as an automatic limit.
  - In bidirectional mode, events can be enabled based on the count direction.
  - Match events can be held until another qualifying event occurs.
- State control features:
  - A state is defined by events that can happen in the state while the counter is running.
  - A state changes into another state as a result of an event.
  - Each event can be assigned to one or more states.
  - State variable allows sequencing across multiple counter cycles.
- SCTimer match outputs (ORed with the general-purpose timer match outputs) serve as ADC hardware trigger inputs.

# 8.19.2 General purpose external event counter/timers (CT32B0/1 and CT16B0/1)

The LPC11U6x includes two 32-bit counter/timers and two 16-bit counter/timers. The counter/timer is designed to count cycles of the system derived clock. It can optionally generate interrupts or perform other actions at specified timer values, based on four match registers. Each counter/timer also includes one capture input to trap the timer value when an input signal transitions, optionally generating an interrupt.

#### 8.19.2.1 Features

- A 32-bit/16-bit timer/counter with a programmable 32-bit/16-bit prescaler.
- Counter or timer operation.
- One capture channel per timer, that can take a snapshot of the timer value when an input signal transitions. A capture event may also generate an interrupt.
- Four match registers per timer that allow:
  - Continuous operation with optional interrupt generation on match.
  - Stop timer on match with optional interrupt generation.
  - Reset timer on match with optional interrupt generation.
- Up to four external outputs corresponding to match registers, with the following capabilities:
  - Set LOW on match.
  - Set HIGH on match.
  - Toggle on match.
  - Do nothing on match.
- The timer and prescaler may be configured to be cleared on a designated capture event. This feature permits easy pulse-width measurement by clearing the timer on the leading edge of an input pulse and capturing the timer value on the trailing edge.
- PWM output function.
- Match outputs and capture inputs serve as hardware triggers for ADC conversions.

# 8.20 System tick timer (SysTick)

The ARM Cortex-M0+ includes a system tick timer (SYSTICK) that is intended to generate a dedicated SYSTICK exception at a fixed time interval (typically 10 ms).

# 8.21 Windowed WatchDog Timer (WWDT)

The purpose of the WWDT is to prevent an unresponsive system state. If software fails to update the watchdog within a programmable time window, the watchdog resets the microcontroller

#### 8.21.1 Features

- Internally resets chip if not periodically reloaded during the programmable time-out period.
- Optional windowed operation requires reload to occur between a minimum and maximum time period, both programmable.

I PC11U6x

- Optional warning interrupt can be generated at a programmable time before watchdog time-out.
- Software enables the WWDT, but a hardware reset or a watchdog reset/interrupt is required to disable the WWDT.
- Incorrect feed sequence causes reset or interrupt, if enabled.
- Flag to indicate watchdog reset.
- Programmable 24-bit timer with internal prescaler.
- Selectable time period from  $(T_{cy(WDCLK)} \times 256 \times 4)$  to  $(T_{cy(WDCLK)} \times 2^{24} \times 4)$  in multiples of  $T_{cy(WDCLK)} \times 4$ .
- The WatchDog Clock (WDCLK) source can be selected from the IRC or the dedicated watchdog oscillator (WDOsc). The clock source selection provides a wide range of potential timing choices of watchdog operation under different power conditions.

# 8.22 Real-Time Clock (RTC)

The RTC resides in a separate always-on voltage domain with battery back-up. The RTC uses an independent oscillator, also located in the always-on voltage domain.

#### 8.22.1 Features

- 32-bit, 1 Hz RTC counter and associated match register for alarm generation.
- Separate 16-bit high-resolution/wake-up timer clocked at 1 kHz for 1 ms resolution with a more that one minute maximum time-out period.
- RTC alarm and high-resolution/wake-up timer time-out each generate independent interrupt requests. Either time-out can wake up the part from any of the low-power modes, including Deep power-down.

# 8.23 Analog-to-Digital Converter (ADC)

The ADC supports a resolution of 12 bit and fast conversion rates of up to 2 MSamples/s. Sequences of analog-to-digital conversions can be triggered by multiple sources. Possible trigger sources are the counter/timer match outputs and capture inputs and the ARM TXEV.

The ADC includes a hardware threshold compare function with zero-crossing detection.

#### 8.23.1 Features

- 12-bit successive approximation analog to digital converter.
- 12-bit conversion rate of up to 2 MSamples/s.
- Temperature sensor voltage output selectable as internal voltage source for channel 0.
- Two configurable conversion sequences with independent triggers.
- Optional automatic high/low threshold comparison and zero-crossing detection.
- Power-down mode and low-power operating mode.
- Measurement range VREFN to VREFP (typically 3 V; not to exceed V<sub>DDA</sub> voltage level).
- Burst conversion mode for single or multiple inputs.

# 8.24 Temperature sensor

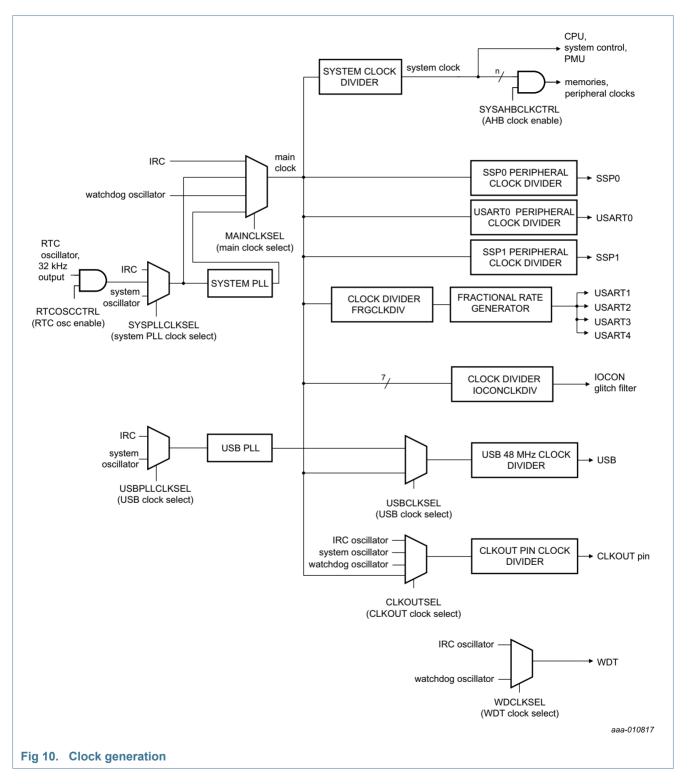
The temperature sensor transducer uses an intrinsic pn-junction diode reference and outputs a CTAT voltage (Complement To Absolute Temperature). The output voltage varies inversely with device temperature with an absolute accuracy of better than  $\pm$ 5 °C over the full temperature range (-40 °C to +105 °C) for typical samples. The temperature sensor is approximately linear with a slight curvature. The output voltage is measured over different ranges of temperatures and fit with linear-least-square lines.

After power-up and after switching the input channels of the ADC, the temperature sensor output must be allowed to settle to its stable value before it can be used as an accurate ADC input.

For an accurate measurement of the temperature sensor by the ADC, the ADC must be configured in single-channel burst mode. The last value of a nine-conversion (or more) burst provides an accurate result.

# 8.25 Clocking and power control

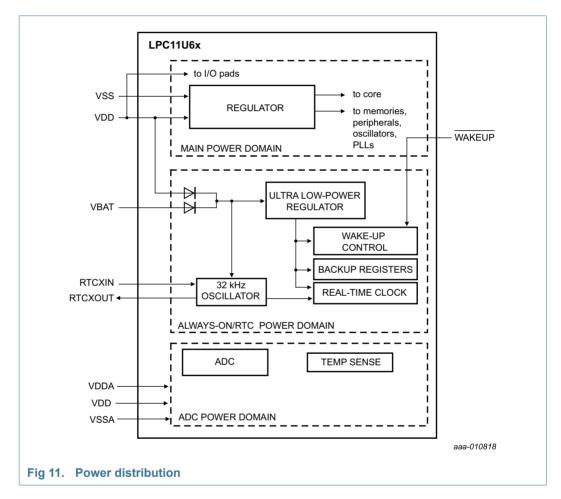
# 8.25.1 Clock generation



## 8.25.2 Power domains

The LPC11U6x provide two independent power domains that allow the bulk of the device to have power removed while maintaining operation of the RTC and the backup registers.

The VBAT pin supplies power only to the RTC domain. The RTC requires a minimum of power to operate, which can be supplied by an external battery. The device core power (V<sub>DD</sub>) is used to operate the RTC whenever V<sub>DD</sub> is present. Therefore, there is no power drain from the RTC battery when V<sub>DD</sub> is available and V<sub>DD</sub>  $\geq$  VBAT + 0.3 V.



## 8.25.3 Integrated oscillators

The LPC11U6x include the following independent oscillators: the system oscillator, the Internal RC oscillator (IRC), the watchdog oscillator, and the 32 kHz RTC oscillator. Each oscillator can be used for more than one purpose as required in a particular application.

Following reset, the LPC11U6x operates from the internal RC oscillator until software switches to a different clock source. The IRC allows the system to operate without any external crystal and the bootloader code to operate at a known frequency.

See Figure 10 for an overview of the LPC11U6x clock generation.

## 8.25.3.1 Internal RC oscillator

The IRC can be used as the clock source for the WDT, the USB PLL in low-speed USB applications, or as the clock that drives the system PLL and then the CPU. The nominal IRC frequency is 12 MHz.

Upon power-up, any chip reset, or wake-up from Deep power-down mode, the LPC11U6x use the IRC as the clock source. Software can later switch to one of the other available clock sources.

#### 8.25.3.2 System oscillator

The system oscillator can be used as the clock source for the CPU, with or without using the PLL. Use the system oscillator to provide the clock source to USB.

The system oscillator operates at frequencies of 1 MHz to 25 MHz. This frequency can be boosted to a higher frequency, up to the maximum CPU operating frequency, by the system PLL.

The system oscillator has a wake-up time of approximately 500 µs.

#### 8.25.3.3 WatchDog oscillator

The watchdog oscillator can be used as a clock source that directly drives the CPU, the watchdog timer, or the CLKOUT pin. The watchdog oscillator nominal frequency is programmable between 9.4 kHz and 2.3 MHz. The frequency spread over processing and temperature is  $\pm 40$  % (see also Table 14).

#### 8.25.3.4 RTC oscillator

The low-power RTC oscillator provides a 1 Hz clock and a 1 kHz clock to the RTC and a 32 kHz clock output that can be used to obtain the main clock (see Figure 10).

## 8.25.4 System PLL and USB PLL

The LPC11U6x contain a system PLL and a dedicated PLL for generating the 48 MHz USB clock. The system and USB PLLs are identical.

The PLL accepts an input clock frequency in the range of 10 MHz to 25 MHz. The input frequency is multiplied up to a high frequency with a Current Controlled Oscillator (CCO). The multiplier can be an integer value from 1 to 32. The CCO operates in the range of 156 MHz to 320 MHz. To support this frequency range, an additional divider keeps the CCO within its frequency range while the PLL is providing the desired output frequency. The output divider can be set to divide by 2, 4, 8, or 16 to produce the output clock. The PLL output frequency must be lower than 100 MHz. Since the minimum output divider value is 2, it is insured that the PLL output has a 50 % duty cycle. The PLL is turned off and bypassed following a chip reset. Software can enable the PLL later. The program must configure and activate the PLL, wait for the PLL to lock, and then connect to the PLL as a clock source. The PLL settling time is 100  $\mu$ s.

## 8.25.5 Clock output

The LPC11U6x feature a clock output function that routes the IRC oscillator, the system oscillator, the watchdog oscillator, or the main clock to an output pin.

## 8.25.6 Wake-up process

The LPC11U6x begin operation by using the 12 MHz IRC oscillator as the clock source at power-up and when awakened from Deep power-down mode. This mechanism allows chip operation to resume quickly. If the application uses the main oscillator or the PLL, software must enable these components and wait for them to stabilize. Only then can the system use the PLL and main oscillator as a clock source.

## 8.25.7 Power control

The LPC11U6x support various power control features. There are four special modes of processor power reduction: Sleep mode, Deep-sleep mode, Power-down mode, and Deep power-down mode. The CPU clock rate can also be controlled as needed by changing clock sources, reconfiguring PLL values, and/or altering the CPU clock divider value. This power control mechanism allows a trade-off of power versus processing speed based on application requirements. In addition, a register is provided for shutting down the clocks to individual on-chip peripherals. This register allows fine-tuning of power consumption by eliminating all dynamic power use in any peripherals that are not required for the application. Selected peripherals have their own clock divider which provides even better power control.

## 8.25.7.1 Power profiles

The power consumption in Active and Sleep modes can be optimized for the application through simple calls to the power profile. The power configuration routine configures the LPC11U6x for one of the following power modes:

- Default mode corresponding to power configuration after reset.
- · CPU performance mode corresponding to optimized processing capability.
- Efficiency mode corresponding to optimized balance of current consumption and CPU performance.
- Low-current mode corresponding to lowest power consumption.

In addition, the power profile includes routines to select the optimal PLL settings for a given system clock and PLL input clock.

**Remark:** When using the USB, configure the LPC11U6x in Default mode.

#### 8.25.7.2 Sleep mode

When Sleep mode is entered, the clock to the core is stopped. Resumption from the Sleep mode does not need any special sequence but re-enabling the clock to the ARM core.

In Sleep mode, execution of instructions is suspended until either a reset or interrupt occurs. Peripheral functions continue operation during Sleep mode and can generate interrupts to cause the processor to resume execution. Sleep mode eliminates dynamic power used by the processor itself, by memory systems and related controllers, and by internal buses.

## 8.25.7.3 Deep-sleep mode

In Deep-sleep mode, the LPC11U6x core is in Sleep mode and all peripheral clocks and all clock sources are off except for the IRC. The IRC output is disabled unless the IRC is selected as input to the watchdog timer. In addition, all analog blocks are shut down and the flash is in standby mode. In Deep-sleep mode, the application can keep the watchdog oscillator and the BOD circuit running for self-timed wake-up and BOD protection.

The LPC11U6x can wake up from Deep-sleep mode via reset, selected GPIO pins, a watchdog timer interrupt, an interrupt generating USB port activity, an RTC interrupt, or any interrupts that the USART1 to USART4 interfaces can create in Deep-sleep mode. The USART wake-up requires the 32 kHz mode, the synchronous mode, or the CTS interrupt to be set up.

Deep-sleep mode saves power and allows for short wake-up times.

#### 8.25.7.4 Power-down mode

In Power-down mode, the LPC11U6x is in Sleep mode and all peripheral clocks and all clock sources are off except for watchdog oscillator if selected. In addition, all analog blocks and the flash are shut down. In Power-down mode, the application can keep the BOD circuit running for BOD protection.

The LPC11U6x can wake up from Power-down mode via reset, selected GPIO pins, a watchdog timer interrupt, an interrupt generating USB port activity, an RTC interrupt, or any interrupts that the USART1 to USART4 interfaces can create in Power-down mode. The USART wake-up requires the 32 kHz mode, the synchronous mode, or the CTS interrupt to be set up.

Power-down mode reduces power consumption compared to Deep-sleep mode at the expense of longer wake-up times.

#### 8.25.7.5 Deep power-down mode

In Deep power-down mode, power is shut off to the entire chip except for the WAKEUP pin and the always-on RTC power domain. The LPC11U6x can wake up from Deep power-down mode via the WAKEUP pin or a wake-up signal generated by the RTC interrupt.

The LPC11U6x can be blocked from entering Deep power-down mode by setting a lock bit in the PMU block. Blocking the Deep power-down mode enables the application to keep the watchdog timer or the BOD running at all times.

If the WAKEUP pin is used in the application, an external pull-up resistor is required on the WAKEUP pin to hold it HIGH while the part is in deep power-down mode. To wake up from deep power-down mode, pull the WAKEUP pin LOW. In addition, pull the RESET pin HIGH to prevent it from floating while in Deep power-down mode.

## 8.26 System control

## 8.26.1 Reset

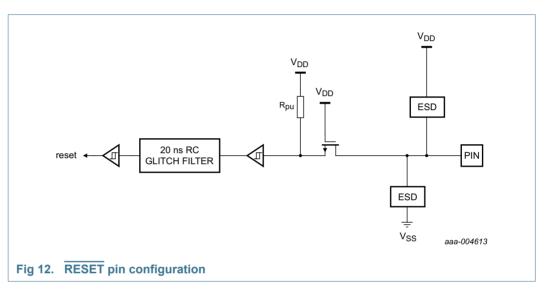
Reset has four sources on the LPC11U6x: the RESET pin, the WatchDog reset, power-on reset (POR), and the BrownOut Detection (BOD) circuit. The RESET pin is a Schmitt trigger input pin. Assertion of chip reset by any source, once the operating voltage attains a usable level, starts the IRC and initializes the flash controller.

I PC11U6x

When the internal Reset is removed, the processor begins executing at address 0, which is initially the Reset vector mapped from the boot block. At that point, all of the processor and peripheral registers have been initialized to predetermined values. The internal reset status is reflected on the RSTOUT pin.

In Deep power-down mode, an external pull-up resistor is required on the  $\overline{\text{RESET}}$  pin.

The RESET pin is operational in active, sleep, deep-sleep, and power-down modes if the RESET function is selected in the IOCON register for pin PIO0\_0 (this is the default). A LOW-going pulse as short as 50 ns executes the reset and also wakes up the part if in sleep, deep-sleep or power-down mode. The RESET pin is not functional in Deep power-down mode.



## 8.26.2 Brownout detection

The LPC11U6x includes two levels for monitoring the voltage on the V<sub>DD</sub> pin. If this voltage falls below one of the selected levels, the BOD asserts an interrupt signal to the NVIC. This signal can be enabled for interrupt in the Interrupt Enable Register in the NVIC to cause a CPU interrupt. Alternatively, software can monitor the signal by reading a dedicated status register. Two threshold levels can be selected to cause a forced reset of the chip.

## 8.26.3 Code security (Code Read Protection - CRP)

CRP provides different levels of security in the system so that access to the on-chip flash and use of the Serial Wire Debugger (SWD) and In-System Programming (ISP) can be restricted. Programming a specific pattern into a dedicated flash location invokes CRP. IAP commands are not affected by the CRP.

In addition, ISP entry via the PIO0\_1 pin can be disabled without enabling CRP. For details, see the *LPC11Uxx user manual*.

There are three levels of Code Read Protection:

LPC11U6x

- 1. CRP1 disables access to the chip via the SWD and allows partial flash update (excluding flash sector 0) using a limited set of the ISP commands. This mode is useful when CRP is required and flash field updates are needed but all sectors cannot be erased.
- 2. CRP2 disables access to the chip via the SWD and only allows full flash erase and update using a reduced set of the ISP commands.
- 3. Running an application with level CRP3 selected, fully disables any access to the chip via the SWD pins and the ISP. This mode effectively disables ISP override using PIO0\_1 pin as well. If necessary, the application must provide a flash update mechanism using IAP calls or using a call to the reinvoke ISP command to enable flash update via the USART.

#### CAUTION



If level three Code Read Protection (CRP3) is selected, no future factory testing can be performed on the device.

In addition to the three CRP levels, sampling of pin PIO0\_1 for valid user code can be disabled. For details, see the *LPC11U6x user manual*.

## 8.27 Emulation and debugging

Debug functions are integrated into the ARM Cortex-M0+. Serial wire debug functions are supported in addition to a standard JTAG boundary scan. The ARM Cortex-M0+ is configured to support up to four breakpoints and two watch points.

The  $\overline{\text{RESET}}$  pin selects between the JTAG boundary scan ( $\overline{\text{RESET}}$  = LOW) and the ARM SWD debug ( $\overline{\text{RESET}}$  = HIGH). The ARM SWD debug port is disabled while the LPC11U6x is in reset.

To perform boundary scan testing, follow these steps:

- 1. Erase any user code residing in flash.
- 2. Power up the part with the  $\overline{\text{RESET}}$  pin pulled HIGH externally.
- 3. Wait for at least 250  $\mu$ s.
- 4. Pull the  $\overline{\text{RESET}}$  pin LOW externally.
- 5. Perform boundary scan operations.
- 6. Once the boundary scan operations are completed, assert the TRST pin to enable the SWD debug mode, and release the RESET pin (pull HIGH).

**Remark:** The JTAG interface cannot be used for debug purposes.

# 9. Limiting values

#### Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).[1]

Symbol	Parameter	Conditions	Min	Мах	Unit
V <sub>DD</sub>	supply voltage	[2]	-0.5	4.6	V
V <sub>DDA</sub>	analog supply voltage		-0.5	4.6	V
V <sub>ref</sub>	reference voltage	on pin VREFP	-0.5	4.6	V
V <sub>BAT</sub>	battery supply voltage		-0.5	4.6	V
Vı	input voltage		-0.5	+5.5	V
		on open-drain [5] I2C-bus pins PIO0_4 and PIO0_5	-0.5	+5.5	V V V V V V V V V V mA mA mA
		USB_DM, USB_DP pins	-0.5	V <sub>DD</sub> + 0.5	V
VIA	analog input voltage	[6] [7]	-0.5	4.6	V
V <sub>i(xtal)</sub>	crystal input voltage	pins configured for [2] XTALIN and XTALOUT	-0.5	+2.5	V
V <sub>i(rtcx)</sub>	32 kHz oscillator input voltage	[2]	-0.5	4.6	V
I <sub>DD</sub>	supply current	per supply pin	-	100	mA
I <sub>SS</sub>	ground current	per ground pin	-	100	mA
I <sub>latch</sub>	I/O latch-up current	-(0.5 V <sub>DD(IO)</sub> ) < V <sub>I</sub> < (1.5 V <sub>DD(IO)</sub> ); T <sub>j</sub> < 125 °C	-	100	mA
T <sub>stg</sub>	storage temperature	[8]	-65	+150	°C
T <sub>j(max)</sub>	maximum junction temperature		-	150	°C
P <sub>tot(pack)</sub>	total power dissipation (per package)	based on package heat transfer, not device power consumption	-	1.5	W
V <sub>esd</sub>	electrostatic discharge voltage	human body [9] model; all pins	-	3	kV

[1] The following applies to the limiting values:

a) This product includes circuitry specifically designed for the protection of its internal devices from the damaging effects of excessive static charge. Nonetheless, it is suggested that conventional precautions be taken to avoid applying greater than the rated maximum.

b) Parameters are valid over operating temperature range unless otherwise specified. All voltages are with respect to V<sub>SS</sub> unless otherwise noted.

[2] Maximum/minimum voltage above the maximum operating voltage (see <u>Table 8</u>) and below ground that can be applied for a short time (< 10 ms) to a device without leading to irrecoverable failure. Failure includes the loss of reliability and shorter lifetime of the device.

[3] Applies to all 5 V tolerant I/O pins except true open-drain pins PIO0\_4 and PIO0\_5.

- [4] Including the voltage on outputs in 3-state mode.
- [5] V<sub>DD(IO)</sub> present or not present. Compliant with the I<sup>2</sup>C-bus standard. 5.5 V can be applied to this pin when V<sub>DD(IO)</sub> is powered down.
- [6] An ADC input voltage above 3.6 V can be applied for a short time without leading to immediate, unrecoverable failure. Accumulated exposure to elevated voltages at 4.6 V must be less than 10<sup>6</sup> s total over the lifetime of the device. Applying an elevated voltage to the ADC inputs for a long time affects the reliability of the device and reduces its lifetime.
- [7] It is recommended to connect an overvoltage protection diode between the analog input pin and the voltage supply pin.
- [8] Dependent on package type.
- [9] Human body model: equivalent to discharging a 100 pF capacitor through a 1.5 kΩ series resistor.

## **10. Thermal characteristics**

The average chip junction temperature,  $T_j$  (°C), can be calculated using the following equation:

$$T_{j} = T_{amb} + (P_{D} \times R_{th(j-a)}) \tag{1}$$

- T<sub>amb</sub> = ambient temperature (°C),
- R<sub>th(i-a)</sub> = the package junction-to-ambient thermal resistance (°C/W)
- P<sub>D</sub> = sum of internal and I/O power dissipation

The internal power dissipation is the product of  $I_{DD}$  and  $V_{DD}$ . The I/O power dissipation of the I/O pins is often small and many times can be negligible. However it can be significant in some applications.

Symbol	Parameter	Conditions	Тур	Unit
LQFP48			I	
θja	thermal resistance			
	junction-to-ambient	JEDEC (4.5 in × 4 in)		
		0 m/s	67	°C/W
		1 m/s	58	°C/W
		2.5 m/s	53	°C/W
		8-layer (4.5 in $\times$ 3 in)		
		0 m/s	100	°C/W
		1 m/s	79	°C/W
		2.5 m/s	71	°C/W
өјс	thermal resistance junction-to-case		15	°C/W
θjb	thermal resistance junction-to-board		19	°C/W

#### Table 7. Thermal resistance value (C/W): ±15 %

Symbol	Parameter	Conditions	Тур	Unit
LQFP64		1	I	
өја	thermal resistance			
	junction-to-ambient	JEDEC (4.5 in × 4 in)		
		0 m/s	58	°C/W
		1 m/s	51	°C/W
		2.5 m/s	47	°C/W
		8-layer (4.5 in $\times$ 3 in)		
		0 m/s	81	°C/W
		1 m/s	66	°C/W
		2.5 m/s	60	°C/W
өјс	thermal resistance junction-to-case		18	°C/W
θjb	thermal resistance junction-to-board		23	°C/W
LQFP100	)	,		
θja	thermal resistance			
	junction-to-ambient	JEDEC (4.5 in × 4 in)		
		0 m/s	49	°C/W
		1 m/s	44	°C/W
		2.5 m/s	41	°C/W
		8-layer (4.5 in $\times$ 3 in)		
		0 m/s	66	°C/W
		1 m/s	55	°C/W
		2.5 m/s	51	°C/W
өјс	thermal resistance junction-to-case		18	°C/W
θjb	thermal resistance junction-to-board		24	°C/W

#### Table 7. Thermal resistance value (C/W): ±15 %

# **11. Static characteristics**

#### Table 8. Static characteristics

 $T_{amb} = -40 \circ C$  to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V <sub>DD</sub>	supply voltage (core and external rail)	[2]	2.4	3.3	3.6	V
V <sub>DDA</sub>	analog supply voltage		2.4	3.3	3.6	V
V <sub>ref</sub>	reference voltage	on pin VREFP	2.4	-	V <sub>DDA</sub>	V
V <sub>BAT</sub>	battery supply voltage		2.4	3.3	3.6	V

**LPC11U6x** 

#### Table 8. Static characteristics ...continued

 $T_{amb}$  = -40 °C to +105 °C, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Typ[1]	Мах	Unit
I <sub>DD</sub>	supply current	Active mode; code					
		while(1){}					
		executed from flash					
		system clock = 12 MHz; default mode; V <sub>DD</sub> = 3.3 V	[3][4][5] [7][8]	-	2.3	-	mA
		system clock = 12 MHz; low-current mode; V <sub>DD</sub> = 3.3 V	[3][4][5] [7][8]	-	1.5	-	mA
		system clock = 50 MHz; default mode; V <sub>DD</sub> = 3.3 V	[3][4][7] [8][10]	-	7.8	-	mA
		system clock = 50 MHz; low-current mode; V <sub>DD</sub> = 3.3 V	[3][4][7] [8][10]	-	6.4	-	mA
DD	supply current	Sleep mode;					
		system clock = 12 MHz; default mode; V <sub>DD</sub> = 3.3 V	[3][4][5] [7][8]	-	1.2	-	mA
		system clock = 12 MHz; low-current mode; V <sub>DD</sub> = 3.3 V	[3][4][5] [7][8]	-	0.8	-	mA
		system clock = 50 MHz; default mode; V <sub>DD</sub> = 3.3 V	[3][4][10] [7][8]	-	3.3	-	mA
		system clock = 50 MHz; low-current mode; V <sub>DD</sub> = 3.3 V	[3][4][10] [7][8]	-	2.8	-	mA
I <sub>DD</sub>	supply current	Deep-sleep mode; $V_{DD} = 3.3 V;$	[3][4][11]	-	275	350	μA
		T <sub>amb</sub> = 25 °C					
		T <sub>amb</sub> = 105 °C		-	-	640	μA
I <sub>DD</sub>	supply current	Power-down mode; $V_{DD} = 3.3 V$	[3][4][11]	-	5	22	μA
		T <sub>amb</sub> = 25 °C					
		T <sub>amb</sub> = 105 °C		-	-	130	μA
I <sub>DD</sub>	supply current	Deep power-down mode; $V_{DD} =$ 3.3 V; VBAT = 0 or VBAT = 3.0 V	[3][12]				
		RTC oscillator running					
		T <sub>amb</sub> = 25 °C		-	1.2	5	μA
		T <sub>amb</sub> = 105 ℃		-	-	14	
		RTC oscillator input grounded	[3][12]	-	550	-	nA
BAT	battery supply current	Deep power-down mode; $V_{DD}$ = $V_{DDA}$ = 3.3 V; VBAT = 3.0 V;		-	0	-	-
		RTC oscillator running					
		RTC off		-	0	-	-
BAT	battery supply current	$V_{DD} = V_{DDA} = 0 V$ ; VBAT = 3.0 V RTC oscillator running		-	1.2	-	μA
Standard	port pins configured as	digital pins, RESET; see Figure 13					
IIL	LOW-level input current	V <sub>I</sub> = 0 V; on-chip pull-up resistor disabled		-	0.5	10	nA

$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
ourrent         pull-up/down resistors disabled         Image: model of the mode	I <sub>IH</sub>			-	0.5	10	nA
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	I <sub>OZ</sub>			-	0.5	10	nA
Vo O O Output voltageoutput active0-Vp_DVVIHHIGH-level input voltageoutput active0.7 VbD O.7 VbDVVILLOW-level input voltage0.3 VbDVVoHHIGH-level output voltageloH = 4 mA0.05 VbD O.05 VbDVVOHHIGH-level output voltageloH = 4 mAVbD - 0.40.4VVoLLOW-level output voltageloH = 4 mA0.4VVIoHHIGH-level output currentVOH = VbD - 0.4 V;4mAIoHLOW-level output currentVoH = 0 V100-45mAIoLSLOW-level output output currentVoH = 0 V10150mAIoLSLOW-level short-circuit output currentVoH = 0 V10150150µAIoLSLOW-level short-circuit output currentVoH = 0 V; VD = 0 V; VD = 0 V;AIoLSLOW-level short-circuit output currentVoH = 0 V; VD = 0 V; VD = 0 V;-000µAIoppull-down currentVj = 0 V; VD = 0 V; VD = 0 V;50mAIopVDVD-0000µAIop<	VI	input voltage		0	-	5	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			V <sub>DD</sub> = 0 V	0	-	3.6	V
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Vo	output voltage	output active	0	-	V <sub>DD</sub>	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	V <sub>IH</sub>			0.7 V <sub>DD</sub>	-	-	V
	V <sub>IL</sub>	LOW-level input voltage		-	-	0.3 V <sub>DD</sub>	V
$ \begin{array}{ c c c c c c } \hline \begin{tabular}{ c c c c c c } \hline \begin{tabular}{ c c c c c c c } \hline \begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	V <sub>hys</sub>	hysteresis voltage		$0.05 V_{DD}$	-	-	V
voltage         <	V <sub>OH</sub>		I <sub>OH</sub> = 4 mA	$V_{DD}-0.4$	-	-	V
current<	V <sub>OL</sub>		I <sub>OL</sub> = 4 mA	-	-	0.4	V
current         <	I <sub>OH</sub>	-	$V_{OH} = V_{DD} - 0.4 V;$	4	-	-	mA
$\begin{array}{ c c c c } \hline \mbox{Normal current} & Normal $	I <sub>OL</sub>		V <sub>OL</sub> = 0.4 V	4	-	-	mA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I <sub>OHS</sub>		V <sub>OH</sub> = 0 V [16]	-	-	45	mA
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	I <sub>OLS</sub>		$V_{OL} = V_{DD}$ [16]	-	-	50	mA
$\begin{array}{ c c c c c } \hline P_{DD} & 2.4 \ V \leq V_{DD} \leq 3.6 \ V \\ \hline V_{DD} < V_{I} < 5 \ V & 0 & 0 & 0 & 0 \\ \hline W_{DD} < V_{I} < 5 \ V & 0 & 0 & 0 & 0 & \mu A \\ \hline \end{tabular}$	I <sub>pd</sub>	pull-down current	V <sub>1</sub> = 5 V	10	50	150	μA
VDD < VI < 5 V0000 $\mu A$ High-drive output pins configured as digital pin (PIO0_7 and PIO1_31); see Figure 13IILLOW-level input currentVI = 0 V; on-chip pull-up resistor disabled-0.510nAIILHIGH-level input currentVI = VDD; on-chip pull-down resistor disabled-0.510nAIILHIGH-level input currentVI = VDD; on-chip pull-down resistor disabled-0.510nAIOZOFF-state output currentVO = 0 V; VO = VDD; on-chip pull-up/down resistors disabled-0.510nAVIinput voltageVDD > 2.4 V[14] [15]0-5VVDD = 0 V0-3.6VVOoutput voltageoutput active0-3.6VVIHHIGH-level input voltageoutput active0VDDV	I <sub>pu</sub>	pull-up current	V <sub>1</sub> = 0 V;	-10	-50	-85	μA
High-drive output pins configured as digital pin (PIO0_7 and PIO1_31); see Figure 13IILLOW-level input current $V_I = 0$ V; on-chip pull-up resistor disabled-0.510nAIIHHIGH-level input current $V_I = V_{DD}$ ; on-chip pull-down resistor disabled-0.510nAIOZOFF-state output current $V_0 = 0$ V; $V_0 = V_{DD}$ ; on-chip pull-up/down resistors disabled-0.510nAIOZOFF-state output current $V_0 = 0$ V; $V_0 = V_{DD}$ ; on-chip pull-up/down resistors disabled-0.510nAVIinput voltage $V_{DD} \ge 2.4$ V[14] [15]0-5VV_DD = 0 V0-3.6VVOoutput voltageoutput active0-V_DDVVIHHIGH-level input voltageoutput active0.7 V_{DD}V			$2.4~V \leq V_{DD} \leq 3.6~V$				
IILLOW-level input current $V_1 = 0 V$ ; on-chip pull-up resistor disabled-0.510nAIIHHIGH-level input current $V_1 = V_{DD}$ ; on-chip pull-down resistor disabled-0.510nAIozOFF-state output current $V_0 = 0 V$ ; $V_0 = V_{DD}$ ; on-chip pull-up/down resistors disabled-0.510nAV_1input voltage $V_0 = 0 V$ ; $V_0 = V_{DD}$ ; on-chip pull-up/down resistors disabled-0.510nAV_1input voltage $V_{DD} \ge 2.4 V$ $\begin{bmatrix} 141\\ 15 \end{bmatrix}$ 0-5VV_DD = 0 V0-3.6VV_0output voltageoutput active0-V_DDVV_HHIGH-level input voltageoutput active0.7 $V_{DD}$ V			$V_{DD} < V_{I} < 5 V$	0	0	0	μA
Image: Section of the disableddisabledImage: Section of the disabledImage: Section of the d	High-drive	output pins configured	as digital pin (PIO0_7 and PIO1_31); see <u>F</u>	igure 13			
currentresistor disabledImage: Constraint of the sector disabledImage: Constraint of the se	IIL	LOW-level input current		-	0.5	10	nA
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	I <sub>IH</sub>	-		-	0.5	10	nA
$\frac{15}{V_{DD} = 0 \text{ V}} \qquad \qquad$	I <sub>OZ</sub>			-	0.5	10	nA
Vooutput voltageoutput active0-VDDVVIHHIGH-level input voltage-V0.7 VDD-V	VI	input voltage		0	-	5	V
VIHHIGH-level input voltage0.7 VDDV			V <sub>DD</sub> = 0 V	0	-	3.6	V
voltage	Vo	output voltage	output active	0	-	V <sub>DD</sub>	V
V <sub>IL</sub> LOW-level input voltage 0.3 V <sub>DD</sub> V	V <sub>IH</sub>			0.7 V <sub>DD</sub>	-	-	V
	V <sub>IL</sub>	LOW-level input voltage		-	-	0.3 V <sub>DD</sub>	V

#### Table 8. Static characteristics ... continued

hysteresis voltage

V<sub>hys</sub>

\_

 $0.05 V_{DD}$ 

\_

V

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
V <sub>OH</sub>	HIGH-level output	$I_{OH}$ = 12 mA; 2.4 V $\leq$ V <sub>DD</sub> $<$ 2.5 V		V <sub>DD</sub> – 0.4	-	-	V
	voltage	$I_{OH}$ = 20 mA; 2.5 V $\leq$ V <sub>DD</sub> $<$ 3.6 V		V <sub>DD</sub> – 0.4	-	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>OL</sub> = 4 mA		-	-	0.4	V
I <sub>OH</sub>	HIGH-level output current			12	-	-	mA
				20	-	-	mA
I <sub>OL</sub>	LOW-level output current	V <sub>OL</sub> = 0.4 V		4	-	-	mA
I <sub>OHS</sub>	HIGH-level short-circuit output current	V <sub>OH</sub> = 0 V [16]		-	-	45	mA
I <sub>OLS</sub>	LOW-level short-circuit output current	$V_{OL} = V_{DD}$ [16]		-	-	50	mA
I <sub>pd</sub>	pull-down current	V <sub>1</sub> = 5 V	[17]	10	50	150	μA
I <sub>pu</sub>	pull-up current	$V_{I} = 0 V$	[17]	-10	-50	-85	μA
		$V_{DD} < V_{I} < 5 V$		0	0	0	μA
l <sup>2</sup> C-bus p	ins (PIO0_4 and PIO0_5);	see Figure 13					
V <sub>IH</sub>	HIGH-level input voltage			0.7 V <sub>DD</sub>	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	0.3 V <sub>DD</sub>	V
V <sub>hys</sub>	hysteresis voltage			0.05 V <sub>DD</sub>	-	-	V
I <sub>OL</sub>	LOW-level output current	V <sub>OL</sub> = 0.4 V; I <sup>2</sup> C-bus pins configured as standard mode pins		3.5	-	-	mA
I <sub>OL</sub>	LOW-level output current	V <sub>OL</sub> = 0.4 V; I <sup>2</sup> C-bus pins configured as Fast-mode Plus pins		20	-	-	mA
ILI	input leakage current	$V_{I} = V_{DD}$	[18]	-	2	4	μA
		$V_1 = 5 V$		-	10	22	μA
USB_DM	and USB_DP pins	1		1			
VI	input voltage		[2]	0	-	V <sub>DD</sub>	V
V <sub>IH</sub>	HIGH-level input voltage			1.5	-	-	V
V <sub>IL</sub>	LOW-level input voltage			-	-	1.3	V
V <sub>hys</sub>	hysteresis voltage			0.32	-	-	V
Z <sub>out</sub>	output impedance			28	-	44	Ω
V <sub>OH</sub>	HIGH-level output voltage	With 15 k $\Omega$ resistor to ground		2.9	-	-	V
V <sub>OL</sub>	LOW-level output voltage	With internal 1.5 kΩ resistor to 3.6 V pull-up enabled		-	-	0.18	V
I <sub>OH</sub>	HIGH-level output current	$V_{OH} = V_{DD} - 0.3 V$	[19]	4.8	-	-	mA
I <sub>OL</sub>	LOW-level output current	V <sub>OL</sub> = 0.3 V	[19]	5.0	-	-	mA

#### Table 8. Static characteristics ... continued

Symbol	Parameter	Conditions		Min	Typ[1]	Max	Unit
I <sub>OLS</sub>	LOW-level short-circuit output current	drive LOW; pad connected to ground		-	-	125	mA
I <sub>OHS</sub>	HIGH-level short-circuit output current	drive HIGH; pad connected to ground		-	-	125	mA
Oscillator	pins						
V <sub>i(xtal)</sub>	crystal input voltage			-0.5	1.8	1.95	V
V <sub>o(xtal)</sub>	crystal output voltage			-0.5	1.8	1.95	V
V <sub>i(rtcx)</sub>	32 kHz oscillator input voltage	on pin RTCXIN	[20]	-0.5	-	3.6	V
V <sub>o(rtcx)</sub>	32 kHz oscillator output voltage	on pin RTCXOUT	[20]	-0.5	-	3.6	V
Pin capac	itance	1		1		1	
C <sub>io</sub>	input/output capacitance	pins with analog and digital functions	[21]	-	-	7.1	pF
		I <sup>2</sup> C-bus pins (PIO0_4 and PIO0_5)	[21]	-	-	2.5	pF
		pins with digital functions only	[21]	-	-	2.8	pF

#### Table 8. Static characteristics ... continued

 $T_{amb}$  = -40 °C to +105 °C, unless otherwise specified.

[1] Typical ratings are not guaranteed. The values listed are for room temperature (25 °C), nominal supply voltages.

[2] For USB operation:  $3.0 \text{ V} \le \text{V}_{\text{DD}} \le 3.6 \text{ V}.$ 

[3] T<sub>amb</sub> = 25 °C.

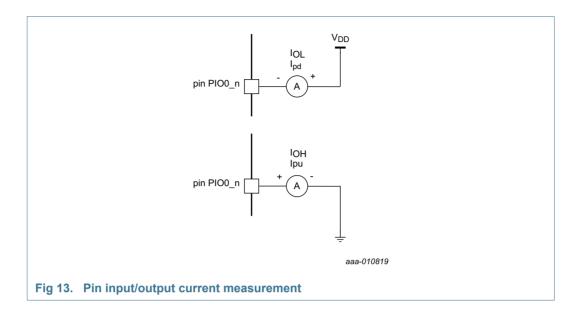
- [4] IDD measurements were performed with all pins configured as GPIO outputs driven LOW and pull-up resistors disabled.
- [5] IRC enabled; system oscillator disabled; system PLL disabled.
- [6] System oscillator enabled; IRC disabled; system PLL disabled.

[7] BOD disabled.

- [8] All peripherals disabled in the SYSAHBCLKCTRL register. Peripheral clocks to USART, CLKOUT, and IOCON disabled in system configuration block.
- [9] IRC enabled; system oscillator disabled; system PLL enabled.
- [10] IRC disabled; system oscillator enabled; system PLL enabled.
- [11] All oscillators and analog blocks turned off.
- [12] WAKEUP pin pulled HIGH externally.
- [13] Low-current mode PWR\_LOW\_CURRENT selected when running the set\_power routine in the power profiles.
- [14] Including voltage on outputs in tri-state mode.
- [15] Tri-state outputs go into tri-state mode in Deep power-down mode.
- [16] Allowed as long as the current limit does not exceed the maximum current allowed by the device.
- [17] Pull-up and pull-down currents are measured across the weak internal pull-up/pull-down resistors. See Figure 13.

[18] To V<sub>SS</sub>.

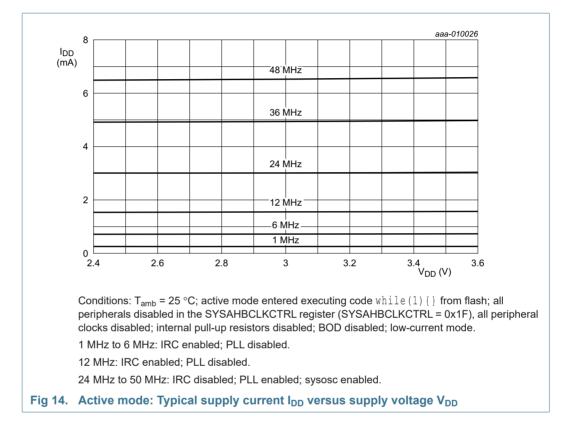
- [19] The parameter values specified are simulated and absolute values.
- [20] The input voltage of the RTC oscillator is limited as follows:  $V_{i(rtcx)}$ ,  $V_{o(rtcx)} < max(VBAT, V_{DD})$ .
- [21] Including bonding pad capacitance.



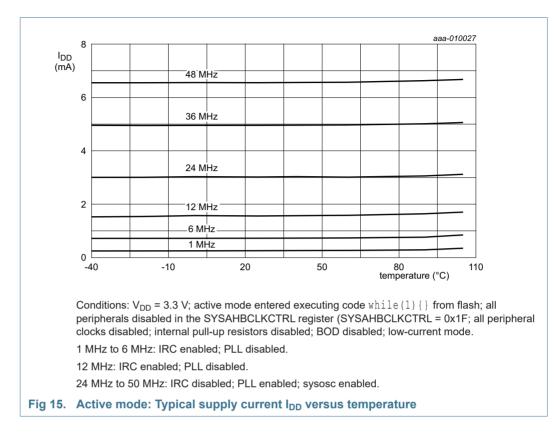
## **11.1 Power consumption**

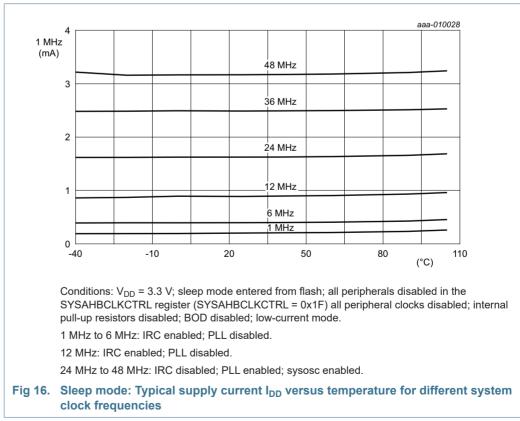
Power measurements in Active, Sleep, and Deep-sleep modes were performed under the following conditions:

- Configure all pins as GPIO with pull-up resistor disabled in the IOCON block.
- Configure GPIO pins as outputs using the GPIO DIR register.
- Write 1 to the GPIO CLR register to drive the outputs LOW.



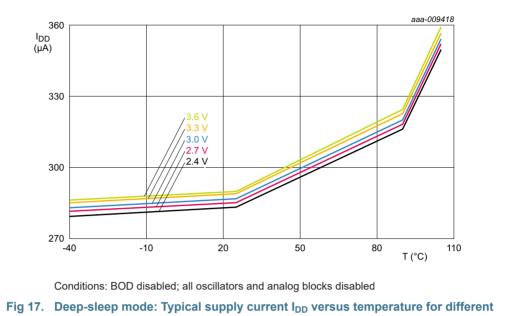
LPC11U6x



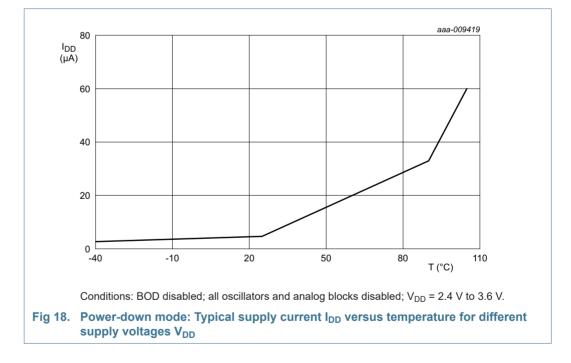


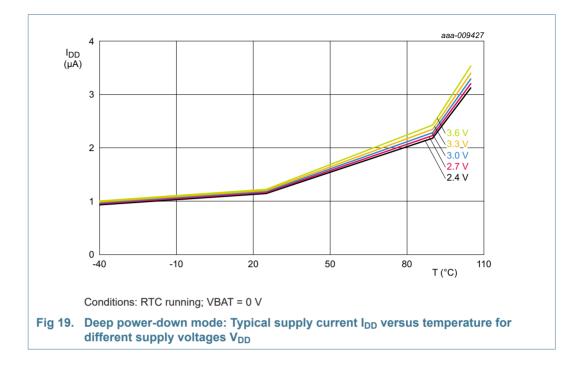
© NXP Semiconductors N.V. 2020. All rights reserved.

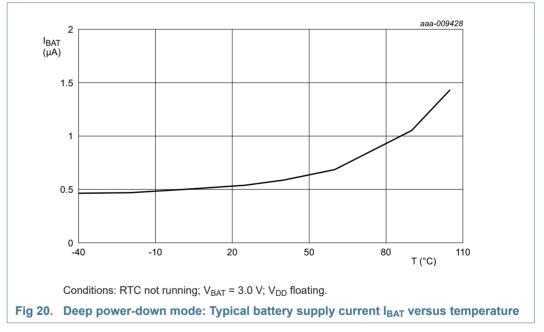
LPC11U6x

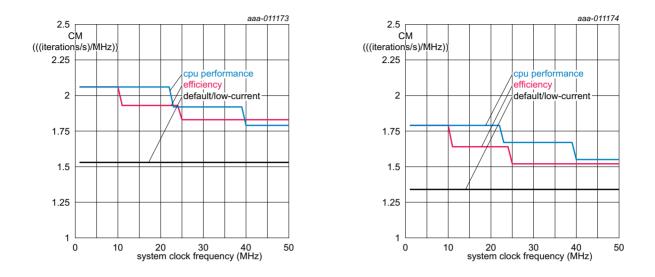












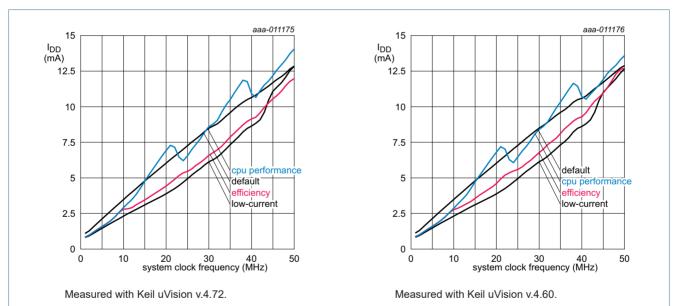
## 11.2 CoreMark data

Measured with Keil uVision v.4.72.

Measured with Keil uVision v.4.60.

Conditions: Conditions: V<sub>DD</sub> = 3.3 V; active mode; all peripherals except one UART and the SCTimer disabled in the SYSAHBCLKCTRL register; internal pull-up resistors enabled; BOD disabled.

#### Fig 21. CoreMark score for different power mode settings of the power profiles



Conditions: Conditions: V<sub>DD</sub> = 3.3 V; active mode; all peripherals except one UART and the SCTimer/PWM disabled in the SYSAHBCLKCTRL register; internal pull-up resistors enabled; BOD disabled.

Fig 22. Active mode: CoreMark power consumption I<sub>DD</sub> for different power mode settings of the power profiles

The CoreMark scores serve as a guideline to select the best power mode for a given application. To find the most suitable power mode, run the application in mode and compare power consumption and performance.

**Remark:** Applications using the USB can only run in default mode.

The power profiles optimize the chip performance for power consumption or core efficiency by controlling the flash access and core power. As shown in Figure 21 and Figure 22, different power modes result in different CoreMark scores reflecting the trade-off of efficiency and power consumption. In CPU and efficiency modes, the power profiles aim to keep the core efficiency at a maximum for the given system frequency. Depending on optimal flash access parameters that change with frequency, the CoreMark score and also the power consumption change. Since the compiled code for CoreMark testing runs out of flash memory, the CoreMark score depends on the compiler version.

## 11.3 Peripheral power consumption

The supply current per peripheral is measured as the difference in supply current between the peripheral block enabled and the peripheral block disabled in the SYSAHBCLKCFG and PDRUNCFG (for analog blocks) registers. All other blocks are disabled in both registers and no code accessing the peripheral is executed except for the ADC. Measured on a typical sample at  $T_{amb} = 25$  °C. Unless noted otherwise, the system oscillator and PLL are running in both measurements.

The supply currents are shown for system clock frequencies of 12 MHz and 48 MHz.

Peripheral	Typical s	supply current	in mA	Notes
	n/a	12 MHz	48 MHz	
IRC	0.24	-	-	System oscillator running; PLL off; independent of main clock frequency.
System oscillator at 12 MHz	0.28	-	-	IRC running; PLL off; independent of main clock frequency.
WatchDog oscillator at 600 kHz/2	0	-	-	System oscillator running; PLL off; independent of main clock frequency.
BOD	0.05	-	-	Independent of main clock frequency.
System PLL	0.25	-	-	-
USB PLL	0.37	-	-	-
CLKOUT	-	0.25	0.89	System PLL is source of CLKOUT.
ROM	-	0.09	0.37	-
FLASHREG	-	0.17	0.66	-
FLASHARRAY	-	0.13	0.52	-
SRAM1	-	0.15	0.59	-
USB SRAM	-	0.14	0.56	-
GPIO + pin interrupt/pattern match	-	0.18	0.69	GPIO pins configured as outputs and set to LOW. Direction and pin state are maintained if the GPIO is disabled in the SYSAHBCLKCFG register.
IOCON	-	0.08	0.30	-
SCTimer0/PWM + SCTimer1/PWM	-	0.29	1.1	-
CT16B0	-	0.05	0.17	-
CT16B1	-	0.04	0.16	-
CT32B0	-	0.04	0.13	-
CT32B1	-	0.03	0.13	-

Table 9. Power consumption for individual analog and digital blocks

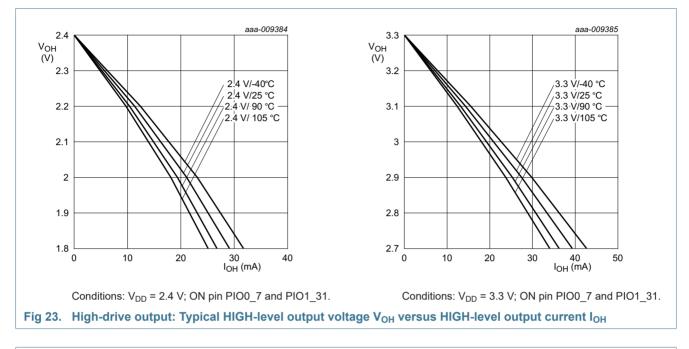
LPC11U6x

© NXP Semiconductors N.V. 2020. All rights reserved.

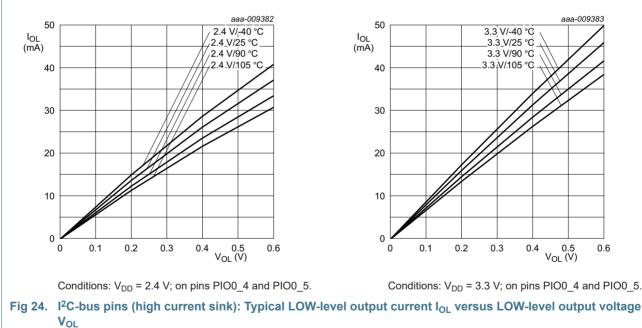
Peripheral	Typical s	supply current	in mA	Notes
	n/a	12 MHz	48 MHz	
RTC	-	0.02	0.10	-
WWDT	-	0.05	0.17	Main clock selected as clock source for the WDT.
I2C0	-	0.05	0.22	-
I2C1	-	0.05	0.18	-
SSP0	-	0.15	0.59	-
SSP1	-	0.15	0.58	-
USART0	-	0.31	1.19	-
USART1	-	0.12	0.50	-
USART2	-	0.13	0.49	-
USART3 + USART4	-	0.21	0.81	-
USB	-	0.43	0.72	Register interface disabled in SYSAHBCLKCTRL.
USB PHY	0.54	-	-	
ADC0	-	2.15	2.68	Register interface disabled in SYSAHBCLKCTRL and analog block disabled in PDRUNCFG registers. Power consumption measured while the ADC is sampling a single channel with an ADC clock of 12 MHz or 48 MHz.
Temperature sensor	0.18	-	-	-
DMA	-	0.28	1.1	-
CRC	-	0.04	0.14	-

#### Table 9. Power consumption for individual analog and digital blocks ...continued

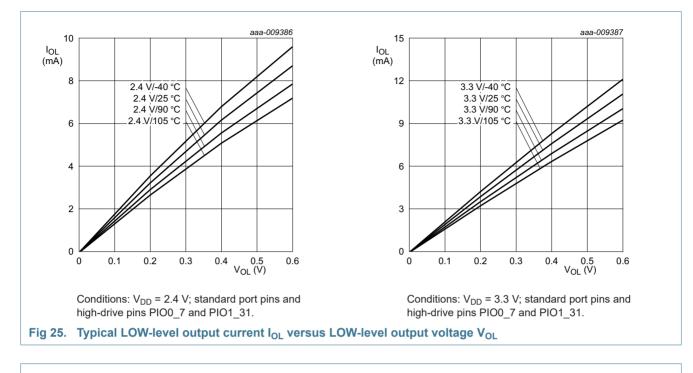
**LPC11U6x** 

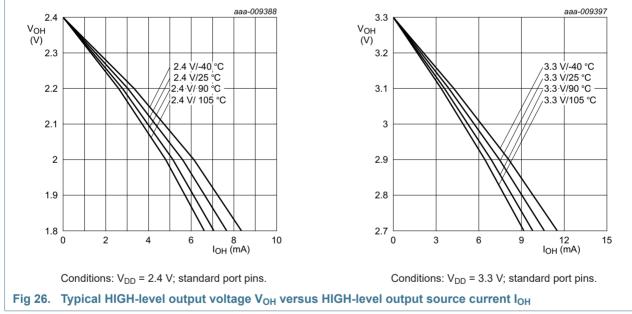


# 11.4 Electrical pin characteristics



# LPC11U6x 32-bit ARM Cortex-M0+ microcontroller





**LPC11U6x** 

aaa-009399

5

4 V<sub>I</sub> (V)

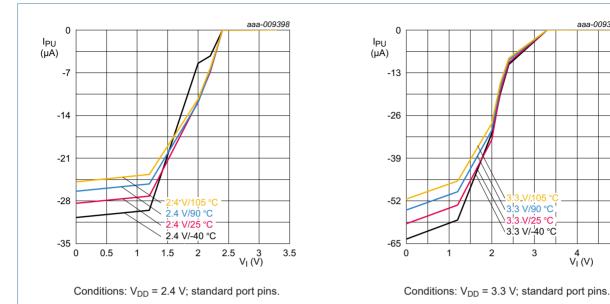
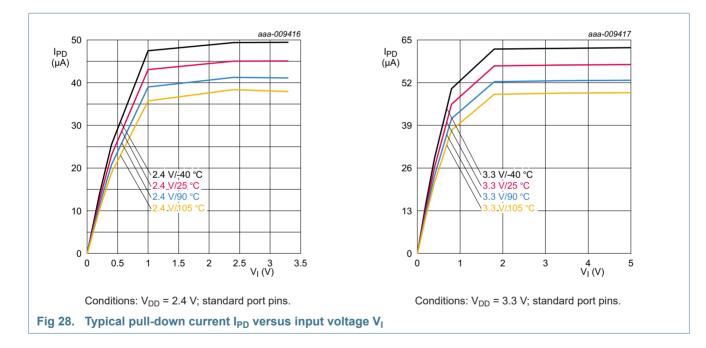


Fig 27. Typical pull-up current IPU versus input voltage VI



# **12. Dynamic characteristics**

## 12.1 Flash/EEPROM memory

#### Table 10. Flash characteristics

 $T_{amb}$  = -40 °C to +105 °C. Based on JEDEC NVM qualification. Failure rate < 10 ppm for parts as specified below.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
N <sub>endu</sub>	endurance		[1]	10000	100000	-	cycles
t <sub>ret</sub>	retention time	powered		10	20	-	years
		unpowered		20	40	-	years
t <sub>er</sub>	erase time	page or multiple consecutive pages, sector or multiple consecutive sectors		95	100	105	ms
t <sub>prog</sub>	programming time		[2]	0.95	1	1.05	ms

[1] Number of program/erase cycles.

[2] Programming times are given for writing 256 bytes to the flash. T<sub>amb</sub> <= +85 °C. Flash programming with IAP calls (see LPC11U6x user manual).

#### Table 11. EEPROM characteristics

 $T_{amb}$  = -40 °C to +85 °C;  $V_{DD}$  = 2.7 V to 3.6 V. Based on JEDEC NVM qualification. Failure rate < 10 ppm for parts as specified below.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
N <sub>endu</sub>	endurance		100000	1000000	-	cycles
t <sub>ret</sub>	retention time	powered	100	200	-	years
		unpowered	150	300	-	years
t <sub>prog</sub>	programming time	64 bytes	-	2.9	-	ms

## 12.2 External clock for the oscillator in slave mode

**Remark:** The input voltage on the XTAL1/2 pins must be  $\leq$  1.95 V (see <u>Table 8</u>). For connecting the oscillator to the XTAL pins, also see Section 14.4.

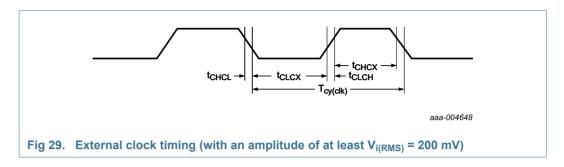
 Table 12.
 Dynamic characteristic: external clock (XTALIN input)

 $T_{amb} = -40 \text{ °C to } +105 \text{ °C}; V_{DD} \text{ over specified ranges.}$ 

Symbol	Parameter	Conditions	Min	Typ[2]	Max	Unit
f <sub>osc</sub>	oscillator frequency		1	-	25	MHz
T <sub>cy(clk)</sub>	clock cycle time		40	-	1000	ns
t <sub>CHCX</sub>	clock HIGH time		$T_{cy(clk)} \times 0.4$	-	-	ns
t <sub>CLCX</sub>	clock LOW time		$T_{cy(clk)} \times 0.4$	-	-	ns
t <sub>CLCH</sub>	clock rise time		-	-	5	ns
t <sub>CHCL</sub>	clock fall time		-	-	5	ns

[1] Parameters are valid over operating temperature range unless otherwise specified.

[2] Typical ratings are not guaranteed. The values listed are for room temperature (25 °C), nominal supply voltages.



## **12.3 Internal oscillators**

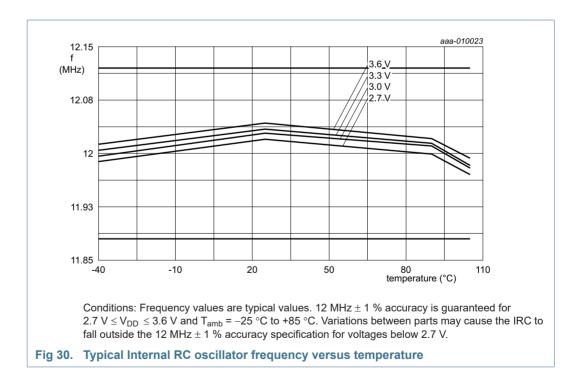
## Table 13. Dynamic characteristics: IRC

 $T_{amb} = -40 \circ C$  to  $+105 \circ C$ ; 2.7 V  $\leq V_{DD} \leq 3.6 V^{[1]}$ .

Symbol	Parameter	Conditions	Min	Typ[2]	Мах	Unit
f <sub>osc(RC)</sub>		$-25 \text{ °C} \le T_{amb} \le +85 \text{ °C}$	12 - 1%	12	12 + 1 %	MHz
	oscillator frequency	$-40 \ ^\circ C \le T_{amb} < -25 \ ^\circ C$	12 - 2%	12	12 + 1 %	MHz
		$85 ^\circ\text{C} < \text{T}_{amb} \leq 105 ^\circ\text{C}$	12 - 1.5 %	12	12 + 1.5 %	MHz

[1] Parameters are valid over operating temperature range unless otherwise specified.

[2] Typical ratings are not guaranteed. The values listed are for room temperature (25 °C), nominal supply voltages.



		onotion matching og obonnator				
Symbol	Parameter	Conditions	Min	Typ <u>[1]</u>	Max	Unit
f <sub>osc(int)</sub>	internal oscillator frequency	DIVSEL = 0x1F, FREQSEL = 0x1 [2]] in the WDTOSCCTRL register;	3] -	9.4	-	kHz
		DIVSEL = 0x00, FREQSEL = 0xF [2]] in the WDTOSCCTRL register	3] -	2300	-	kHz

#### Table 14. Dynamic characteristics: WatchDog oscillator

- [1] Typical ratings are not guaranteed. The values listed are at nominal supply voltages.
- [2] The typical frequency spread over processing and temperature (T<sub>amb</sub> =  $-40 \text{ }^{\circ}\text{C}$  to  $+105 \text{ }^{\circ}\text{C}$ ) is  $\pm40 \text{ }^{\circ}\text{K}$ .
- [3] See the LPC11U6x user manual.

## 12.4 I/O pins

#### Table 15. Dynamic characteristics: I/O pins[1]

 $T_{amb} = -40 \circ C$  to  $+105 \circ C$ ;  $3.0 V \le V_{DD} \le 3.6 V$ .

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
tr	rise time	pin configured as output	3.0	-	5.0	ns
t <sub>f</sub>	fall time	pin configured as output	2.5	-	5.0	ns

[1] Applies to standard port pins and RESET pin.

## 12.5 I<sup>2</sup>C-bus

## Table 16. Dynamic characteristic: I<sup>2</sup>C-bus pins<sup>[1]</sup>

 $T_{amb} = -40 \circ C \text{ to } +105 \circ C.$ [2]

Symbol	Parameter	Conditions	Min	Max	Unit
f <sub>SCL</sub>	SCL clock	Standard-mode	0	100	kHz
	frequency	Fast-mode	0	400	kHz
		Fast-mode Plus; on pins PIO0_4 and PIO0_5	0	1	MHz
t <sub>f</sub>	fall time	of both SDA and SCL signals	-	300	ns
		Standard-mode			
		Fast-mode	$20 + 0.1 \times C_b$	300	ns
		Fast-mode Plus; on pins PIO0_4 and PIO0_5	-	120	ns
t <sub>LOW</sub>	LOW period of	Standard-mode	4.7	-	μs
	the SCL clock	Fast-mode	1.3	-	μs
		Fast-mode Plus; on pins PIO0_4 and PIO0_5	0.5	-	μs
t <sub>HIGH</sub>	HIGH period of	Standard-mode	4.0	-	μs
	the SCL clock	Fast-mode	0.6	-	μs
		Fast-mode Plus; on pins PIO0_4 and PIO0_5	0.26	-	μs

Symbol	Parameter		Conditions	Min	Мах	Unit
t <sub>hd;dat</sub>	data hold time	[3][4][8]	Standard-mode	0	-	μs
			Fast-mode	0	-	μs
			Fast-mode Plus; on pins PIO0_4 and PIO0_5	0	-	μs
t <sub>SU;DAT</sub>	data set-up	[9][10]	Standard-mode	250	-	ns
	time		Fast-mode	100	-	ns
			Fast-mode Plus; on pins PIO0_4 and PIO0_5	50	-	ns

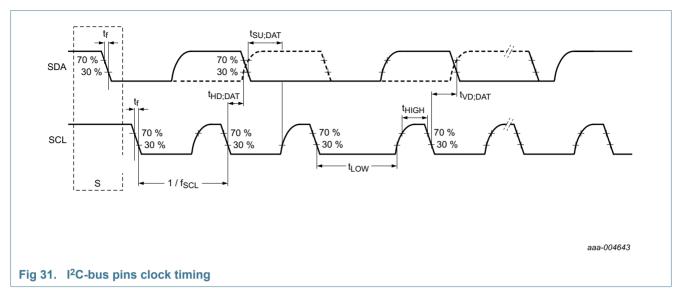
#### **Table 16.** Dynamic characteristic: $I^2$ C-bus pins[1] ...continued $T_{omb} = -40 \degree C$ to $\pm 105 \degree C$ [2]

[1] See the I<sup>2</sup>C-bus specification *UM10204* for details.

- [2] Parameters are valid over operating temperature range unless otherwise specified.
- [3] t<sub>HD;DAT</sub> is the data hold time that is measured from the falling edge of SCL; applies to data in transmission and the acknowledge.
- [4] A device must internally provide a hold time of at least 300 ns for the SDA signal (with respect to the  $V_{IH}(min)$  of the SCL signal) to bridge the undefined region of the falling edge of SCL.
- [5]  $C_b$  = total capacitance of one bus line in pF.
- [6] The maximum  $t_f$  for the SDA and SCL bus lines is specified at 300 ns. The maximum fall time for the SDA output stage  $t_f$  is specified at 250 ns. This allows series protection resistors to be connected in between the SDA and the SCL pins and the SDA/SCL bus lines without exceeding the maximum specified  $t_f$ .
- [7] In Fast-mode Plus, fall time is specified the same for both output stage and bus timing. If series resistors are used, designers should allow for this when considering bus timing.
- [8] The maximum  $t_{HD;DAT}$  could be 3.45  $\mu$ s and 0.9  $\mu$ s for Standard-mode and Fast-mode but must be less than the maximum of  $t_{VD;DAT}$  or  $t_{VD;ACK}$  by a transition time (see *UM10204*). This maximum must only be met if the device does not stretch the LOW period ( $t_{LOW}$ ) of the SCL signal. If the clock stretches the SCL, the data must be valid by the set-up time before it releases the clock.
- [9] t<sub>SU;DAT</sub> is the data set-up time that is measured with respect to the rising edge of SCL; applies to data in transmission and the acknowledge.
- [10] A Fast-mode I<sup>2</sup>C-bus device can be used in a Standard-mode I<sup>2</sup>C-bus system but the requirement  $t_{SU;DAT}$  = 250 ns must then be met. This will automatically be the case if the device does not stretch the LOW period of the SCL signal. If such a device does stretch the LOW period of the SCL signal, it must output the next data bit to the SDA line  $t_{r(max)} + t_{SU;DAT} = 1000 + 250 = 1250$  ns (according to the Standard-mode I<sup>2</sup>C-bus specification) before the SCL line is released. Also the acknowledge timing must meet this set-up time.

# LPC11U6x

## 32-bit ARM Cortex-M0+ microcontroller



## 12.6 SSP interface

Table 17.	Dynamic c	haracteristics	of SPI pins	in SPI mode
-----------	-----------	----------------	-------------	-------------

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
SPI maste	er (in SPI mode)	1					
T <sub>cy(clk)</sub>	clock cycle time	full-duplex mode	[1]	50	-	-	ns
		when only transmitting	[1]	40			ns
t <sub>DS</sub>	data set-up time	in SPI mode	[2]	15	-	-	ns
t <sub>DH</sub>	data hold time	in SPI mode	[2]	0	-	-	ns
t <sub>v(Q)</sub>	data output valid time	in SPI mode	[2]	-	-	10	ns
t <sub>h(Q)</sub>	data output hold time	in SPI mode	[2]	0	-	-	ns
SPI slave	(in SPI mode)						
T <sub>cy(PCLK)</sub>	PCLK cycle time			20	-	-	ns
t <sub>DS</sub>	data set-up time	in SPI mode	[3][4]	0	-	-	ns
t <sub>DH</sub>	data hold time	in SPI mode	[3][4]	$3 \times T_{cy(PCLK)}$ + 4	-	-	ns
t <sub>v(Q)</sub>	data output valid time	in SPI mode	[3][4]	-	-	$3 \times T_{cy(PCLK)}$ + 11	ns
t <sub>h(Q)</sub>	data output hold time	in SPI mode	[3][4]	-	-	$2 \times T_{cy(PCLK)}$ + 5	ns

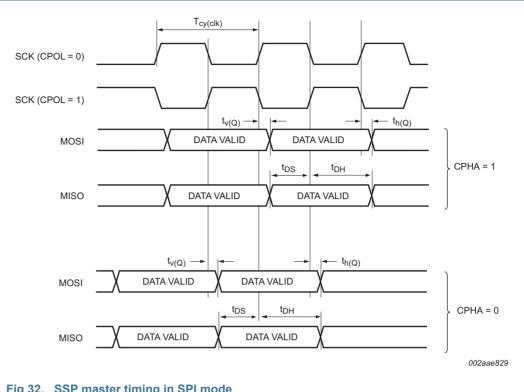
[1]  $T_{cy(clk)} = (SSPCLKDIV \times (1 + SCR) \times CPSDVSR) / f_{main}$ . The clock cycle time derived from the SPI bit rate  $T_{cy(clk)}$  is a function of the main clock frequency  $f_{main}$ , the SPI peripheral clock divider (SSPCLKDIV), the SPI SCR parameter (specified in the SSP0CR0 register), and the SPI CPSDVSR parameter (specified in the SPI clock prescale register).

[2]  $T_{amb}$  = -40 °C to 105 °C; 2.4 V  $\leq$  V<sub>DD</sub>  $\leq$  3.6 V.

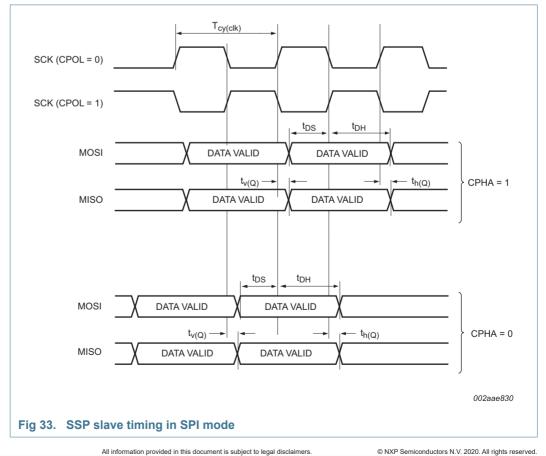
[3]  $T_{cy(clk)} = 12 \times T_{cy(PCLK)}$ .

[4]  $T_{amb} = 25 \text{ °C}$ ; for normal voltage supply range:  $V_{DD} = 3.3 \text{ V}$ .

LPC11U6x



## Fig 32. SSP master timing in SPI mode



**Product data sheet** 

LPC11U6x

© NXP Semiconductors N.V. 2020. All rights reserved.

## 12.7 USART interface

The maximum USART bit rate for all USARTs is 3.125 Mbit/s in asynchronous mode and 10 Mbit/s in synchronous slave and master mode.

#### Table 18. USART dynamic characteristics USART0

 $T_{amb} = -40 \text{ °C}$  to 105 °C; 2.4 V <= V<sub>DD</sub> <= 3.6 V;  $C_L = 10 \text{ pF}$ . Simulated parameters sampled at the 50 % level of the falling or rising edge; values guaranteed by design.

Symbol	Parameter	Min	Мах	Unit
T <sub>cy(clk)</sub>	clock cycle time [1]	100	-	ns
USART ma	aster (in synchronous mode)	·		
t <sub>su(D)</sub>	data input set-up time	44	-	ns
t <sub>h(D)</sub>	data input hold time	0	-	ns
t <sub>v(Q)</sub>	data output valid time	-	10	ns
t <sub>h(Q)</sub>	data output hold time	0	-	ns
USART sla	ve (in synchronous mode)	·	·	
t <sub>su(D)</sub>	data input set-up time	5	-	ns
t <sub>h(D)</sub>	data input hold time	20	-	ns
t <sub>v(Q)</sub>	data output valid time	-	40	ns
t <sub>h(Q)</sub>	data output hold time	25	-	ns

 T<sub>cy(clk)</sub> = (main clock cycle time)/(UARTCLKDIV x 2 x (256 x DLM + DLL)). See the LPC11U6x User manual UM10732.

#### Table 19. USART dynamic characteristics USART1/2/3/4

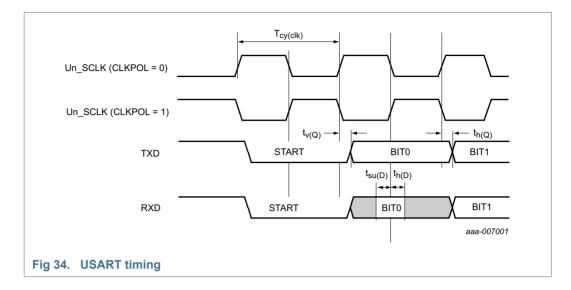
 $T_{amb}$  = -40 °C to 105 °C; 2.4 V <= V<sub>DD</sub> <= 3.6 V; C<sub>L</sub> = 10 pF. Simulated parameters sampled at the 50 % level of the falling or rising edge; values guaranteed by design.

Symbol	Parameter	Min	Мах	Unit
T <sub>cy(clk)</sub>	clock cycle time [1]	100	-	ns
USART ma	ster (in synchronous mode)	·		
t <sub>su(D)</sub>	data input set-up time	44	-	ns
t <sub>h(D)</sub>	data input hold time	0	-	ns
t <sub>v(Q)</sub>	data output valid time	-	10	ns
t <sub>h(Q)</sub>	data output hold time	0	-	ns
USART sla	ve (in synchronous mode)	·		
t <sub>su(D)</sub>	data input set-up time	5	-	ns
t <sub>h(D)</sub>	data input hold time	0	-	ns
t <sub>v(Q)</sub>	data output valid time	-	40	ns
t <sub>h(Q)</sub>	data output hold time	20	-	ns

[1] T<sub>cy(clk)</sub> = U\_PCLK/BRGVAL. See the LPC11U6x User manual UM10732.

# LPC11U6x

## 32-bit ARM Cortex-M0+ microcontroller



## 12.8 SCTimer/PWM output timing

#### Table 20. SCTimer/PWM output dynamic characteristics

 $T_{amb} = -40 \text{ °C}$  to 105 °C; 2.4 V <=  $V_{DD}$  <= 3.6 V. Simulated skew (over process, voltage, and temperature) between any two SCT outputs; sampled at the 50 % level of the falling or rising edge; values guaranteed by design.

Symbol	Parameter	Min	Мах	Unit
SCTimer0/PWI	N			
t <sub>sk(o)</sub>	output skew time	< 1	2	ns
SCTimer1/PWI	N			
t <sub>sk(o)</sub>	output skew time	< 1	2	ns

# **13. Characteristics of analog peripherals**

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V <sub>th</sub>	threshold voltage	interrupt level 2				
	assertion	-	2.54	-	V	
	de-assertion	-	2.68	-	V	
	interrupt level 3					
	assertion	-	2.82	-	V	
		de-assertion	-	2.93	-	V
		reset level 2				
		assertion	-	2.34	-	V
		de-assertion	-	2.49	-	V
		reset level 3				
	assertion	-	2.62	-	V	
		de-assertion	-	2.77	-	V

## Table 21. BOD static characteristics<sup>[1]</sup>

[1] Interrupt and reset levels are selected by writing the level value to the BOD control register BODCTRL, see *the* LPC11U6x *user manual*. Interrupt levels 0 and 1 are reserved.

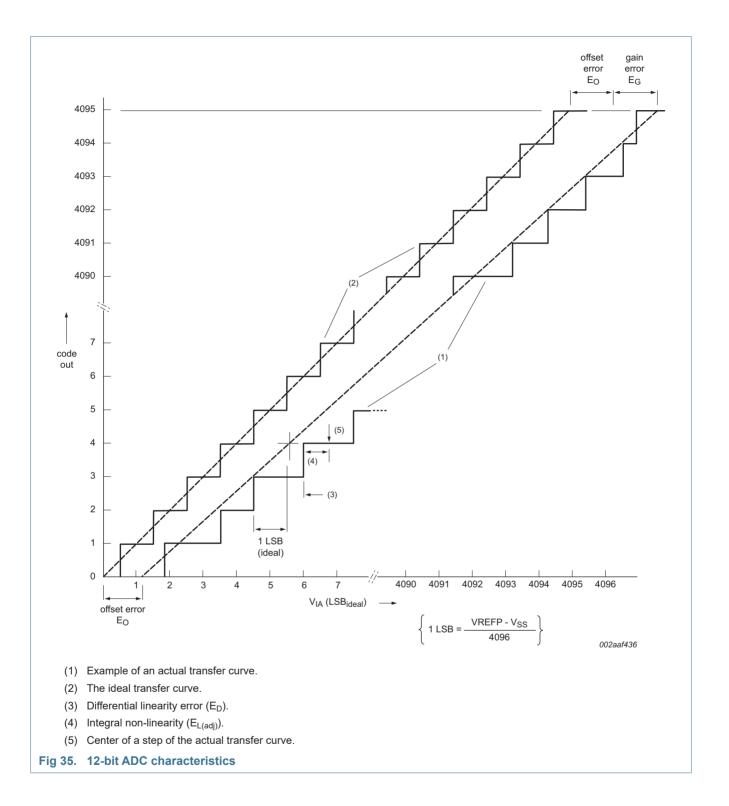
#### Table 22. 12-bit ADC static characteristics

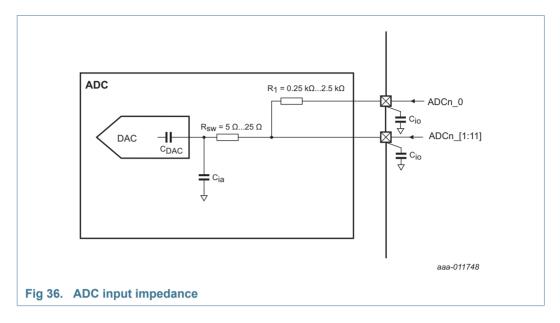
 $T_{amb}$  = -40 °C to +105 °C;  $V_{DD}$  = 2.4 V to 3.6 V; VREFP =  $V_{DDA}$ ;  $V_{SSA}$  = 0; VREFN =  $V_{SSA}$ . ADC calibrated at T = 25 °C.

Symbol	Parameter	Conditions		Min	Тур [ <u>1]</u>	Мах	Unit
V <sub>IA</sub>	analog input voltage		[2]	0	-	V <sub>DDA</sub>	V
C <sub>ia</sub>	analog input capacitance		[3]	-	-	0.32	pF
f <sub>clk(ADC)</sub>	ADC clock frequency	$V_{DDA} \ge 2.7 \text{ V}$				50	MHz
		$V_{DDA} \ge 2.4 \text{ V}$				25	MHz
f <sub>s</sub>	sampling frequency	$V_{DDA} \ge 2.7 \text{ V}$		-	-	2	Msamples/s
		$V_{DDA} \ge 2.4 \text{ V}$		-	-	1	Msamples/s
E <sub>D</sub>	differential linearity error		[4]	-	-	±2.5	LSB
E <sub>L(adj)</sub>	integral non-linearity		[5]	-	-	±2.5	LSB
Eo	offset error		[6]	-	-	±4.5	LSB
V <sub>err(FS)</sub>	full-scale error voltage		[7]	-	-	±0.5	%
Z <sub>i</sub>	input impedance	f <sub>s</sub> = 2 Msamples/s	[8][9]	0.1	-	-	MΩ

[1] Typical ratings are not guaranteed. The values listed are at room temperature (25 °C), nominal supply voltages.

- [2] The input resistance of ADC channel 0 is higher than for all other channels.
- [3] C<sub>ia</sub> represents the external capacitance on the analog input channel for sampling speeds of 2 Msamples/s.
- $\ensuremath{\left[4\right]} \quad \mbox{The differential linearity error (E_D) is the difference between the actual step width and the ideal step width. See Figure 35.$
- [5] The integral non-linearity (E<sub>L(adj)</sub>) is the peak difference between the center of the steps of the actual and the ideal transfer curve after appropriate adjustment of gain and offset errors. See Figure 35.
- [6] The offset error ( $E_0$ ) is the absolute difference between the straight line which fits the actual curve and the straight line which fits the ideal curve. See Figure 35.
- [7] The full-scale error voltage or gain error (E<sub>G</sub>) is the difference between the straight-line fitting the actual transfer curve after removing offset error, and the straight line which fits the ideal transfer curve. See Figure 35.
- [8]  $T_{amb} = 25 \text{ °C}$ ; maximum sampling frequency  $f_s = 2$  Msamples/s and analog input capacitance  $C_{ia} = 0.32 \text{ pF}$ .
- [9] Input impedance  $Z_i$  is inversely proportional to the sampling frequency and the total input capacity including  $C_{ia}$ :  $Z_i \propto 1 / (f_s \times C_i)$ . See Table 8 for  $C_{io}$ .





# Table 23. Temperature sensor static and dynamic characteristics $V_{DDA}$ = 2.4 V to 3.6 V

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
DT <sub>sen</sub>	sensor temperature accuracy	$T_{amb} = -40 \ ^{\circ}C \ to +105 \ ^{\circ}C \ [1]$	-	±5	-	°C
EL	linearity error	T <sub>amb</sub> = -40 °C to +105 °C	-	±4	-	°C
t <sub>s(pu)</sub>	power-up settling time	to 99% of temperature [2] sensor output value	-	14	-	μs

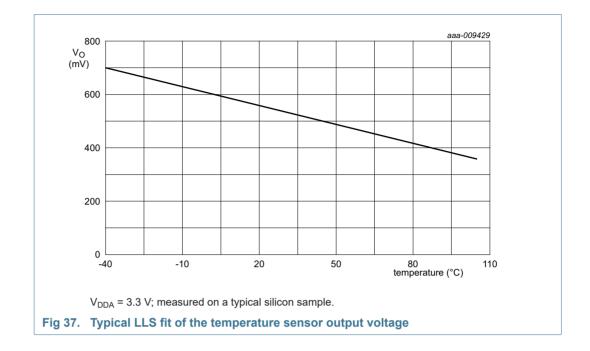
[1] Absolute temperature accuracy.

[2] Typical values are derived from nominal simulation (V<sub>DDA</sub> = 3.3 V; T<sub>amb</sub> = 27 °C; nominal process models).

# Table 24. Temperature sensor Linear-Least-Square (LLS) fit parameters $V_{DDA}$ = 2.4 V to 3.6 V

Fit parameter	Range	Min	Тур	Max	Unit
LLS slope	$T_{amb}$ = -40 °C to +105 °C	-	-2.36	-	mV/°C
LLS intercept	T <sub>amb</sub> = –40 °C to +105°C	-	606	-	mV

LPC11U6x



**Product data sheet** 

# 14. Application information

### 14.1 ADC usage notes

The following guidelines show how to increase the performance of the ADC in a noisy environment beyond the ADC specifications listed in <u>Table 22</u>:

- The ADC input trace must be short and as close as possible to the LPC11U6x chip.
- The ADC input traces must be shielded from fast switching digital signals and noisy power supply lines.
- If the ADC and the digital core share a power supply, the power supply line must be adequately filtered.
- To improve the ADC performance in a very noisy environment, put the device in Sleep mode during the ADC conversion.

# 14.2 Typical wake-up times

#### Table 25. Typical wake-up times

 $V_{DD} = 3.3 V; T_{amb} = 25 °C$ 

Power modes	Wake-up time
Sleep mode (12 MHz) <sup>[1][2]</sup>	2.6 μs
Deep-sleep mode[1][3]	4.4 μs
Power-down mode <sup>[1][3]</sup>	86.8 μs
Deep Power-down mode <sup>[4]</sup>	276 μs

- [1] The wake-up time measured is the time between when a GPIO input pin is triggered to wake up the device from the low-power modes and from when a GPIO output pin is set in the interrupt service routine (ISR) wake-up handler.
- [2] IRC enabled, all peripherals off.
- [3] WatchDog oscillator disabled, Brown-Out Detect (BOD) disabled.
- [4] Wake-up from deep power-down causes the part to go through entire reset process. The wake-up time measured is the time between when a wake-up pin is triggered to wake up the device from the low-power modes and when a GPIO output pin is set in the reset handler.

## 14.3 Suggested USB interface solutions

The USB device can be connected to the USB as self-powered device (see Figure 38) or bus-powered device (see Figure 39).

On the LPC11U6x, the PIO0\_3/USB\_VBUS pin is 5 V tolerant only when  $V_{DD}$  is applied and at operating voltage level. Therefore, if the USB\_VBUS function is connected to the USB connector and the device is self-powered, the USB\_VBUS pin must be protected for situations when  $V_{DD} = 0$  V.

If  $V_{DD}$  is always at operating level while VBUS = 5 V, the USB\_VBUS pin can be connected directly to the VBUS pin on the USB connector.

For systems where  $V_{DD}$  can be 0 V and VBUS is directly applied to the VBUS pin, precautions must be taken to reduce the voltage to below 3.6 V, which is the maximum allowable voltage on the USB\_VBUS pin in this case.

LPC11U6x

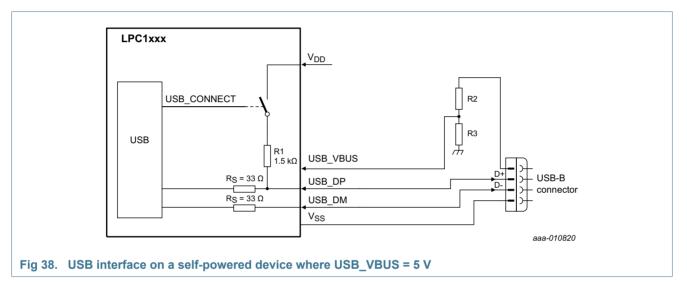
One method is to use a voltage divider to connect the USB\_VBUS pin to the VBUS on the USB connector. The voltage divider ratio should be such that the USB\_VBUS pin is greater than 0.7  $V_{DD}$  to indicate a logic HIGH while below the 3.6 V allowable maximum voltage.

For the following operating conditions

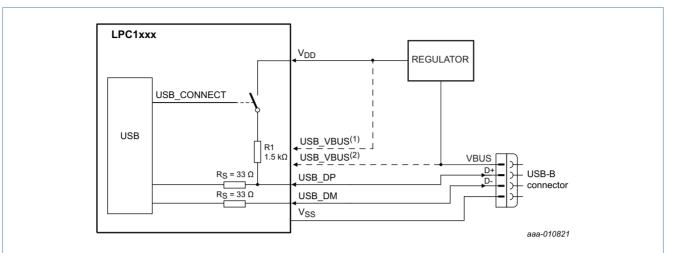
VBUS<sub>max</sub> = 5.25 V

V<sub>DD</sub> = 3.6 V,

the voltage divider should provide a reduction of 3.6 V/5.25 V or ~0.686 V.



The USB\_CONNECT function can be enabled internally by setting the DCON bit in the DEVCMDSTAT register to prevent the USB from timing out when there is a significant delay between power-up and handling USB traffic. External circuitry is not required for the USB\_CONNECT functionality.



Two options exist for connecting VBUS to the USB\_VBUS pin:

- (1) Connect the regulator output to USB\_VBUS. In this case, the USB\_VBUS signal is HIGH whenever the part is powered.
- (2) Connect the VBUS signal directly from the connector to the USB\_VBUS pin. In this case, 5 V are applied to the USB\_VBUS pin while the regulator is ramping up to supply V<sub>DD</sub>. Since the PIO0\_3/USB\_VBUS pin is only 5 V tolerant when V<sub>DD</sub> is at operating level, this connection can degrade the performance of the part over its lifetime. Simulation shows that lifetime is reduced to 15 years at T<sub>amb</sub> = 45 °C and 8 years at T<sub>amb</sub> = 55 °C assuming that USB\_VBUS = 5 V is applied continuously while V<sub>DD</sub> = 0 V.

#### Fig 39. USB interface on a bus-powered device

**Remark:** When a self-powered circuit is used without connecting VBUS, configure the PIO0\_3/USB\_VBUS pin for GPIO (PIO0\_3) and provide software that can detect the host presence through some other mechanism before enabling USB\_CONNECT and the SoftConnect feature. Enabling the SoftConnect without host presence leads to USB compliance failure.

#### 14.3.1 USB Low-speed operation

The USB device controller can be used in low-speed mode supporting 1.5 Mbit/s data exchange with a USB host controller.

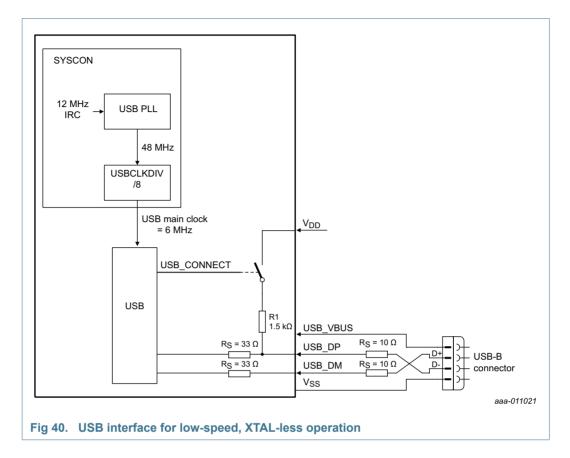
Remark: To operate in low-speed mode, change the board connections as follows:

- 1. Connect USB\_DP to the D- pin of the connector.
- 2. Connect USB\_DM to the D+ pin of the connector.

Use the IRC as clock source for the USB PLL to generate 48 MHz, then set the USB clock divider USBCLKDIV to 8 for a 6 MHz USB clock (see Figure 10 "Clock generation").

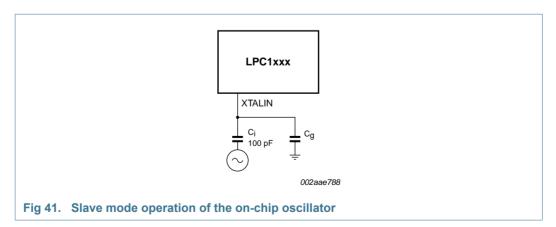
External 10  $\Omega$  resistors are recommended in low-speed mode to reduce over-shoots and accommodate for 5 m cable length required for USB-IF testing.

LPC11U6x



## 14.4 XTAL input and crystal oscillator component selection

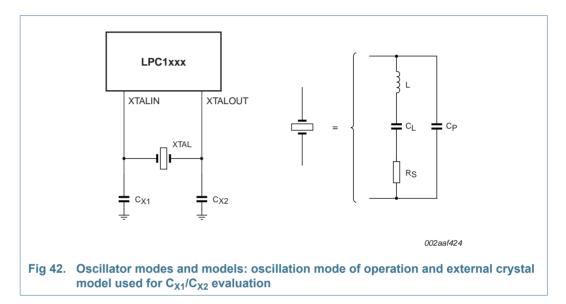
The input voltage to the on-chip oscillators is limited to 1.8 V. If the oscillator is driven by a clock in slave mode, it is recommended that the input be coupled through a capacitor with  $C_i = 100 \text{ pF}$ . To limit the input voltage to the specified range, choose an additional capacitor to ground  $C_g$  which attenuates the input voltage by a factor  $C_i/(C_i + C_g)$ . In slave mode, a minimum of 200 mV(RMS) is needed.



In slave mode the input clock signal should be coupled through a capacitor of 100 pF (Figure 41), with an amplitude between 200 mV (RMS) and 1000 mV (RMS). This corresponds to a square wave signal with a signal swing of between 280 mV and 1.4 V. The XTALOUT pin in this configuration can be left unconnected.

LPC11U6x

External components and models used in oscillation mode are shown in Figure 42 and in Table 26 and Table 27. Since the feedback resistance is integrated on chip, only a crystal and the capacitances  $C_{X1}$  and  $C_{X2}$  must be connected externally in case of fundamental mode oscillation (the fundamental frequency is represented by L,  $C_L$  and  $R_S$ ). Capacitance  $C_P$  in Figure 42 represents the parallel package capacitance and should not be larger than 7 pF. Parameters  $F_{OSC}$ ,  $C_L$ ,  $R_S$  and  $C_P$  are supplied by the crystal manufacturer (see Table 26).



# Table 26.Recommended values for $C_{X1}/C_{X2}$ in oscillation mode (crystal and external<br/>components parameters) low frequency mode

Fundamental oscillation frequency F <sub>OSC</sub>	Crystal load capacitance C <sub>L</sub>	Maximum crystal series resistance R <sub>S</sub>	External load capacitors C <sub>X1</sub> , C <sub>X2</sub>
1 MHz to 5 MHz	10 pF	< 300 Ω	18 pF, 18 pF
	20 pF	< 300 Ω	39 pF, 39 pF
	30 pF	< 300 Ω	57 pF, 57 pF
5 MHz to 10 MHz	10 pF	< 300 Ω	18 pF, 18 pF
	20 pF	< 200 Ω	39 pF, 39 pF
	30 pF	< 100 Ω	57 pF, 57 pF
10 MHz to 15 MHz	10 pF	< 160 Ω	18 pF, 18 pF
	20 pF	< 60 Ω	39 pF, 39 pF
15 MHz to 20 MHz	10 pF	< 80 Ω	18 pF, 18 pF

# Table 27. Recommended values for $C_{X1}/C_{X2}$ in oscillation mode (crystal and external components parameters) high frequency mode

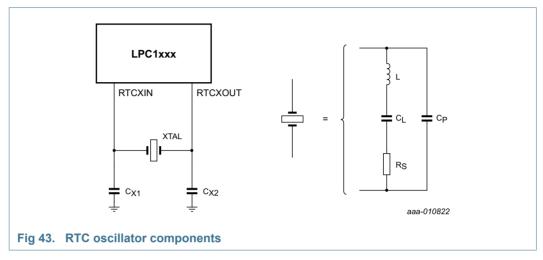
Fundamental oscillation frequency F <sub>OSC</sub>	Crystal load capacitance C <sub>L</sub>	Maximum crystal series resistance R <sub>S</sub>	External load capacitors C <sub>X1</sub> , C <sub>X2</sub>
15 MHz to 20 MHz	10 pF	< 180 Ω	18 pF, 18 pF
	20 pF	< 100 Ω	39 pF, 39 pF
20 MHz to 25 MHz	10 pF	< 160 Ω	18 pF, 18 pF
	20 pF	< 80 Ω	39 pF, 39 pF

# 14.5 XTAL Printed-Circuit Board (PCB) layout guidelines

The crystal should be connected on the PCB as close as possible to the oscillator input and output pins of the chip. Take care that the load capacitors  $C_{x1}$ ,  $C_{x2}$ , and  $C_{x3}$  in case of third overtone crystal usage have a common ground plane. The external components must also be connected to the ground plane. Loops must be made as small as possible to keep the noise coupled in via the PCB as small as possible. Also parasitics should stay as small as possible. Smaller values of  $C_{x1}$  and  $C_{x2}$  should be chosen according to the increase in parasitics of the PCB layout.

### 14.6 RTC oscillator component selection

The 32 kHz crystal must be connected to the part via the RTCXIN and RTCXOUT pins as shown in Figure 43. If the RTC is not used, the RTCXIN pin can be grounded.



Select  $C_{x1}$  and  $C_{x2}$  based on the external 32 kHz crystal used in the application circuitry. The pad capacitance  $C_P$  of the RTCXIN and RTCXOUT pad is 3 pF. If the load capacitance of the external crystal is  $C_L$ , the optimal  $C_{x1}$  and  $C_{x2}$  can be selected as:

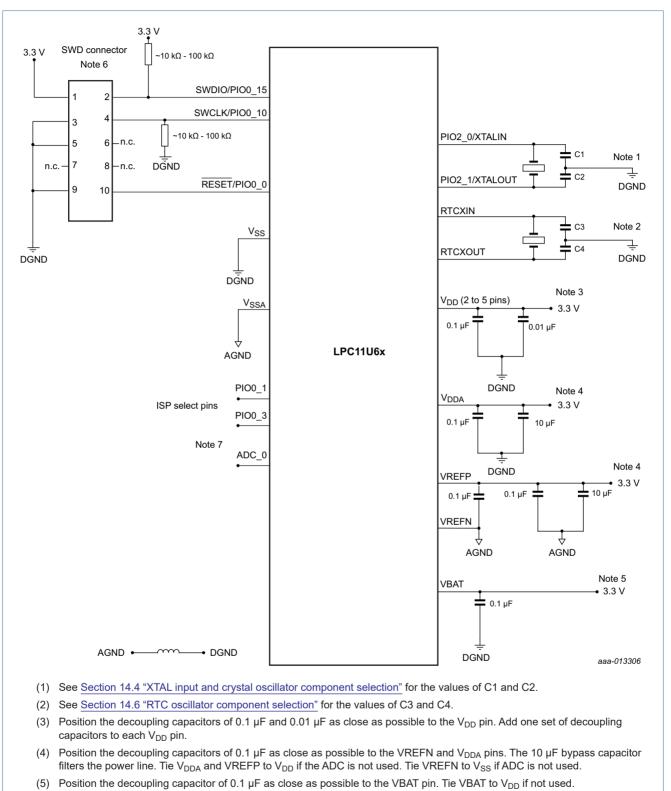
$$C_{x1} = C_{x2} = 2 \times C_L - C_P$$

To achieve the best performance and accurate frequency, it is recommended to use Cx1 = Cx2 = 24 pF and CL = 12 pF.

Please note the actual board layout and placement of external components influences the optimal values of external load capacitors. Therefore, it is recommended to fine tune the values of external load capacitors on the hardware board to get the accurate clock frequency. For fine tuning, measure the clock on the CLOCKOUT pin and optimize the values of external load capacitors for minimum frequency deviation.

## 14.7 Connecting power, clocks, and debug functions

Figure 44 shows the basic board connections used to power the LPC11U6x, connect the external crystal and the 32 kHz oscillator for the RTC, and provide debug capabilities via the serial wire port.



- (6) Uses the ARM 10-pin interface for SWD.
- (7) When measuring signals of low frequency, use a low-pass filter to remove noise and to improve ADC performance. Also see Ref. 3.
- Fig 44. Power, clock, and debug connections

# 14.8 Termination of unused pins

<u>Table 28</u> shows how to terminate pins that are **not** used in the application. In many cases, unused pins may should be connected externally or configured correctly by software to minimize the overall power consumption of the part.

Unused pins with GPIO function should be configured as outputs set to LOW with their internal pull-up disabled. To configure a GPIO pin as output and drive it LOW, select the GPIO function in the IOCON register, select output in the GPIO DIR register, and write a 0 to the GPIO PORT register for that pin. Disable the pull-up in the pin's IOCON register.

In addition, it is recommended to configure all GPIO pins that are not bonded out on smaller packages as outputs driven LOW with their internal pull-up disabled.

Pin	Default state <sup>[1]</sup>	Recommended termination of unused pins
RESET/PIO0_0	I; PU	In an application that does not use the RESET pin or its GPIO function, the termination of this pin depends on whether Deep power-down mode is used:
		• Deep power-down used: Connect an external pull-up resistor and keep pin in default state (input, pull-up enabled) during all other power modes.
		<ul> <li>Deep power-down not used and no external pull-up connected: can be left unconnected if internal pull-up is disabled and pin is driven LOW and configured as output by software.</li> </ul>
all PIOn_m (not open-drain)	I; PU	Can be left unconnected if driven LOW and configured as GPIO output with pull-up disabled by software.
PIOn_m (I2C open-drain)	IA	Can be left unconnected if driven LOW and configured as GPIO output by software.
RSTOUT	IA; O	Can be left unconnected. Not configurable by software.
USB_DP/USB_DM	F	Can be left unconnected. When the USP PHY is disabled, the pins are LOW.
RTCXIN	-	Connect to ground. When grounded, the RTC oscillator is disabled.
RTCXOUT	-	Can be left unconnected.
VREFP	-	Tie to VDD.
VREFN	-	Tie to VSS.
VDDA	-	Tie to VDD.
VBAT	-	Tie to VDD if no external battery connected.
VSSA	-	Tie to VSS.

Table 28. Termination of unused pins

[1] I = Input, O = Output, IA = Inactive (no pull-up/pull-down enabled), F = floating, PU = Pull-Up.

# 14.9 Pin states in different power modes

#### Table 29. Pin states in different power modes

Pin	Active	Sleep	Deep-sleep/Power- down	Deep power-down
PIOn_m pins (not I2C)	As configured in th enabled.	e IOCON <sup>[1]</sup> . Defau	ilt: internal pull-up	Floating.
PIO0_4, PIO0_5 (open-drain I2C-bus pins)	As configured in th	e IOCON <u>[1]</u> .		Floating.
RESET	Reset function ena enabled.	Reset function enabled. Default: input, internal pull-up enabled.		Reset function disabled; floating; if the part is in deep power-down mode, the RESET pin needs an external pull-up to reduce power consumption.
PIO0_16/ WAKEUP	As configured in th	e IOCON <sup>[1]</sup> . WAKE	EUP function inactive.	Wake-up function enabled; can be disabled by software.

[1] Default and programmed pin states are retained in sleep, deep-sleep, and power-down modes.

# 14.10 ElectroMagnetic Compatibility (EMC)

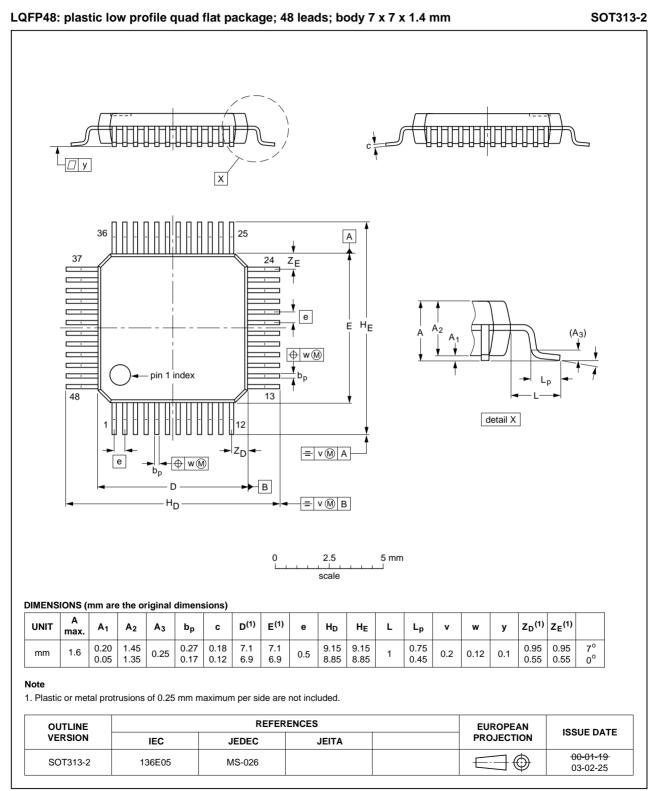
Radiated emission measurements according to the IEC61967-2 standard using the TEM-cell method are shown for part LPC11U68JBD100.

Table 30.ElectroMagnetic Compatibility (EMC) for part LPC11U68 (TEM-cell method) $V_{DD}$  = 3.3 V;  $T_{amb}$  = 25 °C.

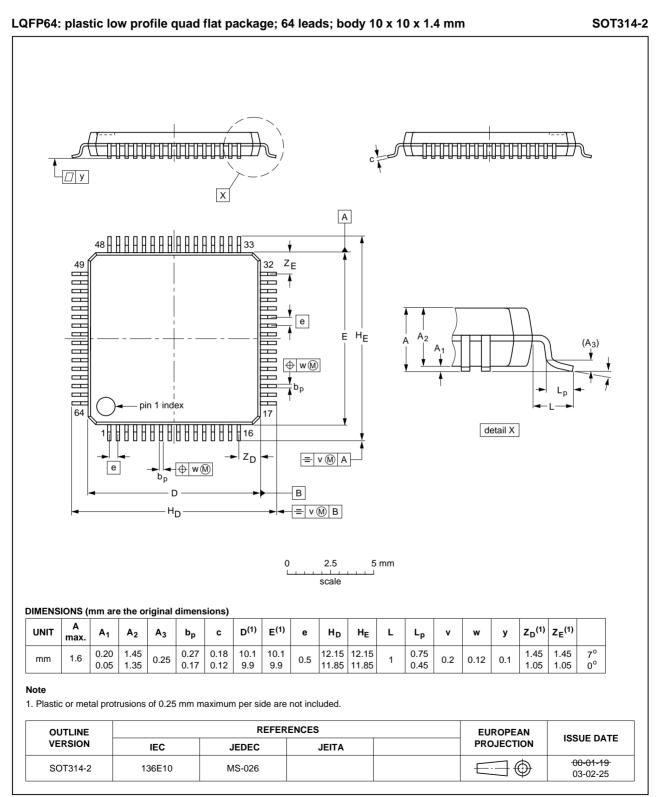
Parameter	Frequency band	System clock =				Unit
		12 MHz	24 MHz	36 MHz	48 MHz	
Input clock:	IRC (12 MHz)					
maximum	1 MHz to 30 MHz	-5	-5	-5	-5	dBμV
peak level	30 MHz to 150 MHz	-1	0	+4	+4	dBμV
	150 MHz to 1 GHz	-1	0	+4	+4	dBμV
IEC level <sup>[1]</sup>	-	0	0	0	0	-
Input clock:	crystal oscillator (12 N	lHz)				
maximum	1 MHz to 30 MHz	-2	-6	-4	-5	dBμV
peak level	30 MHz to 150 MHz	-1	0	+3	+3	dBμV
	150 MHz to 1 GHz	-2	0	+2	+5	dBμV
IEC level <sup>[1]</sup>	-	0	0	0	0	-

[1] IEC levels refer to Appendix D in the IEC61967-2 Specification.

# **15. Package outline**

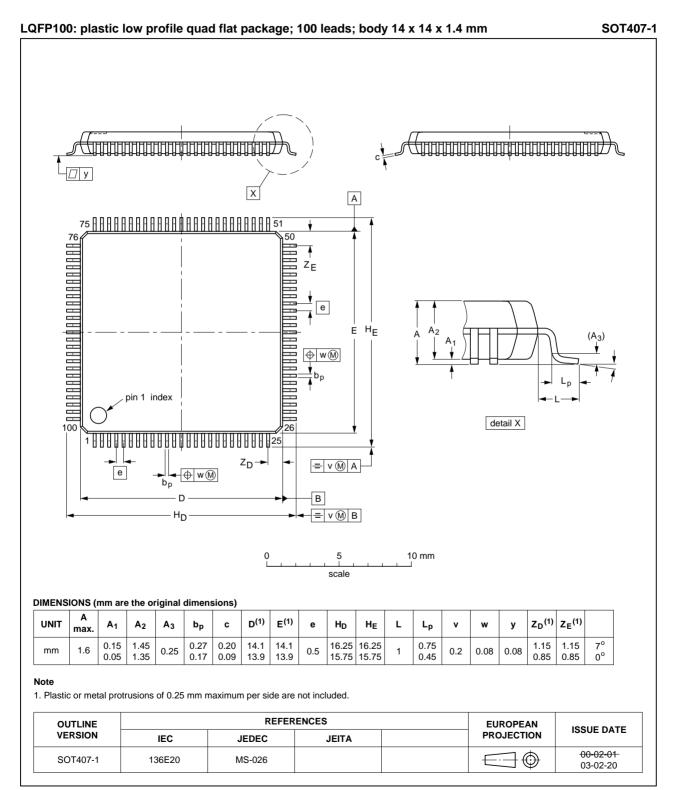


#### Fig 45. Package outline LQFP48 (SOT313-2)



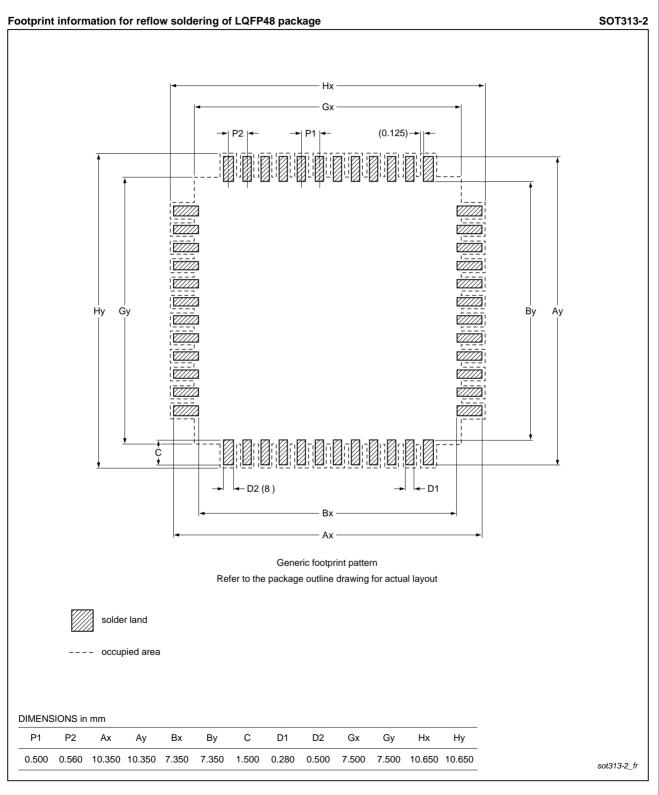
#### Fig 46. Package outline LQFP64 (SOT314-2)

LPC11U6x

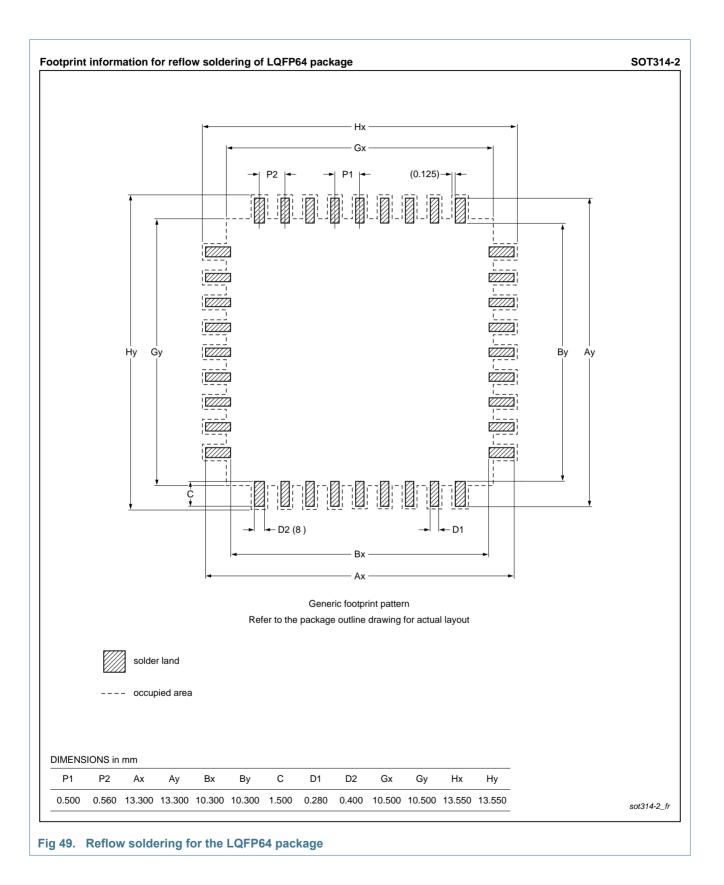


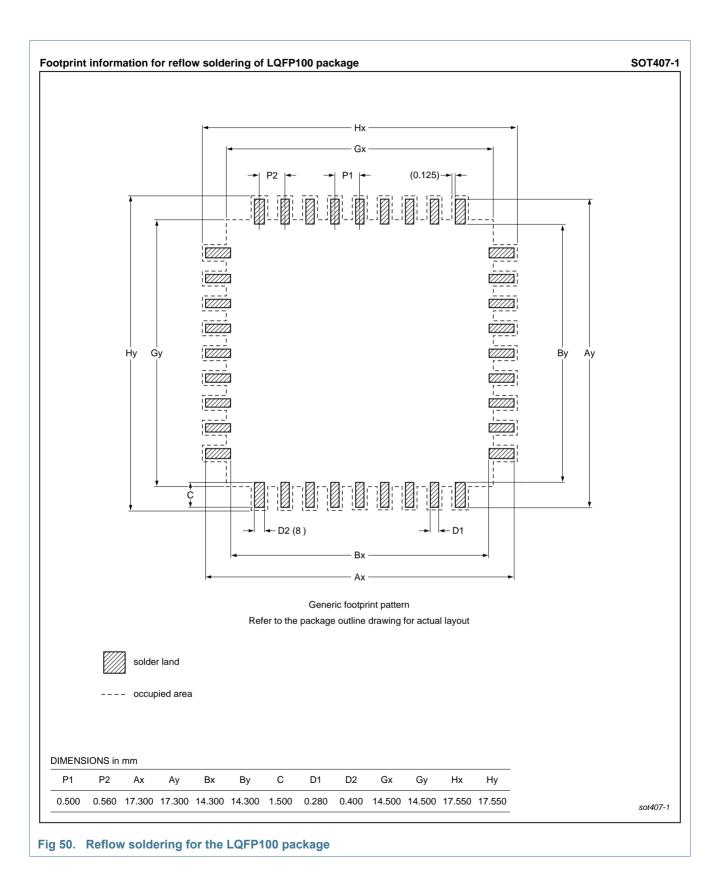
#### Fig 47. Package outline LQFP100 (SOT407-1)

# 16. Soldering



#### Fig 48. Reflow soldering for the LQFP48 package





# **17. References**

- [1] LPC11U6x User manual UM10732: http://www.nxp.com/documents/user\_manual/UM10732.pdf
- [2] LPC11U6x Errata sheet: http://www.nxp.com/documents/errata\_sheet/ES\_LPC11U6X.pdf
- [3] Technical note ADC design guidelines: http://www.nxp.com/documents/technical\_note/TN00009.pdf

# 18. Revision history

alteration. 20200724 • Updated S recommend 20160906 • Section 14. • Replaced C <u>description</u> • Replaced C <u>Table 3 "Pir</u>	Product data sheet Section 14.6 "RTC oscilla dation. Product data sheet 10 "ElectroMagnetic Co CT16B0_CAP1 with CT1  CT32B0_CAP1 with CT3 description". gure 7 "AHB multilayer r	- ator component sel - mpatibility (EMC)" 6B0_CAP2 for pin 32B0_CAP2 for pin	LPC11U6x v.1.2
alteration. 20200724 • Updated S recommend 20160906 • Section 14. • Replaced C <u>description</u> • Replaced C <u>Table 3 "Pir</u> • Updated Fig DMA or US 20140526	Product data sheet Section 14.6 "RTC oscilla dation. Product data sheet 10 "ElectroMagnetic Co CT16B0_CAP1 with CT1 2. CT32B0_CAP1 with CT3 n description". gure 7 "AHB multilayer r B.	- ator component sel - mpatibility (EMC)" 6B0_CAP2 for pin 32B0_CAP2 for pin	LPC11U6x v.1.3 ection" with frequency LPC11U6x v.1.2 added. PI01_21. See <u>Table 3 "Pin</u> PIO1_6 and pin PIO1_29. See
<ul> <li>Updated S recommend</li> <li>20160906</li> <li>Section 14.</li> <li>Replaced C description"</li> <li>Replaced C Table 3 "Pir</li> <li>Updated Fig DMA or US</li> <li>20140526</li> </ul>	Section 14.6 "RTC oscilla dation. Product data sheet 10 "ElectroMagnetic Co CT16B0_CAP1 with CT1 CT32B0_CAP1 with CT3 description". gure 7 "AHB multilayer r B.	- mpatibility (EMC)" 6B0_CAP2 for pin 32B0_CAP2 for pin	ection" with frequency LPC11U6x v.1.2 added. PI01_21. See <u>Table 3 "Pin</u> PIO1_6 and pin PIO1_29. See
recommend         20160906         • Section 14.         • Replaced C         description"         • Replaced C         Table 3 "Pir         • Updated Fig         DMA or US         20140526	dation. Product data sheet 10 "ElectroMagnetic Co CT16B0_CAP1 with CT1 2. CT32B0_CAP1 with CT3 n description". gure 7 "AHB multilayer r B.	- mpatibility (EMC)" 6B0_CAP2 for pin 32B0_CAP2 for pin	LPC11U6x v.1.2 added. PI01_21. See <u>Table 3 "Pin</u> PIO1_6 and pin PIO1_29. See
<ul> <li>Section 14.</li> <li>Replaced C description"</li> <li>Replaced C Table 3 "Pir</li> <li>Updated Fig DMA or US</li> <li>20140526</li> </ul>	10 "ElectroMagnetic Co CT16B0_CAP1 with CT1 2. CT32B0_CAP1 with CT3 1 description". gure 7 "AHB multilayer r B.	6B0_CAP2 for pin	added. Pl01_21. See <u>Table 3 "Pin</u> PlO1_6 and pin PlO1_29. See
<ul> <li>Replaced C description"</li> <li>Replaced C <u>Table 3 "Pir</u></li> <li>Updated Fig DMA or US</li> <li>20140526</li> </ul>	CT16B0_CAP1 with CT1 CT32B0_CAP1 with CT3 <u>1 description"</u> . gure 7 "AHB multilayer r B.	6B0_CAP2 for pin	PI01_21. See <u>Table 3 "Pin</u> PIO1_6 and pin PIO1_29. See
20140526			
	Droduct data chact		1
Part markin		-	LPC11U6x v.1.1
<ul> <li>Section 14.</li> <li>Remark add 14.3 "Sugget Figure 39 "to connection</li> </ul>	7 "Connecting power, cl 9 "Pin states in different ded about using the reg ested USB interface sol USB interface on a bus- to part.	power modes" add ulator in the USB br utions". powered device" cl	ded. us-powered set-up. See <u>Sectior</u> hanged to show USB_VBUS
20140312	Product data sheet	-	LPC11U6x v.1
<ul> <li>Description "Suggested internally by</li> <li>Parameter</li> <li>Figure 36 "/</li> <li>Parameter</li> <li>Pin description</li> <li>See Table 3</li> <li>Pin description</li> <li>Pin description</li> <li>Pin function</li> <li>Pin description</li> <li>Pin description</li> <li>Section 14.</li> </ul>	of the internal USB_CC I USB interface solution y software and does not Cia corrected in Table 2 ADC input impedance" a pin capacitance added tion for VBAT updated: I 3. tion for RESET/PIO0_0 IGH externally. The RE an external RESET fun ns TMS, TDI, TDO, and tion table updated for cl 1 "ADC usage notes" ad	DNNECT function c s". The USB_CONI require external ci 2 "12-bit ADC station added. In Table 8. f no battery is used <u>updated: In deep p</u> SET pin can be left ction is not needed TRST changed to c arity (VBAT, I2C-bu dded.	larified in Section 14.3 NECT function can be set rcuitry. c characteristics". d, tie VBAT to VDD or to ground power-down mode, this pin mus unconnected or be used as a l. See Table 3. default function in Table 3. is pins, WAKEUP pin).
	<ul> <li>connection</li> <li>Parts addee</li> <li>20140312</li> <li>Parameter</li> <li>Description "Suggested internally by</li> <li>Parameter</li> <li>Figure 36 "//</li> <li>Parameter</li> <li>Pin descrip See Table 3</li> <li>Pin descrip be pulled H GPIO pin if</li> <li>Pin functior</li> <li>Pin descrip</li> <li>Section 14.</li> <li>Use of USE</li> </ul>	<ul> <li>connection to part.</li> <li>Parts added: LPC11U67JBD100, L</li> <li>20140312 Product data sheet</li> <li>Parameter R<sub>I</sub> renamed to Z<sub>I</sub> (input</li> <li>Description of the internal USB_CC "Suggested USB interface solutions internally by software and does not</li> <li>Parameter Cia corrected in Table 2</li> <li>Figure 36 "ADC input impedance" a</li> <li>Parameter pin capacitance added i</li> <li>Pin description for VBAT updated: I See Table 3.</li> <li>Pin description for RESET/PIO0_0 be pulled HIGH externally. The RES GPIO pin if an external RESET fun</li> <li>Pin functions TMS, TDI, TDO, and</li> <li>Pin description table updated for cl</li> <li>Section 14.1 "ADC usage notes" ac</li> <li>Use of USB_CONNECT signal exp Section 14.3.</li> </ul>	<ul> <li>Parts added: LPC11U67JBD100, LPC11U67JBD64, L</li> <li>20140312 Product data sheet -</li> <li>Parameter R<sub>I</sub> renamed to Z<sub>I</sub> (input impedance) in Table</li> <li>Description of the internal USB_CONNECT function of "Suggested USB interface solutions". The USB_CONI internally by software and does not require external ci</li> <li>Parameter Cia corrected in Table 22 "12-bit ADC stations". The USB_CONI internally by software and does not require external ci</li> <li>Parameter Cia corrected in Table 22 "12-bit ADC stations". The USB_CONI internally by software and does not require external ci</li> <li>Parameter Cia corrected in Table 22 "12-bit ADC stations". The USB_CONI internality of the transmitter of</li></ul>

# **19. Legal information**

## **19.1 Data sheet status**

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

# 19.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

# **19.3 Disclaimers**

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nxp.com/profile/terms">http://www.nxp.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b)

# 20. Contact information

whenever customer uses the product for automotive applications beyond NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

# 19.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

I<sup>2</sup>C-bus — logo is a trademark of NXP Semiconductors N.V.

#### For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

# 21. Contents

3       Applications       3         4       Ordering information       4         4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning information       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Faatures       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12       GPIO group interrupts       26	3       Applications       3         4       Ordering information       4         4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9.1       OctoN block       23         8.9.2       Standard I/O pad configuration       24         8.10       Faatures       25         8.11       Features       25         8.12       GPIO group interruptse parallel I/O (GPIO)       24 <th>1</th> <th>General description 1</th>	1	General description 1
4       Ordering information.       4         4.1       Ordering options.       4         5       Marking.       5         6       Block diagram       6         7       Pinning information.       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine <th>4       Ordering information       4         4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26<!--</th--><th>2</th><th>Features and benefits 1</th></th>	4       Ordering information       4         4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26 </th <th>2</th> <th>Features and benefits 1</th>	2	Features and benefits 1
4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.11       Features	4.1       Ordering options       4         5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.9.2       Standard I/O pad configuration       24         8.10       Features       25         8.11       Peatures       25         8.12       GPIO group interrupts parallel I/O (GPIO)       24         8.10       Features       25         8.11       Peatures       26	3	Applications 3
5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       9         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.11       Pin ontroller </td <td>5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13.1       Features</td> <td>4</td> <td>Ordering information 4</td>	5       Marking       5         6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13.1       Features	4	Ordering information 4
6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       9         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.13       D	6       Block diagram       6         7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13.1       Features       26         8.13       DMA controll	4.1	Ordering options 4
7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.13       DMA controller       27         8.14	7       Pinning information       7         7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10       Features       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.13       DMA controller       27         8.14       USB interface	5	Marking 5
7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.15.1       Features       26         8.16       USART0       27         8.17       SSP serial I/O controller (SSP0/1) <th>7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9.1       OCON block       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.15.1       Features       26         8.14       <td< th=""><th>6</th><th>Block diagram 6</th></td<></th>	7.1       Pinning       7         7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9.1       OCON block       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.15.1       Features       26         8.14 <td< th=""><th>6</th><th>Block diagram 6</th></td<>	6	Block diagram 6
7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.15       USART0       27         8.16	7.2       Pin description       9         8       Functional description       19         8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources.       23         8.9.1       DOCON block.       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB device controller       27         8.15.1       Features       26	7	Pinning information7
8         Functional description         19           8.1         ARM Cortex-M0+ core         19           8.2         AHB multilayer matrix         19           8.3         On-chip flash programming memory         21           8.4         EEPROM         21           8.5         SRAM         21           8.6         On-chip ROM         21           8.7         Memory mapping         21           8.8         Nested Vectored Interrupt Controller (NVIC)         22           8.8.1         Features         23           8.8.2         Interrupt sources         23           8.9         IOCON block         23           8.9.1         Features         23           8.9.2         Standard I/O pad configuration         24           8.10         Fast General-Purpose parallel I/O (GPIO)         24           8.10.1         Features         25           8.11         Pin interrupt/pattern match engine         25           8.12         GPIO group interrupts         26           8.12.1         Features         26           8.13         DMA controller         27           8.14         USB interface         27      <	8         Functional description         19           8.1         ARM Cortex-M0+ core         19           8.2         AHB multilayer matrix         19           8.3         On-chip flash programming memory         21           8.4         EEPROM         21           8.5         SRAM         21           8.6         On-chip ROM         21           8.7         Memory mapping         21           8.8         Nested Vectored Interrupt Controller (NVIC)         22           8.8.1         Features         23           8.8.2         Interrupt sources         23           8.9         IOCON block         23           8.9.1         Features         23           8.9.2         Standard I/O pad configuration         24           8.10         Fast General-Purpose parallel I/O (GPIO)         24           8.10.1         Features         25           8.11         Pin interrupt/pattern match engine         25           8.11         Features         26           8.12         GPIO group interrupts         26           8.12.1         Features         26           8.13         DMA controller         27		
8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.15       USART0       27         8.16       USART1/2/3/4 <td>8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts.       26         8.13       DMA controller       26         8.14       USB interface       27         8.15.1       Features       27         8.16       USART1/2/3/4.       28         8.16       USART1/2/3/4.       28         8.16.1       <t< td=""><td>7.2</td><td></td></t<></td>	8.1       ARM Cortex-M0+ core       19         8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts.       26         8.13       DMA controller       26         8.14       USB interface       27         8.15.1       Features       27         8.16       USART1/2/3/4.       28         8.16       USART1/2/3/4.       28         8.16.1 <t< td=""><td>7.2</td><td></td></t<>	7.2	
8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.15.1       Features </td <td>8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.16</td> <td>8</td> <td>Functional description 19</td>	8.2       AHB multilayer matrix       19         8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.16	8	Functional description 19
8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts.       26         8.13.1       Features       26         8.13.1       Features       27         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Feat	8.3       On-chip flash programming memory       21         8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14       USART0       27         8.15       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.17       SS	•••	
8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       <	8.4       EEPROM       21         8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14       USART0       27         8.15       USART0       27         8.16       USART1/2/3/4       28         8.16.1       Features       29 <t< td=""><td></td><td></td></t<>		
8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       26         8.12.1       GPIO group interrupts       26         8.12.1       Features       26         8.13.1       Features       27         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features	8.5       SRAM       21         8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14       USART0       27         8.16       USART0       27         8.16.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)		
8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13.1       Features       26         8.14.1       Features       26         8.13       DMA controller       26         8.14.1       Features       27         8.14.1       Features       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features	8.6       On-chip ROM       21         8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       26         8.12.1       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.15       USARTO       27         8.16       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18.1       Features       30         8.19       Timer/	<b>.</b>	
8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Fin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Features       27         8.14.1       Features       27         8.15.1       Features       27         8.16       USARTO       27         8.15.1       Features       28         8.16       USARTO       27         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)	8.7       Memory mapping       21         8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14       USARTO       27         8.15.1       Features       28         8.16       USART1/2/3/4.       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)       29         8.18.1       Features       30         8.19       Timer/		
8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       27         8.14.1       Features       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       28         8.16       USART0       27         8.15.1       Features       28         8.16.1       Features       28         8.16.1       Features	8.8       Nested Vectored Interrupt Controller (NVIC)       22         8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.15       USART0       27         8.16       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29		
8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Features       25         8.11       Fin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Features       27         8.15.1       Features       27         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       28         8.16.1       Features       29         8.17	8.8.1       Features       23         8.8.2       Interrupt sources       23         8.9       IOCON block       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.11       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14       USARTO       27         8.15       USARTO       27         8.16       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O	•	
8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts.       26         8.13.1       Features       26         8.14.1       Features       26         8.13.1       Features       26         8.14.1       Features       26         8.13.1       Features       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O cont	8.8.2       Interrupt sources.       23         8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.15       USART0       27         8.16       USART1/2/3/4.       28         8.16       USART1/2/3/4.       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PW		
8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts.       26         8.13.1       Features       26         8.14       USB interface       26         8.13.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Features       27         8.15.1       Features       27         8.16.1       Features       28         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I²C-bus serial I/O controller       2	8.9       IOCON block.       23         8.9.1       Features       23         8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB RTD       27         8.15       USARTO       27         8.16       USART1/2/3/4.       28         8.16       USART1/2/3/4.       28         8.16       VSART1/2/3/4.       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features		
8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Features       27         8.15.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17       SSP serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O controller	8.9.1       Features       23         8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.11       Features       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.12.1       Features       26         8.12       GPIO group interrupts       26         8.13       DMA controller       26         8.13.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14       USART0       27         8.15       USART0       27         8.16       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.16       VSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller <t< td=""><td></td><td>•</td></t<>		•
8.9.2       Standard I/O pad configuration       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Full-speed USB device controller       27         8.15.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller <td>8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I<sup>2</sup>C-bus serial I/O controller       29         8.18       <td< td=""><td></td><td></td></td<></td>	8.9.2       Standard I/O pad configuration.       24         8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18 <td< td=""><td></td><td></td></td<>		
8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13       DMA controller       26         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17       SSP serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Featu	8.10       Fast General-Purpose parallel I/O (GPIO)       24         8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Features       27         8.15       USART0       27         8.15       USART1/2/3/4       28         8.16       USART1/2/3/4       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.19       Timer/PWM subsystem		
8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.10.1       Features       25         8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.14.1       Features       27         8.14.1       Features       27         8.15.1       Features       27         8.16       USART0       27         8.16.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.11       Pin interrupt/pattern match engine       25         8.11       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I²C-bus serial I/O controller       29         8.18.1       Features       30	8.11       Pin interrupt/pattern match engine       25         8.11.1       Features       25         8.12       GPIO group interrupts       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14.1       Features       26         8.13       DMA controller       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.15       USART0       27         8.15       USART0       27         8.15       VSART0       27         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.11.1       Features       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.11.1       Features       25         8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13.1       Features       26         8.14.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.16       USART1/2/3/4.       28         8.16       USART1/2/3/4.       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13       DMA controller       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       27         8.15.1       Features       28         8.16       USART0       27         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.12       GPIO group interrupts.       26         8.12.1       Features       26         8.13       DMA controller       26         8.14       USB interface       27         8.14       USB interface       27         8.14       Features       27         8.15       USART0       27         8.15       USART1       28         8.16       USART1/2/3/4       28         8.16       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18       Features       30         8.19       Timer/PWM subsystem       30         8.19.1		
8.12.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.13.1       Features       26         8.13.1       Features       26         8.13.1       Features       26         8.14.1       Full-speed USB device controller       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I²C-bus serial I/O controller       29         8.18.1       Features       30	8.12.1       Features       26         8.13       DMA controller       26         8.13.1       Features       26         8.13.1       Features       26         8.13.1       Features       26         8.13.1       Features       26         8.14.1       Full-speed USB device controller       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4.       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.13       DMA controller       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USARTO       27         8.15.1       Features       28         8.16       USART1/2/3/4.       28         8.16.1       Features       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.13       DMA controller       26         8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.14.1       Features       27         8.15       USART0       27         8.15       USART0       27         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.16.1       Features       29         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.13.1       Features       26         8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.14       USB interface       27         8.14.1       Full-speed USB device controller       27         8.14.1       Features       27         8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.14.1       Full-speed USB device controller       27         8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.14.1       Full-speed USB device controller       27         8.14.1.1       Features       27         8.14.1.1       Features       27         8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.14.1.1       Features       27         8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4       28         8.16.1       Features       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30	8.15       USART0       27         8.15.1       Features       28         8.16       USART1/2/3/4.       28         8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and		
8.16       USART1/2/3/4	8.16       USART1/2/3/4		
8.16.1         Features         28           8.17         SSP serial I/O controller (SSP0/1)         29           8.17.1         Features         29           8.18         I²C-bus serial I/O controller         29           8.18.1         Features         30	8.16.1       Features       28         8.17       SSP serial I/O controller (SSP0/1)       29         8.17.1       Features       29         8.18       I <sup>2</sup> C-bus serial I/O controller       29         8.18.1       Features       30         8.19       Timer/PWM subsystem       30         8.19.1       State Configurable Timers (SCTimer0/PWM and	8.15.1	Features
8.17         SSP serial I/O controller (SSP0/1)	8.17         SSP serial I/O controller (SSP0/1)         29           8.17.1         Features         29           8.18         I²C-bus serial I/O controller         29           8.18.1         Features         30           8.19         Timer/PWM subsystem         30           8.19.1         State Configurable Timers (SCTimer0/PWM and	8.16	USART1/2/3/4
8.17.1         Features         29           8.18         I <sup>2</sup> C-bus serial I/O controller         29           8.18.1         Features         30	8.17.1         Features         29           8.18         l <sup>2</sup> C-bus serial I/O controller         29           8.18.1         Features         30           8.19         Timer/PWM subsystem         30           8.19.1         State Configurable Timers (SCTimer0/PWM and	8.16.1	Features
8.17.1         Features         29           8.18         I <sup>2</sup> C-bus serial I/O controller         29           8.18.1         Features         30	8.17.1         Features         29           8.18         l <sup>2</sup> C-bus serial I/O controller         29           8.18.1         Features         30           8.19         Timer/PWM subsystem         30           8.19.1         State Configurable Timers (SCTimer0/PWM and		
8.18.1 Features	8.18.1Features308.19Timer/PWM subsystem308.19.1State Configurable Timers (SCTimer0/PWM and		Features
8.18.1 Features	8.18.1Features308.19Timer/PWM subsystem308.19.1State Configurable Timers (SCTimer0/PWM and	8.18	I <sup>2</sup> C-bus serial I/O controller
8.19 Timer/PWM subsystem	8.19.1 State Configurable Timers (SCTimer0/PWM and	8.18.1	
	8.19.1 State Configurable Timers (SCTimer0/PWM and	8.19	Timer/PWM subsystem
8.19.1 State Configurable Timers (SCTimer0/PWM and		8.19.1	State Configurable Timers (SCTimer0/PWM and
SCTimer1/PWM)			SCTimer1/PWM)

8.19.1.1	Features	32
8.19.2	General purpose external event counter/timer	s
	(CT32B0/1 and CT16B0/1)	33
8.19.2.1	Features	33
8.20	System tick timer (SysTick)	33
8.21	Windowed WatchDog Timer (WWDT)	33
8.21.1	Features	33
8.22	Real-Time Clock (RTC)	34
8.22.1	Features	34
8.23	Analog-to-Digital Converter (ADC)	34
8.23.1	Features	34
8.24	Temperature sensor	35
8.25	Clocking and power control	36
8.25.1	Clock generation	36
8.25.2	Power domains	37
8.25.3	Integrated oscillators	37
8.25.3.1	Internal RC oscillator	38
8.25.3.2	5	38
8.25.3.3		38
8.25.3.4		38
8.25.4	System PLL and USB PLL	38
8.25.5		38
8.25.6	Wake-up process	39
8.25.7	Power control	39
8.25.7.1	Power profiles	39
8.25.7.2		39
8.25.7.3	1 1	40 40
8.25.7.4		40 40
8.25.7.5		40 40
8.26 8.26.1	System control	40 40
o.∠o. i 8.26.2	Reset	40
8.26.3	Brownout detection Code security (Code Read Protection - CRP)	41
0.20.3 8.27		41
	Emulation and debugging	
9	Limiting values	44
10	Thermal characteristics	45
11	Static characteristics	46
11.1	Power consumption	52
11.2	CoreMark data	56
11.3	Peripheral power consumption	57
11.4	Electrical pin characteristics	59
12	Dynamic characteristics	62
12.1	Flash/EEPROM memory	62
12.2	External clock for the oscillator in slave mode	62
12.3	Internal oscillators	63
12.4	I/O pins	64
12.5	l <sup>2</sup> C-bus	64

### continued >>

12.6	SSP interface 66	
12.7	USART interface	
12.8	SCTimer/PWM output timing 69	
13	Characteristics of analog peripherals 70	
14	Application information	
14.1	ADC usage notes	
14.2	Typical wake-up times	
14.3	Suggested USB interface solutions	
14.3.1	USB Low-speed operation	
14.4	XTAL input and crystal oscillator component	
	selection	
14.5	XTAL Printed-Circuit Board (PCB) layout	
	guidelines	
14.6	RTC oscillator component selection 81	
14.7	Connecting power, clocks, and debug functions	
	81	
14.8	Termination of unused pins	
14.9	Pin states in different power modes 84	
14.10	ElectroMagnetic Compatibility (EMC) 85	
15	Package outline 86	
16	Soldering 89	
17	References	
18	Revision history 93	
19	Legal information	
19.1	Data sheet status	
19.2	Definitions	
19.3	Disclaimers	
19.4	Trademarks	
20	Contact information 95	
21	Contents	

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

#### © NXP Semiconductors N.V. 2020.

#### All rights reserved.

For more information, please visit: http://www.nxp.com For sales office addresses, please send an email to: salesaddresses@nxp.com

Date of release: 12 August 2020 Document identifier: LPC11U6x

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for ARM Microcontrollers - MCU category:

Click to view products by NXP manufacturer:

Other Similar products are found below :

R7FS3A77C2A01CLK#AC1\_CP8363AT\_MB96F119RBPMC-GSE1\_MB9BF122LPMC1-G-JNE2\_MB9BF122LPMC-G-JNE2 MB9BF128SAPMC-GE2\_MB9BF218TBGL-GE1\_MB9BF529TBGL-GE1\_26-21/R6C-AT1V2B/CT\_5962-8506403MQA MB9AF342MAPMC-G-JNE2\_MB96F001YBPMC1-GSE1\_MB9BF121KPMC-G-JNE2\_VA10800-D000003PCA\_CP8547AT CY9AF156NPMC-G-JNE2\_MB9BF104NAPMC-G-JNE1\_CY8C4724FNI-S402T\_ADUCM410BCBZ-RL7\_GD32f303RGT6 NHS3152UK/A1Z\_MK26FN2M0CAC18R\_EFM32TG230F32-D-QFN64\_EFM32TG232F32-D-QFP64\_EFM32TG825F32-D-BGA48 MB9AFB44NBBGL-GE1\_MB9BF304RBPMC-G-JNE2\_MB9BF416RPMC-G-JNE2\_MB9AF155MABGL-GE1\_MB9BF306RBPMC-G-JNE2 MB9BF618TBGL-GE1\_ATSAMS70N21A-CN\_MK20DX64VFT5\_MK50DX128CMC7\_MK51DN256CMD10\_MK51DX128CMC7 MK53DX256CMD10\_MKL25Z32VFT4\_LPC1754FBD80\_STM32F030K6T6TR\_STM32L073VBT6\_LPC11U24FET48301, AT91M42800A-33AU\_AT91SAM7L64-CU\_ATSAM3N0AA-MU\_ATSAM3N0CA-CU\_ATSAM3SD8BA-MU\_ATSAM4LC2BA-UUR\_ATSAM4LC4BA-MU ATSAM4LS2AA-MU